

(A State University Established in 1985)

Karaikudi - 630003. Tamil Nadu, India















FACULTY OF SCIENCE DEPARTMENT OF BIOELECTRONICS AND BIOSENSORS



M.Sc., MATERIALS SCIENCE

REGULATIONS AND SYLLABUS

(For the candidates admitted from the **Academic Year 2022 - 2023)**

DEPARTMENT OF BIOELECTRONICS AND BIOSENSORS M.Sc., Materials Science

REGULATIONS AND SYLLABUS

[For the candidates admitted from the Academic Year 2022 – 2023 onwards]



ALAGAPPA UNIVERSITY

(A State University Accredited with "A+" grade by NAAC (CGPA: 3.64) in the Third Cycle and Graded as Category-I University by MHRD-UGC)

Karaikudi -630003, Tamil Nadu.

The panel of Members-Broad Based Board of Studies

Chairperson: Dr. C. Sekar, Professor and Head, Department of Bioelectronics and Biosensors, Alagappa University, Karaikudi. Areas of Expertise Materials Science: Metal Oxide Semiconductors, Carbon Nanostructures, Biomaterials, Low Dimensional Cuprates Sensors: Chemical Sensors, Biosensors for Medical, Food, Agricultural and Environmental Applications.



Foreign Expert: Dr. Giovanni Neri, Professor, Department of Engineering, University of Messina. Italy. Areas of Expertise Catalysis, Gas Sensors, Biosensors.



Indian Expert: Dr. J. Mathiyarasu, Principal Scientist, Biosensors Division, CSIR-Central Electrochemical Research Institute, India. Email: almathi@cecri.res.in. Areas of Expertise: Electrochemical Biosensors.



Indian Expert: Dr. N. Rameshbabu, Associate Professor, Department of Metallurgy, National Institute of Trichy, Tamil nadu, India. Email: rameshrohith@gmail.com. Areas of expertise: Bio materials, Ceramic materials, Plasma electrolytic oxidation coatings



Industry Expert: Dr. V. Viswabaskaran, The General Manager, VB ceramics, kottivakkam, Chennai, India. Email: drvbcrc@gmail.com, Area of Expertise: Ceramic Consultant



Members: Dr. G. Ravi, Professor and Head, Department of Physics, Alagappa University, Karaikudi – 630003, Tamil Nadu, India. Email: raviganesa@rediffmail.com. Areas of Expertise: Crystal Growth of Organic & Inorganic Materials, Nano Materials Synthesis and Thin Films Preparation for Supercapacitors, Photocatalytic and Sensor Applications, Opto-Electronics and E-O Modulator–Devices



Dr. V. Dharuman, Assistant Professor, Department of Bioelectronics and Biosensors, Alagappa University, Karaikudi – 630003, Tamil Nadu,India. Email: dharumanudhay@yahoo.com. Areas of Expertise: Chemistry/Electrochemistry/Diabetic, Cancer Biosensors Development using, DNA, Antibody (Immunosensors) and Neurological Disorder Sensors.



Dr. J. Wilson, Assistant Professor, Department of Bioelectronics & Biosensors, Alagappa University, Karaikudi – 630003, Tamil Nadu, India. Email: wilson.j2008@yahoo.com. Areas of Expertise: Conducting Polymers, Metal Oxides, Carbon Based Materials, Biosensors, and Lithium Batteries.



Alumnus/Alumna: Mrs. S.Meenakshi, Research Scholar, Department of Bioelectronics and Biosensors, Karaikudi, India. Email: meenakshisolaimani@gmail.com. Areas of Expertise: Chemo-Biosensors, Shock waves.





ALAGAPPA UNIVERSITY DEPARTMENT OF BIOELECTRONICS & BIOSENSORS

Karaikudi -630003, Tamil Nadu.

REGULATIONS AND SYLLABUS (CBCS-University Department)

[For the candidates admitted from the Academic Year 2022 – 2023 onwards]

Name of the Department

Name of the Programme

: Bioelectronics & Biosensors

: M.Sc., Materials Science

Duration of the Programme

: Full Time (Two Years)

Choice-Based Credit System

A Choice-Based Credit System is a flexible system of learning. This system allows students to gain knowledge at their own tempo. Students shall decide on electives from a wide range of elective courses offered by the University Departments in consultation with the Department committee. Students undergo additional courses and acquire more than the required number of credits. They can also adopt an inter-disciplinary and intra-disciplinary approach to learning, and make the best use of the expertise of available faculty.

Programme

"Programme" means a course of study leading to the award of a degree in a discipline.

Courses

'Course' is a component (a paper) of a programme. Each course offered by the Department is identified by a unique course code. A course contains lectures/ tutorials/laboratory work/seminar/project work / practical training/report writing /Viva-voce, etc or a combination of these, to meet effectively the teaching and learning needs.

Credits

The Term "Credit" refers to the weightage given to a course, usually in relation to the instructional hours assigned to it. Normally in each of the course's credits will be assigned on the basis of the number of lectures/tutorial/laboratory and other forms of learning required to complete the course contents in a 15-week schedule. One credit is equal to one hour of lecture per week. For laboratory/field work one credit is equal to two hours.

Semesters

An Academic year is divided into two **Semesters.** In each semester, courses are offered in 15 teaching weeks and the remaining 5 weeks are to be utilized for conduct of examination and evaluation purposes. Each week has 30 working hours spread over 5 days a week.

Medium of Instruction

Medium of instruction is English

Departmental committee

The Departmental Committee consists of the faculty of the Department. The Departmental Committee shall be responsible for admission to all the programmes offered by the Department including the conduct of entrance tests, verification of records, admission, and evaluation. The Departmental Committee determine the deliberation of courses and specifies the allocation of credits semester-wise and course-wise. For each course, it will also identify the number of credits for lectures, tutorials, practical's, seminars etc. The courses (Core/Discipline Specific Elective/Non-Major Elective) are designed by teachers and approved by the Departmental Committees. Courses approved by the Departmental Committees shall be approved by the Board of Studies. A teacher offering a course will also be responsible for maintaining attendance and performance sheets (CIA -I, CIA-II, assignments and seminar) of all the students registered for the course. The non-major elective programme and MOOCs coordinator are responsible for submitting the performance sheet to the Head of the department. The Head of the Department consolidates all such performance sheets of courses pertaining to the programmes offered by the department. Then forward the same to be Controller of Examinations.

Programme Educational Objectives- (PEO)

PEO-1	To educate basics and applied aspects of materials science		
PEO-2	To make the students understand the interdisciplinary activities of materials		
PEO-3	To enhance critical thinking on societal issues in using materials		
PEO-4	To adhere to ethical consideration for sustainable development		
PEO-5	To design material adhering to environmental condition and cost effectiveness		
PEO-6	To motivate the students to become researchers in materials advancements		
PEO-7	To enhance analytical skills to solve research problem		
PEO-8	To apply materials science for future technology		
PEO-9	To inculcate strong research culture among materials science students		
PEO-10	To enrich curiosity and expand knowledge through lifelong learning		

Programme Specific Objectives-(PSO)

PSO-1	Learning fundamental knowledge in materials design and development	
PSO-2	Training in using analytical instruments in materials characterization	
PSO-3	Educating different forms of materials and their applications	
PSO-4	Undertaking research problems in material science and solving	
PSO-5	Effective implementation of materials in research and professional applications	

Programme Outcome

PO 1	Attaining proficiency in fundamental knowledge in the field of materials science		
PO 2	Grasping the basic principles of relevant scientific theories		
PO 3	Applying knowledge to practical situations and solving real-world problems		
PO 4	Conducting research to advance the understanding of materials science		
PO 5	Employing techniques for the characterization and evaluation of materials		
PO 6	Generating innovative solutions and ideas in materials science		
PO 7	Optimizing material properties and performance for specific applications		
PO 8	Developing the skills to synthesize and fabricate materials, prototypes		
PO 9	Performing thorough analysis of material properties and behavior		
PO 10	Applying critical thinking and use knowledge in interdisciplinary areas		

Programme Specific Outcome

PSO 1	In-depth understanding of principles governing the properties and behavior of materials at the atomic and molecular level	
PSO 2	Proficiency in applying physio-chemical theory, thermodynamic principles, structured and properties of materials to analyze and predict material responses	
PSO 3	Expertise in material integration with biomolecules for sensors, synthesizing and tailoring the properties of materials for specialized applications	
PSO 4	Advanced skills in synthesizing nanomaterials using cutting-edge techniques and characterization of materials with controlled properties for diverse applications	
PSO 5	Knowledge of sustainable materials for sensors/molecular electronics and green chemistry principles for developing environmentally friendly devices in response to global challenges	

Eligibility for admission

A candidate who has passed B.Sc., Degree Examination with Physics, or Chemistry or equivalent degree in Science with maths, physics or chemistry as allied subjects as University accepted by the syndicate as equivalent thereto.

Minimum Duration of programme

The programme is for a period of two years. Each year shall consist of two semesters viz. Odd and Even semesters. Odd semesters shall be from June / July to October / November and even semesters shall be from November / December to April / May. For each semester, there shall be 90 working days consisting of 6 teaching hours per working day (5 days/week).

Components

A PG programme consists of a number of courses. The term "course" is applied to indicate a logical part of the subject matter of the programme and is invariably equivalent to the subject matter of a "paper" in the conventional sense. The following are the various categories of the courses suggested for the PG programmes:

- A. Core courses (CC)- "Core Papers" means "the core courses" related to the programme concerned including practical's and project work offered under the programme and shall cover Core competency, critical thinking, analytical reasoning, and research skill.
- B. Discipline-specific electives (DSE) means the courses offered under the programme related to the major but are to be selected by the students, shall cover additional academic knowledge, critical thinking, and analytical reasoning.
- C. Non-Major Electives (NME)- Exposure beyond the discipline
 - > Students have to undergo a total of two Non-Major Elective courses with 2 credits offered by other departments (one in II Semester another in III Semester)
 - ➤ A uniform time frame of 3 hours on a common day (Tuesday) shall be allocated for the Non-Major Electives
 - Non-Major Elective courses offered by the departments pertaining to a semester should be announced before the end of previous semester.
 - ➤ Registration process: Students have to register for the Non-Major Elective course within 15 days from the commencement of the semester either in the department or NME portal (University Website).
- D. Self-Learning Courses from MOOCs platforms.
 - ➤ MOOCs shall be on voluntary for the students.
 - > Students have to undergo a total of 2 Self Learning Courses (MOOCs) one in II semester and another in III semester.
 - ➤ The actual credits earned through MOOCs shall be transferred to the credit plan of programmes as extra credits. Otherwise, 2 credits/course be given if the Self Learning

- Course (MOOCs) is without credit.
- ➤ While selecting the MOOCs, preference shall be given to the course related to employability skills.

E. Projects / Dissertation /Internships (Maximum Marks: 200)

The student shall undertake the dissertation work during the fourth semester.

> Plan of work

Project/Dissertation

The candidate shall undergo Project/Dissertation Work during the final semester. The candidate should prepare a scheme of work for the dissertation/project and should get approval from the guide. The candidate, after completing the dissertation /project work, shall be allowed to submit it to the university departments at the end of the final semester. If the candidate is desirous of availing the facility from other departments/universities/laboratories/organizations they will be permitted only after getting approval from the guide and HOD. In such a case, the candidate shall acknowledge the same in their dissertation/project work.

> Format to be followed for dissertation/project report

The format /certificate for thesis to be followed by the student are given below

- > Title page
- > Certificate
- > Acknowledgment
- > Content as follows:

Chapter No	Title	Page number
1	Introduction	
2	Aim and objectives	
3	Review of literature	
4	Materials and methods	
5	Result	
6	Discussion	
7	Summary	
8	References	

> Format of the title page

Title of Dissertation/Project work

Dissertation submitted in partial fulfilment of the requirement for the degree of Master of Science in Material Science to the Alagappa University, Karaikudi -630003.

By

(Student N (Register Nu University	umber)
Department of	
Alagappa Un	iversity
(A State University Accredited with "A+" grade by	NAAC (CGPA: 3.64) in the Third Cycle and
Graded as Category-I University by MHRD-UGC,	2019: QS ASIA Rank-216, QS BRICS Rank-
104,QS India 1	Rank-20)
Karaikudi - (530003
(Year)	VERSITY 8.
Format of certificates	
Certificate - (<mark>Guide</mark>
This is to certify that the thesis entitled "	filment for the degree of Master of Science in) under my supervision. This is based on Department of, Alagappa roject or any part of this work has not been ellowship, or any other similar titles or record of
Place: Karaikudi	Research Supervisor
Date:	
Certificate - (I	HOD) " submitted by
Mr/Mis(Reg No:) to the A award of the degree of Master ofin, Assistan under the supervision of Dr, Assistan Alagappa University. This is to further certify that the basis of the award to the student of any degree, diplo University or Institution.	Alagappa University, in partial fulfilment for the is a bonafide record of research work done t Professor, Department of, ne thesis or any part thereof has not formed the oma, fellowship, or any other similar title of any
Place: Karaikudi	Head of the Department
Date:	

Declaration (student)

I hereby declare that the dissertation entitled "" submitted to
the Alagappa University for the award of the degree of Master of in has been
carried out by me under the guidance of Dr, Assistant Professor, Department of
, Alagappa University, Karaikudi - 630 003. This is my original and independen
work and has not previously formed the basis of the award of any degree, diploma, associateship
fellowship, or any other similar title of any University or Institution.
Place: Karaikudi ()
Date:
Date
<u>Internship</u>
The students who have opted for an Internship must undergo industrial training in the reputed
organizations to accrue industrial knowledge in the final semester. The student has to find industry
related to their discipline (Public limited/Private Limited/owner/NGOs etc.,) in consultation with the
faculty in charge and get approval from the head of the department and Departmental Committee
A STAGARDA HINIVERSITY AP
before going for an internship.
Enument to be followed for Internalin report
Format to be followed for Internship report The format (partificate for internship report to be followed by the student are given below)
The format /certificate for internship report to be followed by the student are given below
Title page -Format of the title page
Title of internship report
Internship report submitted in partial fulfilment of the requirement for the Master of degree in
to the Alagappa University, Karaikudi -630003.
By
(Student Name)
(Register Number)
University Logo

Alagappa University

Department of -----

(A State University Accredited with "A+" grade by NAAC (CGPA: 3.64) in the Third Cycle and Graded as Category-I University by MHRD-UGC, 2019: QS ASIA Rank-216, QS BRICS Rank-104,QS India Rank-20)

Karaikudi - 630003

(Year)

	t of certificate – faculty in-charge		
	report entitled "" submitted to		
Alagappa University, Karaikudi-630 003 in partial fulfilment for the Master of Science inby Mr/Mis (Reg. No:) under my supervision. This is based on the work carried out by him/her in the organization M/S This Internship report or any part of this work has not been submitted elsewhere for any other degree, diploma, fellowship, or any other similar record of any University or Institution.			
Place: Research Supervisor			
Date:			
	Certificate (HOD)		
	that the Internship report entitled "" submitted by		
the award of the Master of Science supervision of, As University and the work carried of to further certify that the thesis or	to the Alagappa University, in partial fulfilment for se in is a bonafide record of Internship report done under the sistant Professor, Department of, Alagappa ut by him/her in the organization M/S This is any part thereof has not formed the basis of the award to the student p, or any other similar title of any University or Institution.		
Place: Karaikudi	Head of the Department		
Date:			
Certificate-FormatOrganization	of certificate – Company supervisor or Head of the		
Alagappa University, Karaikudi-6by Mr/Mis (Reg. carried out by him/her in our orga or This Internship report o	report entitled "" submitted to 30 003 in partial fulfilment for the Master of Science in No:) under my supervision. This is based on the work anization M/S for the period of three months r any part of this work has not been submitted elsewhere for any or any other similar record of any University or Institution.		
Place:	Supervisor or in charge		

Declaration (student)

I hereby declare that the dissertation/project entitled "	" submitted to the
Alagappa University for the award of the Master of Science in	has been carried out by me
under the supervision of, Assistant Professor, Department	nt of,
Alagappa University, Karaikudi - 630 003. This is my original and independent	endent work carried out by
me in the organization M/S for the period of three n previously formed the basis of the award of any degree, diploma, associate other similar title of any University or Institution.	
Place: Karaikudi	()

Place: Karaikudi	()

Date:		

- > Acknowledgment
- > Content as follows:

Chapter No	Title	Page number
1	Introduction	
2	Aim and objectives	
3	Organisation profile /details	
4	Method work	6.
5	Observation and knowledge gained	
6	Summary and outcome of the study	
7	References	

No. of copies of the dissertation/project report/internship report

The candidate should prepare three copies of the dissertation/project/report and submit the same for the evaluation of examiners. After evaluation, one copy will be retained in the department library, one copy will be retained by the guide and the student shall hold one copy.

Teaching methods

Department teachers shall instruct using power point presentation along with white board and smart boards. Use of internet and library as and when required for effective learning

Attendance

Students must have earned 75% of attendance in each course for appearing for the examination. Students who have earned 74% to 70% of attendance need to apply for condonation in the prescribed form with the prescribed fee. Students who have earned 69% to 60% of attendance need to apply for condonation in the prescribed form with the prescribed fee along with the Medical Certificate. Students who have below 60% of attendance are not eligible to appear for the End Semester Examination (ESE). They shall re-do the semester(s) after completion of the programme

Examination

The examinations shall be conducted separately for theory and practicals to assess (remembering, understanding, applying, analysing, evaluating, and creating) the knowledge required during the study. There shall be two systems of examinations viz., internal and external examinations. The internal examinations shall be conducted as Continuous Internal Assessment tests I and II (CIA Test I & II).

A. Internal Assessment

The internal assessment shall comprise a maximum of 25 marks for each subject. The following procedure shall be followed for awarding internal marks.

Theory -25 marks

Sr.No	Content	Marks	
1	Average marks of two CIA test		15
2	Seminar/group discussion/quiz		5
3	Assignment/field trip report/case study report		5
	Total		25

Practical -25 Marks

1	Major Experiment	10 marks
2	Minor Experiment	5 marks
3	Spotter (2x 5/4 x4) or any other mode	10 marks
	Total	25 Marks

Project/Dissertation/internship-50 Marks (assess by Guide/in-charge/supervisor)

1	Two presentations (mid-term)	30 Marks
2	Progress report	20 Marks
	Total	50 Marks

B. External Examination

- ➤ There shall be examinations at the end of each semester, for odd semesters in the month of October / November; for even semesters in April / May.
- A candidate who does not pass the examination in any course(s) may be permitted to appear in such failed course(s) in the subsequent examinations to be held in October / November or April / May. However, candidates who have arrears in Practical shall be permitted to take their arrear Practical examination only along with Regular Practical examination in the respective semester.
- A candidate should get registered for the first semester examination. If registration is not possible owing to shortage of attendance beyond condonation limit / regulation prescribed OR belated joining OR on medical grounds, the candidates are permitted to move to the next semester. Such candidates shall re-do the missed semester after completion of the programme.
- For the Project Report/ Dissertation Work / internship the maximum marks will be 100 marks for project report evaluation and for the Viva-Voce it is 50 marks (if in some programmes, if

- the project is equivalent to more than one course, the project marks would be in proportion to the number of equivalent courses).
- ➤ Viva-Voce: Each candidate shall be required to appear for Viva-Voce Examination (in defense of the Dissertation Work /Project/ internship).

C. Scheme of External Examination (Question Paper Pattern)

Theory - Maximum 75 Marks

Section A	10 questions. All questions carry equal	$10 \times 1 = 10$	10 questions – 2 each
	marks. (Objective type questions)	Marks	from every unit
Section B	5 questions Either / or type like 1.a		5 questions – 1 each
	(or) b. All questions carry equal		from every unit
	marks.		
Section C	5 questions Either / or type like 1.a		5 question –Should
	(or) b. All questions carry equal		cover all units
	marks.		

Practical – Maximum 75 Marks

Section A	Major experiment	15 Marks
Section B	Minor experiment	10 Marks
Section C	Experimental setup	5 Marks
Section D	Spotters (5 x5)	25 Marks
Section E	Record note	10 Marks
Section F	Vivo voce	10 Marks

Dissertation /Project report/Internship report Scheme of evaluation

Dissertation / Project report / Internship report	100 Marks
Vivo voce	50 Marks

Results

The results of all the examinations will be published through the Department where the student underwent the course as well as through University Website

Passing minimum

- A candidate shall be declared to have passed in each course if he/she secures not less than 40% marks in the End Semester Examinations and 40% marks in the Internal Assessment and not less than 50% in the aggregate, taking Continuous assessment and End Semester Examinations marks together.
- ➤ The candidates not obtained 50% in the Internal Assessment are permitted to improve their Internal Assessment marks in the subsequent semesters (2 chances will be given) by writing the CIA tests and by submitting assignments.

- ➤ Candidates, who have secured the pass marks in the End-Semester Examination and in the CIA but failed to secure the aggregate minimum pass mark (E.S.E + C I.A), are permitted to improve their Internal Assessment mark in the following semester and/or in University examinations.
- A candidate shall be declared to have passed in the Project Work if he /she gets not less than 40% in each of the Project Report and Viva-Voce and not less than 50% in the aggregate of both the marks for Project Report and Viva-Voce.
- A candidate who gets less than 50% in the Project Report must resubmit the Project Report. Such candidates need to take again the Viva-Voce on the resubmitted Project.

Grading of the Courses

The following table gives the marks, Grade points, Letter Grades and classifications meant to indicate the overall academic performance of the candidate.

Conversion of Marks to Grade Points and Letter Grade (Performance in Paper / Course)

RANGE OF MARKS	GRADE POINTS	LETTER GRADE	DESCRIPTION
90 - 100	9.0 – 10.0	O UNIVERSITY 8	Outstanding
80 - 89	8.0 – 8.9	D+	Excellent
75 - 79	7.5 – 7.9	D	Distinction
70 - 74	7.0 – 7.4	A+	Very Good
60 - 69	6.0 – 6.9	A	Good
50 - 59	5.0 - 5.9	В	Average
00 - 49	0.0	U	Re-appear
ABSENT	0.0	AAA	ABSENT

- a) Successful candidates passing the examinations and earning GPA between 9.0 and 10.0 and marks from 90 100 shall be declared to have Outstanding (O).
- b) Successful candidates passing the examinations and earning GPA between 8.0 and 8.9 and marks from 80 89 shall be declared to have Excellent (D+).
- c) Successful candidates passing the examinations and earning GPA between 7.5 7.9 and marks from 75 79 shall be declared to have Distinction (D).
- d) Successful candidates passing the examinations and earning GPA between 7.0 7.4 and marks from 70 74 shall be declared to have Very Good (A+).
- e) Successful candidates passing the examinations and earning GPA between 6.0 6.9 and marks from 60 69 shall be declared to have Good (A).
- f) Successful candidates passing the examinations and earning GPA between 5.0 5.9 and marks from 50 59 shall be declared to have Average (B).

- g) Candidates earning GPA between 0.0 and marks from 00 49 shall be declared to have Reappear (U).
- h) Absence from an examination shall not be taken as an attempt.

From the second semester onwards the total performance within a semester and continuous performance starting from the first semester are indicated respectively by Grade Point Average (GPA) and Cumulative Grade Point Average (CGPA). These two are calculated by the following formulate

GRADE POINT AVERAGE (GPA) = $\Sigma_i C_i G_i / \Sigma_i C_i$

GPA = <u>Sum of the multiplication of Grade Points by the credits of the courses</u> Sum of the credits of the courses in a Semester

Classification of the final result

CGPA	Grade	Classification of Final Result
9.5 – 10.0	0+	First Class – Exemplary*
9.0 and above but below 9.5	0	1 3
8.5 and above but below 9.0	D++	
8.0 and above but below 8.5	D+	First Class with Distinction*
7.5 and above but below 8.0	D	2
7.0 and above but below 7.5	A++	2
6.5 and above but below 7.0	A+	First Class
6.0 and above but below 6.5	A	
5.5 and above but below 6.0	B+	Second Class
5.0 and above but below 5.5	В	Second Class
0.0 and above but below 5.0	$\mathbf{U} = \mathbf{U}$	Re-appear

The final result of the candidate shall be based only on the CGPA earned by the candidate.

- a) Successful candidates passing the examinations and earning CGPA between 9.5 and 10.0 shall be given Letter Grade (O+), those who earned CGPA between 9.0 and 9.4 shall be given Letter Grade (O) and declared to have First Class –Exemplary*.
- b) Successful candidates passing the examinations and earning CGPA between 7.5 and 7.9 shall be given Letter Grade (D), those who earned CGPA between 8.0 and 8.4 shall be given Letter Grade (D+), those who earned CGPA between 8.5 and 8.9 shall be given Letter Grade (D++) and declared to have First Class with Distinction*.
- c) Successful candidates passing the examinations and earning CGPA between 6.0 and 6.4 shall be given Letter Grade (A), those who earned CGPA between 6.5 and 6.9 shall be given Letter Grade (A+), those who earned CGPA between 7.0 and 7.4 shall be given Letter Grade (A++) and declared to have First Class.

- d) Successful candidates passing the examinations and earning CGPA between 5.0 and 5.4 shall be given Letter Grade (B), those who earned CGPA between 5.5 and 5.9 shall be given Letter Grade (B+) and declared to have passed in Second Class.
- e) Candidates those who earned CGPA between 0.0 and 4.9 shall be given Letter Grade (U) and declared to have Re-appear.
- f) Absence from an examination shall not be taken as an attempt.

CUMULATIVE GRADE POINT AVERAGE (CGPA) = $\Sigma_n \Sigma_i C_{ni} G_{ni} / \Sigma_n \Sigma_i C_{ni}$

CGPA = <u>Sum of the multiplication of Grade Points by the credits of the entire Programme</u>

Sum of the credits of the courses for the entire Programme

Where 'Ci' is the Credit earned for Course i in any semester; 'Gi' is the Grade Point obtained by the student for Course i and 'n' refers to the semester in which such courses were credited.

CGPA (Cumulative Grade Point Average) = Average Grade Point of all the Courses passed starting from the first semester to the current semester.

Note: * The candidates who have passed in the first appearance and within the prescribed Semesters of the PG Programme are alone eligible for this classification.

Maximum duration of the completion of the programme

The maximum period for completion of M.Sc.,/ M.A.,/ M.B.A/ B.Ed.,/ M.Ed.,/ B.P.Ed/ M.P.Ed in ------- shall not exceed eight semesters continuing from the first semester.

Conferment of the Master's Degree

A candidate shall be eligible for the conferment of the Degree only after he/ she has earned the minimum required credits for the Programme prescribed there for (i.e. 90 credits). Programme).

Village Extension Programme

The Sivaganga and Ramnad districts are very backward districts where a majority of people Lives in poverty. The rural mass is economically and educationally backward. Thus the aim of the introduction of this Village Extension Programme is to extend out to reach environmental awareness, social activities, hygiene, and health to the rural people of this region. The students in their third semester have to visit any one of the adopted villages within the jurisdiction of Alagappa University and can arrange various programs to educate the rural mass in the following areas for three day based on the theme.1. Environmental awareness 2. Hygiene and Health. A minimum of two faculty members can accompany the students and guide them.

M.Sc., -Materials Science- Programme Structure

S. No	Paper Code		Title of the paper	T/P	Credit	ts Hours/ Week	Mark	S	
			I Semester			1	I	E	Total
1	542101	Core 1	Materials Physics	Т	5	5	25	75	100
2	542102	Core 2	Thermodynamics	Т	5	5	25	75	100
3	542103	Core 3	Electronics and Instrumentation	T	4	4	25	75	100
4	542104	Core 4	Electromagnetic Theory and Optics	T	4	4	25	75	100
6	542105	Core 5	Lab-I : Electrical and Optical Characterization	P	4	8	25	75	100
7		Disciplin	e Specific Elective (DSE) – I	T	3	3	25	75	100
		Library /	Yoga/ Counselling/Field trip			1			
	l				25	30	150	450	600
II Sen	nester			'	· ·	'			
8	542201	Core 6	Materials Chemistry	T	4	4	25	75	100
9	542202	Core 7	Characterization of Materials	T	4	4	25	75	100
10	542203	Core 8	Quantum Mechanics	Т	4	4	25	75	100
11	542204	Core 9	Crystal Growth	T	4	4	25	75	100
12	542205	Core 10	Lab-II: Materials Synthesis and Characterization	P	4	8	25	75	100
13		Discipline	e Specific Elective (DSE) - II	T	3	3	25	75	100
14			or Elective :1	T	2	3	25	75	100
15			ing course (SLC) –MOOCs**		Extra	1			
		1		10	25	30	175	525	700
III Se	mester		N/ AND	N/S					
15	542301	Core 11	Nanomaterials	T	4	4	25	75	100
16	542302	Core 12	Polymer and Composite Materials	T	4	4	25	75	100
17	542303	Core 13	Solid State Physics	T	4	4	25	75	100
18	542304	Core 14	Ceramic Materials	T	4	4	25	75	100
19	542305	Core 15	Lab-III: Device Characterization	P	4	8	25	75	100
20			e Specific Elective (DSE) – III	T	3	3	25	75	100
21			or Elective:2	T	2	3	25	75	100
22		Self-learn	ing course (SLC) –MOOCs**		Extra o				
			Contain the San		25	30	175	525	700
IV Se	mester								
23	542999	Core 16	***Project Dissertation Work or Internship programme	P	15	30	50	150	200
					15	30	50	150	200
			Tota	ıl	90 +		550	1650	2200

^{*}DSE – Discipline Specific Elective.

T-Theory

P-Practical

^{**}SLC- Voluntary basis

^{***} Dissertation / internship report –Marks -Vivo-voce (50) + thesis (100) + internal (50) = 200

Non-Major Elective-Courses offered to the other Department

S.	Paper	Semester	Title of the paper	Credits	Hours/	Ma	ırks	
No.	Code				Week	I	E	T
1	542701	II	Electronics for Daily Life	2	3	25	75	100
2	542702	II	Food Chemistry	2	3	25	75	100
3	542703	III	Nanomaterials Biosensors	2	3	25	75	100
4	542704	III	Green Chemistry	2	3	25	75	100

DISCIPLINE SPECIFIC ELECTIVE (DSE)

No.	Code	Title of the Course	No. of Credits	Contact Hours
I SEN	MESTER	: ILII	1	
1	542501	Biomaterials	3	3
2	542502	Molecular Electronics	3	3
3	542503	Non-Destructive Testing	3	3
4	542504	Nonlinear Optics and Materials	3	3
5	542505	Laser and Applications	3	3
6	542506	Python Programming	3	3
	1	II SEMESTER		
7	542507	Molecular Spectroscopy	3	3
8	542508	Semiconductor Materials and Devices	3	3
9	542509	Physical Metallurgy	3	3
10	542510	Materials Processing	3	3
11	542511	Corrosion Science and Engineering	3	3
12	542512	Solid State Ionics	3	3
	1	III SEMESTER		
13	542513	Biosensors	3	3
14	542514	Bioelectronics	3	3
15	542515	Chemical Sensors	3	3
16	542516	Thin Film Science and Technology	3	3
17	542517	Superconducting Materials and Applications	3	3

Core 1		I-SEMESTER			
	Course code:542101	Materials Physics	T	Credits: 5	Hours:5
		Unit - I			
-	_	ots of various mechanical test and pl			
		formation by slip – the shear streng			
		rengthening against plastic yield – C	_		
ductile fracti	ıre – brittle fracture – Griff	ith criterion – fracture toughness – fat	igue fr	acture - mechar	nical tests -
tensile, hardı	ness and creep tests.				
Outcome 1	Students gain knowleds	ge in mechanical tests and plastic de	format	tion	K2
Outcome 1	mechanisms.				
		Unit - II			
Objective 2	To introduce various di	electric materials and application.			
Dielectric P	roperties - Dielectric const	tant and polarizability - different kinds	s of po	larization - Inte	rnal electri
field in a die	lectric -Clausius- Mossotti	equation - dielectric in a ac field - die	electric	c loss - ferroele	ctric - type
and models	of ferro electric transition	n - electrets and their applications -	– piez	oelectric and p	yroelectric
materials.					
	Students know the appli	ication and various properties of die	lectric	materials.	
Outcome 2		7 150 50 50 50 50 50 50 50 50 50 50 50 50 5			K4
		Unit - III			
Objective 3	To expose different type	es of magnetic materials and proper	ties.		
		of magnetic materials- origin of m		sm – Langevii	nand Weis
_	•	netic anisotropy - magnetic domains	-	•	
		ite structure and uses - magnetic bubl		-	-
	ilute magnetic semiconduct	The state of the s		C	
	Learners make use of fu	undamental magnetic materials prop	erties	and their	
Outcome 3	application.				K4
		Unit - IV			
Objective 4	To study the properties	of various optical materials, LED a	nd LC	D and applicat	ions.
		n in insulators, semiconductors and m			
_		ction luminescence and LEDs- LED m			_
		nd structure - liquid crystal displays-co		•	
	1 7 1 1	1 3			
displays.	Learners gain knowledg	ge of optical materials properties and	l annli	cations.	K2
displays.	Learners gain knowledg	ge of optical materials properties and	l appli	cations.	K2
displays. Outcome 4	To make the students up	Unit - V			
displays.	To make the students u	Unit - V nderstand about various properties of			
Outcome 4 Objective 5	To make the students unmemory alloys CCD and	Unit - V nderstand about various properties of d nanomaterials and applications.	of sma	rt materials, sh	ıape.
Outcome 4 Objective 5	To make the students unmemory alloys CCD and	Unit - V nderstand about various properties of nanomaterials and applications. ses - preparation, properties and applications.	of sma	rt materials, sh	materials
Outcome 4 Objective 5 Advanced I	To make the students unmemory alloys CCD and Materials - Metallic glass, magneto strictive, electrons	Unit - V Inderstand about various properties of dinanomaterials and applications. Ses - preparation, properties and applicative materials - shape memory is	of sma	rt materials, sh ons - SMART - rheological fl	materials
Objective 5 Advanced In piezoelectric device mate	To make the students unmemory alloys CCD and Materials - Metallic glass, magneto strictive, electronials and applications - so	Unit - V Inderstand about various properties of annomaterials and applications. Sess - preparation, properties and applicative materials - shape memory solar cell materials (single crystalling)	of sma	rt materials, sh ons - SMART - rheological fl	materials
Objective 5 Advanced In piezoelectric device mate	To make the students up memory alloys CCD and Materials - Metallic glass, magneto strictive, electronials and applications - set to nanoscale materials and	Unit - V Inderstand about various properties of dinanomaterials and applications. Independent of the properties and applicative materials and applicative materials and applicative materials. The properties are considered in the properties.	of sma plicationalloys e, amo	rt materials, shons - SMART - rheological fl rphous and thi	materials
Objective 5 Advanced In piezoelectric device mate	To make the students unmemory alloys CCD and Materials - Metallic glass, magneto strictive, electrorials and applications - set to nanoscale materials and Learners understand the	Unit - V Inderstand about various properties of annomaterials and applications. Independent of the second	of sma	rt materials, shons - SMART - rheological fl rphous and thi	materials
Objective 5 Advanced In piezoelectric device mate introduction Outcome 5	To make the students unmemory alloys CCD and Materials - Metallic glass, magneto strictive, electrorials and applications - setto nanoscale materials and Learners understand the preparation methods for	Unit - V Inderstand about various properties of dinanomaterials and applications. Independent of the properties and applicative materials and applicative materials and applicative materials. The properties are considered in the properties.	of sma	rt materials, shons - SMART - rheological fl rphous and thi	materials uids - CCI n films) -
Objective 5 Advanced I piezoelectric device mate introduction Outcome 5 Suggested R	To make the students up memory alloys CCD and Materials - Metallic glass, magneto strictive, electrorials and applications - so to nanoscale materials and Learners understand the preparation methods for eadings:-	Unit - V Inderstand about various properties of nanomaterials and applications. Independent of the properties and applicative materials - shape memory polar cell materials (single crystalling their properties. In the properties of the properties and applications are nanomaterials and their properties.	of sma plication	rt materials, shons - SMART - rheological flrphous and thinks	materials uids - CCl n films) -
Objective 5 Advanced I piezoelectric device mate introduction Outcome 5 Suggested R Kasap S.O.	To make the students unmemory alloys CCD and Materials - Metallic glass, magneto strictive, electronials and applications - so to nanoscale materials and Learners understand the preparation methods for eadings:- (2019). Principles of Electronials	Unit - V Inderstand about various properties of nanomaterials and applications. Independent of the properties and application of the properties and application of the properties and application of the properties. Independent of the properties	of sma plication alloys e, amo materia	rt materials, shons - SMART - rheological flrphous and thinks and	materials uids - CCI n films) -
Objective 5 Advanced In piezoelectric device mate introduction Outcome 5 Suggested R Kasap S.O. OtsukaK.	To make the students unmemory alloys CCD and Materials - Metallic glass, magneto strictive, electrorials and applications - so to nanoscale materials and Learners understand the preparation methods for eadings:- (2019). Principles of Electrond WaymanC.M. (1998).	Unit - V Inderstand about various properties of nanomaterials and applications. Independent of the properties and applicative materials - shape memory polar cell materials (single crystalling their properties. In the properties of the properties and applications are nanomaterials and their properties.	of sma plication alloys e, amo materia . V-Hill I	rt materials, shons - SMART - rheological fl rphous and thi als and Education. esity Press.	materials uids - CCl n films) -

Online resources:-

Understanding the physical properties of hybrid perovskites for photovoltaic applications. Nat Rev Mater 2, 17042 (2017). https://doi.org/10.1038/natrevmats.2017.42

A review on metallic porous materials: pore formation, mechanical properties, and their applications. Int J Adv Manuf Technol 95, 2641–2659 (2018). https://doi.org/10.1007/s00170-017-1415-6.

A review of shape memory alloy research, applications and opportunities, 56, 2014, 1078-1113, https://doi.org/10.1016/j.matdes.2013.11.084

K1-Remember	K2-Understand	K3-Apply	X3-Apply K4-Analyse		K6-Create
			Cours	e Designed by: Dr	. J. Wilson

Course Outcome

CO 1	Understand the basic principles of materials	K1, K2
CO 2	Gain the knowledge of various behaviors of materials	K2, K3
CO 3	Understand and design the material based on their properties	K5
CO 4	Expertise in learning the specified material for different application	K3, K4
CO 5	Explore the knowledge of sustainable material for device fabrication	K1, K6

Course outcome Vs Programme outcomes

A ALAGAPPA UNIVERSITY

PO/CO	PO 1	PO 2	PO 3	PO 4	PO 5	PO 6	PO 7	PO 8	PO 9	PO 10
CO 1	S (3)	S (3)	S (3)	L(1)	L (1)	L(1)	M (2)	M (2)	S (3)	S (3)
CO 2	S (3)	S (3)	S (3)	L(1)	L (1)	L(1)	S (3)	M (2)	S (3)	S (3)
CO 3	S (3)	S (3)	S (3)	M (2)	S (3)	M (2)	M (2)	L(1)	S (3)	S (3)
CO 4	S (3)	S (3)	S (3)	M (2)	M (2)	M (2)	M (2)	S (3)	S (3)	M (2)
CO 5	M (2)	M (2)	S (3)	S (3)	M (2)	L(1)	L(1)	S (3)	M (2)	S (3)
W. AV	2.8	2.8	3	1.8	1.8	1.4	2	2.2	2.8	2.8

S – Strong (3), M-Medium (2), L-Low (1)

Course Outcome Vs Programme Specific Outcome

PSO/CO	PSO 1	PSO 2	PSO 3	PSO 4	PSO 5
CO 1	S (3)	M (2)	M (2)	L (1)	S (3)
CO 2	S (3)	S (3)	M (2)	M (2)	S (3)
CO3	S (3)	M (2)	S (3)	M (2)	S (3)
CO 4	S (3)	M (2)	M (2)	S (3)	S (3)
CO 5	S (3)	M (2)	M (2)	M (2)	M (2)
W. AV	3	2.2	2.2	2	2.8

			I-SEMESTER					
Core 2	Co	ourse code:542102	Thermodynamics	Т	Credits: 5	Hours: 5		
	'		Unit - I	'		'		
Object		mechanics	nical aspects of systems and ma					
			NIAN DYNAMICS-Mechanics	_	•	-		
			Generalized coordinates -Virtua			-		
	-	•	ic co-ordinates - Hamilton's eq	uations of m	notion -Euler	Lagrange		
equation	- Princ	ciple of least action.						
Outco	me 1		basics of Lagrangian and Ham	•	amics that	K1		
		provides deeper unde	rstanding in classical mechanic	S				
		1	Unit - II					
Object	tive 2	To discover the common system using canonical	non abstractions and mechanismal forms.	ms greatly fa	cilitates the c	omplex		
CANON	NICAL	TRANSFORMATIC	ON, BRACKETS AND RIGID	BODY- Car	nonical transf	ormation –		
Generati	ng fun	ctions - Poisson brack	tets - Lagrange brackets - Rela	tion between	Lagrange a	nd Poisson		
			dynamics: Euler's anglesAngi	ular velocity	 Principal n 	noment of		
inertia -K	Cinetic	energy.	USD (FIGURE)					
Outco	me 2	Learners understand applications of Canonical Transformations in defining movement of particles using different coordinates and laws of motion						
		Sk	Unit - III	10		'		
Object	tive 3	To understand the conequilibria.	ncepts laws of thermodynamics	its applicati	ons and phas	e		
THERM	10DY		er <mark>modynamics- internal</mark> energy	- Enthalpy-	Entropy- Hel	mholtz and		
Gibbs fr	ee ene	rgies – Thermodynami	c <mark>relations – Euler e</mark> quation – M	faxwell's rel	ations and ap	plications -		
Chemica	al Pote	ntial- Gibbs phase rule	- phase equilibria (single and n	nulticompone	ent systems) -	Clausius -		
Claypero	on equa	ntion – law of mass action	o <mark>n</mark> – fir <mark>st o</mark> rder pha <mark>se t</mark> rans <mark>iti</mark> on ii	n single comp	onent system	s – Second		
order pha	ase trai	nsition.		ATTEN				
Outco	me 3		plic <mark>ation of laws of therm</mark> odyna efriger <mark>at</mark> ors, air con <mark>di</mark> tioners	mi <mark>cs in d</mark> esi	gning	K1, K2, K3		
		100	Unit - IV			<u>'</u>		
Object	tive 4	To understand the sta	ntistical mechanics of systems, p	robability d	istribution la	ws		
CLASSI	ICAL .	AND QUANTUM ST	ATISTICS - Micro and Macro S	States - Enser	nbles - Micro	canonical,		
canonica	al and	grand canonical enser	mbles – Maxwell – Boltzmann	, Bose- Eins	stein and Fer	mi-Dirac		
statistics	- Con	nparison of MB, BE an	d FD statistics.					
04	4	Learners get knowled	lge on the applications of Maxv	vell, Boltzma	nn Fermi	V2 V5		
Outco	me 4	Dirac statistical in the	ermodynamical methods			K3, K5		
		1	Unit - V			<u>'</u>		
Object	tive 5	To analyze the applic physics.	ations of statistical thermodyna	amical metho	ods in solid st	ate		
APPLIC	CATIC	ON OF STATISTICS -	Planck's Radiation law – Stefan	-Boltzmann	law – Einsteii	n model of		
			al partition function and classical	_	Equipartition	theorem –		
Semicon	ductor	statistics - Statistical ed	quilibrium of electrons in semicor	nductors.				
•	me 5	Students gain knowle	edge on the application of statis	tics in practi	ce.	K5, K6		
		eadings:-						

Online resources:-

(http://hyperphysics.phy-astr.gsu.edu/hbase/thermo.html)

 $(\underline{https://www.engineeringmindset.com/thermodynamics-explained/})$

(https://www.youtube.com/watch?v=7KXV7omzP6I)

K1-Remember	K2-Understand	K3-Apply	K3-Apply K4-Analyse		K6-Create				
Course designed by: Dr. V. Dharuman									

Course Outcome

CO 1	Understand the basics of Lagrangian and Hamiltonian dynamics that provides deeper understanding in classical mechanics	K1
CO 2	Defining applications of Canonical Transformations in defining movement of particles using different coordinates and laws of motion	K1, K2
CO 3	Understand the application of laws of thermodynamics in designing automobile engines, refrigerators, air conditioners	K1, K2, K3
CO 4	Get knowledge on the applications of Maxwell, Boltzmann Fermi Dirac statistical in thermodynamical methods	K3, K5
CO 5	Gain knowledge on the application of statistics in practice.	K5, K6

Course outcome Vs Programme outcome

PO/ CO	PO 1	PO 2	PO 3	PO 4	PO 5	PO 6	PO 7	PO 8	PO 9	PO 10
CO 1	M (2)	S (3)	S (3)	M (2)	L(1)	M (2)	M (2)	S (3)	M (2)	M (2)
CO 2	L (1)	M (2)	M (2)	L(1)	M (2)	L (1)	M (2)	M (2)	M (2)	L(1)
CO 3	S (3)	M (2)	L (1)	M (2)	M (2)	L(1)	M (2)	S (3)	L(1)	L(1)
CO 4	S (3)	M (2)	M (2)	L(1)	M (2)	S (3)	M (2)	M (2)	M (2)	L(1)
CO 5	L (1)	L (1)	L(1)	L(1)	M (2)	L(1)	S (3)	M (2)	M (2)	L(1)
W. AV	2	2	1.8	1.6	1.8	1.6	2.2	2.4	1.8	1.2

S – Strong (3), M-Medium (2), L-Low (1)

Course Outcome Vs Programme Specific Outcome

PSO/CO	PSO 1	PSO 2	PSO 3	PSO 4	PSO 5
CO 1	S (3)	S (3)	M (2)	L(1)	L (1)
CO 2	M (2)	S (3)	M (2)	M (2)	M (2)
CO3	S (3)	M (2)	L(1)	L(1)	M (2)
CO 4	L (1)	M (2)	M (2)	M (2)	L (1)
CO 5	M (2)	L(1)	M (2)	L(1)	M (2)
W. AV	2.1	2.1	1.8	1.2	1.6

S – Strong (3), M-Medium (2), L-Low (1)



I-SEMESTER					
	e code :542103	Electronics an	d Instrumentation	T Credits:	4 Hours: 4
		Unit			
Objective 1 To	understand the con	cept of analog	electronics		
				op-amp parameter	rs-feedback-
	_	_		ters – instrumentatio	
_	– OTAs –Voltage re	_			1
Outcome 1 Get	ting Knowledge in	analog amplifie	ers and their funct	ions	K1, K2
		Unit			,
Objective 2 To	gain knowledge in	advanced conc	epts of digital elec	tronics	
DIGITAL ELECT	RONICS- Introduc	ction – overviev	v of logic function	s and logic gates – co	ombinational
logic – flip-flops ar	nd related circuits -	sequential logi	c – registers, coun	ters, shift-registers a	and memory -
microprocessor arch	nitecture – A/D and I	D/A conversion.			
Outcome 2 Lea	rn the operational	principle of dig	ital amplifiers and	d their functions	K2, K3
		Unit	- III		
	learn concepts of o				
OPTOELECTRO	NICS- LEDs – ser	niconductor las	sers – photodiodes	s – solar cells – pho	otodetectors –
optical fibers – con	ımunication – optoe	electronic modu	lation and switchir	ng devices – optocou	pler- optical
data storage device		1317 6	008		
Outcome 3 Kno	owing the optical ap	pplications of so	emiconductors and	d their functions	K5
		Unit			
	understand knowle				
				system – transduce	
				- load cell - flow n	neters – signal
	acquisition and conv		The state of the s		
Outcome 4 Get	ting detailed idea o		All the second s	mental development	K3, K4
		Unit	- NO. A / T NO.		
	study b <mark>asic c</mark> oncept	The second secon	March Labor V. San San San Labor Lab		
			- Table 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1	ures - resonant tunne	_
_		ular switches an	id memory storage	- nano-electromech	anıcal systems
- quantum dot cellu					
	owing the recent ad	vancement in t	ransistor applicat	ions	K1, K6
Suggested Readin		0 1 1 1 :	D : D	E1	
` `	2019). <i>Semiconducto</i> C. AandKuh E.S. (
	,	,		niques. Prentice Hall	of India
	Electronic devices.			iiques. I tentice Han	or mara.
1	09). Fundamentals o			ion Inc.	
\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	ill W. (2006). <i>Art of</i>	,			
	Electronic Instrume				
Online resources					
All About Circui	ts (<u>https://www.allal</u>	ooutcircuits.com	<u>/</u>)		
1		onioshuh ora/\	Flectronics Hub of	fers a wide range of	
Electronics Hub	(https://www.electr	omesmub.org/)	Licenomics fruo of	rero a mrae range or	electronics
	(https://www.electr , and guides, includi			•	electronics
tutorials, projects,	and guides, includi	ng instrumentat	tion-related conten	t.	
tutorials, projects, Adafruit Blog (h	and guides, includi	ng instrumentat com/) Adafruit	tion-related content is a prominent ele	t. ectronics manufactur	er, and their
tutorials, projects. Adafruit Blog (harmonic blog features tutorials)	and guides, includi https://blog.adafruit. rials, project ideas, a	ng instrumentat com/) Adafruit and product rev	ion-related content is a prominent ele iews related to elec	t. ectronics manufacture etronics and instrume	er, and their
tutorials, projects, Adafruit Blog (h	and guides, includi	ng instrumentat com/) Adafruit	tion-related content is a prominent ele	t. ectronics manufactur	rer, and their entation.

Course Outcome

CO 1	Analyze and design circuits for signal processing and amplification	K1, K2
CO 2	Design and implement digital circuits using logic components.	K2, K3
CO 3	Understand and design optoelectronic devices and systems.	K5
CO 4	Apply electronic measurement techniques and design data acquisition systems.	K3, K4
CO 5	Explore nanoscale electronic devices, fabrication techniques, and design principles.	K1, K6

Course outcome Vs Programme outcomes

PO/CO	PO 1	PO 2	PO 3	PO 4	PO 5	PO 6	PO 7	PO 8	PO 9	PO 10
CO 1	S (3)	M (2)	S (3)	M (2)	M (2)	S (3)	L (1)	M (2)	L (1)	M (2)
CO 2	S (3)	M (2)	M (2)	S (3)	S (3)	S (3)				
CO 3	M (2)	M (2)	S (3)	S (3)	S (3)	M (2)	M (2)	L(1)	L (1)	S (3)
CO 4	S (3)	S (3)	S (3)	S (3)	M (2)	M (2)	L(1)	M (2)	M (2)	M (2)
CO 5	M (2)	S (3)	S (3)	S (3)	S (3)	L (1)	L (1)	S (3)	S (3)	S (3)
W. AV	2.6	2.6	3	2.8	2.6	2	1.4	2.2	2	2.6

S – Strong (3), M-Medium (2), L- Low (1)

Course Outcome Vs Programme Specific Outcome

PSO/ CO	PSO 1	PSO 2	PSO 3	PSO 4	PSO 5
CO 1	S (3)	M (2)	M (2)	S (3)	S (3)
CO 2	S (3)	S (3)	M (2)	M (2)	S (3)
CO3	M (2)	M (2)	S (3)	M (2)	S (3)
CO 4	L (1)	M (2)	M (2)	S (3)	S (3)
CO 5	M (2)	M (2)	M (2)	S (3)	S (3)
W. AV	2.2	2.2	2.2	2.6	3

S – Strong (3), M-Medium (2), L- Low (1)

		I-SEMESTER		
Core 4	Course code:542104	Electromagnetic Theory and Optics	T Credits: 4	Hours: 4
		Unit - I		
Objective i	To know the fundament situations.	als of Maxwell's equations are their a	pplications in dif	fferent
		view of Gauss's law in electrostatics and	-	•
Faraday'sla	w -displacement current	- Maxwell's equations - differential an	nd integral forms	- scalar and
vector pote	ntials and applications Po	tential due to a uniformly charged spher	e - magnetic indu	ctiondue to
a current ca	rrying wire.			
Outcome 1	Derive Maxwell's equa magneto statics.	tions and apply them to study the elec	trostatics and	K1, K2
		Unit - II		
Objective 2	To get insight on fundar	nental laws of optics and its relation w	vith Maxwell's E	quation
ELECTRO	OMAGNETIC WAVE	PROPAGATION - Plane electromag	netic waves in fro	ee surface -
	_	edance - wave equation in an isotropic		_
insulators a	and conductors - reflection	on by a perfect conductor - normal and	oblique incidenc	e - Fresnel
equations for	or parallel and perpendicu	llar polarization.		
Outcome 2		conditions between different materials based on Maxwell's equations	s and reflection	K2, K3
		Unit - III		
Objective 3	To Study the novel calcoproperties	ilus of tensors and illustrate their usa	ge in different Ma	aterial
CRYSTAI	OPTICS - Crystal sym	metry-Light propagation in anisotropic	media – Maxwell	's equations:
the constitu	tiverelation -Index ellips	oid <mark>– w</mark> ave plates – <mark>Biaxi</mark> al media: Opt	ic axes – positive	and negative
crystals - E	Electrical conductivity ter	s <mark>or stress optic te</mark> nsor <mark>s -</mark> third rank t	ensors – Linear E	Electro-optic
effect - Fou	orth rank tensors: third ord	le <mark>r suscepti</mark> bili <mark>ty</mark> te <mark>nsor. 🌎 💮 💮 💮</mark>		
Outcome 3		ensors in determining crystal symmetroperties of materials like elastic properties of the elasti		K3, K4
		Unit - IV		
Objective 4	Understand the various	optical activities and their application	s in material	
-	characterization			
OPTICAL	ACTIVITY- Optical I	Polarization – Magneto-optical effects	- Magneto-optic	al Kerr and
Faraday ef	fect - Kerr andPockel ef	fect - applications - Harmonics and su	um & frequency	generation -
stimulated	Brillouin scattering (SBS)	- stimulated Raman scattering (SRS) -	applications of SF	BS and SRS
for material	characterization – examp	les.		
Outcome 4	Elucidate how optical a to further characterize	ctivities occur in materials and how the materials.	hey can be used	K2, K4
		Unit - V		
Objective 5	To know the basics of n	on-linear optical effects and non-linea	r optical materia	ls
		nd applications of non-linear effects - fi		
		cal bistability - nonlinear optical materi		_
and applica		-	-	
Outcome 5		entals of Non-linear optical effects, the properties, and their applications	e nature of	K3, K5

Suggested Readings:-

Corson D. and Lorrain P. (2013). *Introduction to Electromagnetic Fields and Waves*, Literary Licensing, LLC.

FleischD. (2008). A student's Guide to Maxwell's Equations. Cambridge University Press.

Griffiths D.J. (2015). Introduction to Electrodynamics. Pearson Education.

Jordan E. Cand Balmain K.G (2015). Electromagnetic Waves and Radiating Systems. Pearson Education.

New G. (2014). Introduction to Nonlinear Optics, Cambridge University Press.

Online resources:-

Walter Lewin's MIT Lectures on Electricity and Magnetism

(https://www.youtube.com/playlist?list=PLyQSN7X0ro203puVhQsmCj9qhlFQ-As8e)

NPTEL - Electromagnetic Theory (https://nptel.ac.in/courses/115/105/115105132/)

Optics 101 - Crash Course Physics (https://www.youtube.com/watch?v=8Jr-8 pgnq8)

K1-Remember	K2-Understand	K3-Apply	K4-Analyse	K5-Evaluate	K6-Create
			Course d	esigned by: Dr. S. S	aravana kumar

Course Outcome

CO 1	Attain proficiency in theory of magnetism and magnetic induction.	K1, K2
CO 2	Understand the boundary behavior and condition of EM waves.	K2, K3
CO 3	Appreciate the advanced properties of materials.	K3, K4
CO 4	Elucidate optical activities occur in materials.	K2, K4
CO 5	Learn about the nonlinear optics theory and materials.	K3, K5

Course outcome Vs Programme outcomes

PO/CO	PO 1	PO 2	PO 3	PO 4	PO 5	PO 6	PO 7	PO 8	PO 9	PO 10
CO 1	M (2)	S (3)	M (2)	M (2)	M (2)	S (3)				
CO 2	S (3)	S (3)	S (3)	M (2)	M (2)	S (3)	S (3)	M (2)	M (2)	S (3)
CO 3	M (2)	M (2)	S (3)	S (3)	M (2)	S (3)	S (3)	M (2)	M (2)	S (3)
CO 4	S (3)	M (2)	M (2)	M (2)						
CO 5	S (3)	M (2)	M (2)	M (2)						
W. AV	2.6	2.8	3	2.8	2.6	3	2.8	2	2	2.6

S-Strong (3), M-Medium (2), L-Low (1)

Course Outcome Vs Programme Specific Outcome

PSO/ CO	PSO 1	PSO 2	PSO 3	PSO 4	PSO 5
CO 1	M (2)	S (3)	L (1)	L (1)	L (1)
CO 2	M (2)	S (3)	M (2)	L (1)	L (1)
СОЗ	M (2)	S (3)	M (2)	M (2)	M (2)
CO 4	S (3)	S (3)	S (3)	M (2)	M (2)
CO 5	M (2)	S (3)	M (2)	M (2)	M (2)
W. AV	2.2	3	2.0	1.8	1.8

S – Strong (3), M-Medium (2), L-Low (1)



Core 5	Course code 542105	LAB I Electrical and Optical Characterization	P	Credits: 4	Hours: 8							
	The main chie	ective of the course is to impart knowledge	on des	ian and math	adalagy for							
		of various optical and electrical properties		-								
-	course is design		01 111	ateriais. III a	iddition, the							
š	_	the students realise the importance of investi	antina	material prop	arties							
ecti		uce the concepts of various optical technique	_	шастаг ргор	erties							
Objectives	 c. To introduce the students about various electrical materials and their application. d. To expose the students to magnetic materials and their properties. e. To educate electrochemical behaviour of materials and their characterization 											
		gap determination. UV-visible spectrometri			OII							
	-	escence properties of metal oxides	. IIICIII	.ou								
		e characterization of polymers										
		e spectral behavior of organic polymers										
		e properties of carbon materials										
		e properties of metal composites										
		onductivity of metals and alloys with tempera	ture_fo	our probe met	hod							
		Determination of Hall co-efficient, charge ca		•								
		sceptibility-Quincke's method.	111101	ionsity and m	conity.							
	_	owth-Solution technique.										
	,	owth-Gel technique.										
	•	icity – Hysteresis loop - coercivity, retentivit	v and	saturation may	enetization							
		diffraction - using laser	,		5.1.6.117.01.1.1							
		ammetric characterization of electrode mater	ials									
		nical im <mark>pe</mark> dance characterization of electrod		rolvte interfac	e							
		perometric technique for analyte detection us		•								
	_	pulse voltammetric analysis of analyte using	_									
-		pletion of the course, students come famili			periments to							
Outcome		optical and electrical properties of materi		-								
 	_	nd the importance of investigating material			_							
Ő	-	ty and potential application of the materials.	- •									

		I-SEMESTER			
DSE C	Course code :542501	Biomaterials	T	Credits: 3	Hours: 3
•	1	Unit I	'	1	
Objective 1	To introduce the res biomaterials.	ponse of biomaterials to	host enviror	nment, and host	response to
BIOLOGICA	L PERFORMANCE (OF MATERIALS -Bioc	ompatibility	- introduction to	the biologica
environment –	material response: swel	lling and leaching, corrosi	on and disso	olution, deforma	tion and failure
friction and we	ear – host response: the	e inflammatory process -	coagulation	and hemolysis-	approaches to
thrombo- resista	ant materials developmen	nt.			
Outcome 1	_	onse of biomaterials envi the material, and host res			K1/K5
	1	Unit II			
Objective 2	To introduce variou	s materials used in bone	and joint re	placement	
ORTHOPAEI	DIC MATERIALS - E	Bone composition and pro	perties - ter	nporary fixation	devices - joir
replacement -	biomaterials used in bo	one and joint replacement	: metals and	l alloys – stainle	ess steel, coba
based alloys, tit	tanium based materials	- ceramics: carbon, alumi	na, zirconia	, bioactive calci	ım phosphates.
bioglass and gla	ass ceramics – polymers	: PMMA, UHMWPE/HDI	PE, PTFE – ł	one cement – co	omposites
Outcome 2	Understand the biomareplacement.	aterials of metals/alloys u	sed in bone	and joint	K3/K4
	гершеенен	Unit III	6		
Objective 3	To gain knowledge a	about materials used in ca	ardiovascula	r imnlants	
	The state of the s	S-Blood clotting – blood			ne heart – aorta
		lation – the lungs - vascu			
_	•	d s <mark>ubstitutes – extrac</mark> orpor		_	
Outcome 3		en <mark>ta</mark> ls of nano-electronic	1		K3/K5
		Unit IV	0	-	
Objective 4	To know about dent	al materials and dental in	nnlants		
•	(1900 x 200)	position and mechanical		impression ma	terials – bases
		ings and restoration mate	AND THE RESERVE	_	
		algams – dental adhesives		riais for oral air	
		hanical properties of den			K1/K5
		Unit V		<u>-</u>	
Objective 5	To impart knowledg	ge on soft tissue and drug	delivery ma	nterials.	
· ·		materials in ophthalmolo	•		contact lenses
		fts – skin grafts – connec			
	_	and materials – selection	_		
	r implantable sensors.		-		
Outcome 5		naterials used for ophthal	lmology.		K2/K5
Suggested Rea		1	Θv		
	•	nce of Materials: Fundame	entals of Bio	compatibility. N	Iarcel Dekker
Inc, New Yor	-		51 210	<u>F</u>	
•		terials. A Basic Introduction	on. CRC Pre	SS.	
=	• • • • • • • • • • • • • • • • • • • •	An Introduction Springs			

ParkJ.&LakesR.S. (2010).Biomaterials: An Introduction. Springer. RatnerB.D,

Hoffman A.S, SchoenF.J.&LemonsJ.E. (2004). Biomaterials Science: An Introductionto Materials in Medicine. Academic Press.

Online Resources:-

 $\frac{\text{http://acikerisim.btu.edu.tr/xmlui/handle/20.500.12885/1157\#:\sim:text=https\%3A//hdl.handle.net/20.500.12885/1157\#:\sim:text=https\%3A//hdl.handle.net/20.500.12885/1157\#:\sim:text=https\%3A//hdl.handle.net/20.500.12885/1157\#:\sim:text=https\%3A//hdl.handle.net/20.500.12885/1157\#:\sim:text=https\%3A//hdl.handle.net/20.500.12885/1157\#:\sim:text=https\%3A//hdl.handle.net/20.500.12885/1157\#:\sim:text=https\%3A//hdl.handle.net/20.500.12885/1157\#:\sim:text=https\%3A//hdl.handle.net/20.500.12885/1157\#:\sim:text=https\%3A//hdl.handle.net/20.500.12885/1157\#:\sim:text=https\%3A//hdl.handle.net/20.500.12885/1157\#:\sim:text=https\%3A//hdl.handle.net/20.500.12885/1157\#:\sim:text=https\%3A//hdl.handle.net/20.500.12885/1157.$

https://mme.deu.edu.tr/wp-content/uploads/2017/10/biomaterials.pdf.

K1-Remember	K2-Understand	K3-Apply	K4-Analyse	K5-Evaluate	K6-Create
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Course Outcome

CO 1	Analyze the response of biomaterials to host environment, Biocompatibility of the material, and host.	K1/ K3
CO 2	Design and understand the biomaterials of metals and alloys used in bone and joint replacement.	K3/ K4
CO3	Understand the fundamentals of nano-electronic devices and MEMS and selection of materials.	K3/K5
CO 4	Analyze the mechanical properties of impression material for dental implants.	K1/K5
CO 5	Explore the biomaterials used for ophthalmology.	K2/K5

Course outcome Vs Programme outcomes

PO/CO	PO 1	PO 2	PO 3	PO 4	PO 5	PO 6	PO 7	PO 8	PO 9	PO 10
CO 1	S (3)	M (2)	S (3)	M (2)	M (2)	S (3)	L(1)	M (2)	L(1)	M (2)
CO 2	S (3)	M (2)	M (2)	S (3)	S (3)	S (3)				
CO 3	M (2)	M (2)	S (3)	S (3)	S (3)	M (2)	M (2)	L(1)	L(1)	S (3)
CO 4	S (3)	S (3)	S (3)	S (3)	M (2)	M (2)	L (1)	M (2)	M (2)	M (2)
CO 5	M (2)	S (3)	S (3)	S (3)	S (3)	L(1)	L (1)	S (3)	S (3)	S (3)
W. AV	2.6	2.6	3	2.8	2.6	2	1.4	2.2	2	2.6

S – Strong (3), M-Medium (2), L-Low (1)

Course Outcome Vs Programme Specific Outcome

PSO/CO	PSO 1	PSO 2	PSO 3	PSO 4	PSO 5
CO 1	S (3)	M (2)	M (2)	S (3)	S (3)
CO 2	S (3)	S (3)	M (2)	M (2)	S (3)
CO3	M (2)	M (2)	S (3)	M (2)	S (3)
CO 4	L(1)	M (2)	M (2)	S (3)	S (3)
CO 5	M (2)	M (2)	M (2)	S (3)	S (3)
W. AV	2.2	2.2	2.2	2.6	3

S – Strong (3), M-Medium (2), L-Low (1)

DSE
Objective 1 To understand the molecular nanotechnology and its applications in electronic devices. INTRODUCTION TO NANOTECHNOLOGY -Background to nanotechnology: periodic table – atomic structure – molecules and phases – energy – molecular and atomic size – surface and dimensional space – Nanaomaterials-top down and bottom-up approaches. Outcome 1 Understand the molecular and atomic size of nanoparticles, top down and bottom-up approaches of nanomaterials. Unit II Objective 2 To introduce various materials used in bone and joint replacement CARBON NANOSTRUCTURES - Fullerenes – CNTs-types of nanotubes – formation of nanotubes – assemblies – purification of carbon nanotubes – electronic properties – synthesis of carbon nanotubes – carbon nanotube interconnects – carbon materials for required applications. Outcome 2 Select different carbon materials for required applications. Unit III Objective 3 To gain knowledge about materials used in cardiovascular implants. NANOELECTRONIC DEVICES-FUNDAMENTALS – Electrodes & contacts – functions – molecular electronic devices – first test systems – simulation and circuit design – fabrication; Future applications: MEMS – robots – random access memory – mass storage devices Outcome 3 Understand fundamentals of nano-electronic devices and MEMS and selection of materials Unit IV Objective 4 To know about dental materials and dental implants. MOLECULAR COMPUTERS - Molecular wires and switches. Biomolecular computer, molecular arrays as memory stores, DNA for molecular devices – DNA's ability to conduct electrical currents. Charge transfer rates in solution – molecules between nanofabricated electrodes Select molecules to construct conducting wires, rectify, switches and DNA conductors and their role in molecular computer and DNA molecular devices.
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MEMS – robots – random access memory – mass storage devices Outcome 3 Understand fundamentals of nano-electronic devices and MEMS and selection of materials Unit IV Objective 4 To know about dental materials and dental implants. MOLECULAR COMPUTERS - Molecular wires and switches. Biomolecular computer, molecular arrays as memory stores, DNA for molecular devices - DNA's ability to conduct electrical currents. Charge transfer rates in solution - molecules between nanofabricated electrodes Select molecules to construct conducting wires, rectify, switches and DNA conductors and their role in molecular computer and DNA molecular devices. K1/K5/K6
Outcome 3 selection of materials Unit IV Objective 4 To know about dental materials and dental implants. MOLECULAR COMPUTERS - Molecular wires and switches. Biomolecular computer, molecular arrays as memory stores, DNA for molecular devices - DNA's ability to conduct electrical currents. Charge transfer rates in solution - molecules between nanofabricated electrodes Select molecules to construct conducting wires, rectify, switches and DNA conductors and their role in molecular computer and DNA molecular devices. K1/K3/K5
Unit IV Objective 4 To know about dental materials and dental implants. MOLECULAR COMPUTERS - Molecular wires and switches. Biomolecular computer, molecular arrays as memory stores, DNA for molecular devices - DNA's ability to conduct electrical currents. Charge transfer rates in solution - molecules between nanofabricated electrodes Select molecules to construct conducting wires, rectify, switches and DNA conductors and their role in molecular computer and DNA molecular devices. K1/K5/K6
Objective 4 To know about dental materials and dental implants. MOLECULAR COMPUTERS - Molecular wires and switches. Biomolecular computer, molecular arrays as memory stores, DNA for molecular devices - DNA's ability to conduct electrical currents. Charge transfer rates in solution - molecules between nanofabricated electrodes Select molecules to construct conducting wires, rectify, switches and DNA conductors and their role in molecular computer and DNA molecular devices. K1/K5/K6
MOLECULAR COMPUTERS - Molecular wires and switches. Biomolecular computer, molecular arrays as memory stores, DNA for molecular devices - DNA's ability to conduct electrical currents. Charge transfer rates in solution - molecules between nanofabricated electrodes Select molecules to construct conducting wires, rectify, switches and DNA conductors and their role in molecular computer and DNA molecular devices. K1/K5/K6
memory stores, DNA for molecular devices - DNA's ability to conduct electrical currents. Charge transfer rates in solution - molecules between nanofabricated electrodes Select molecules to construct conducting wires, rectify, switches and DNA conductors and their role in molecular computer and DNA molecular devices. K1/K5/K6
rates in solution - molecules between nanofabricated electrodes Select molecules to construct conducting wires, rectify, switches and DNA conductors and their role in molecular computer and DNA molecular devices. K1/K5/K6
Outcome 4 Select molecules to construct conducting wires, rectify, switches and DNA conductors and their role in molecular computer and DNA molecular devices. K1/K5/K6
Outcome 4 DNA conductors and their role in molecular computer and DNA molecular devices. K1/K5/K6
molecular devices.
Unit V
Objective 5 To impart knowledge on soft tissue and drug delivery materials.
FLEXIBLE ELECTRONIC DEVICES - Electroactive organic molecules, Plastic Electronics, Electrical
conduction in ploymers, Donor molecules, Acceptor molecules, Optoelectronic devices: OLEDs, OTFTs.
Students select polymeric materials with suitable electrical and physical
Outcome 5 characteristics for desired electronic flexible devices in optoelectronics. K2/K5/K6
Suggested Readings :-
Swal D.K., Yakhmi J.V. (2010). Molecular and Organic Electronics Devices (Electrical Engineering
Developments) Ed. Nova Science Pub Inc; 1 edition.
Geoffrey J, Ashwell. (1992). Molecular Electronics, Ed., John Wiley & Sons Inc.
James M Tour. Molecular Electronics; Commercial Insights, Chemistry, Devices, Architecture and
Programming: (Rice University, USA), ISBN: 978-981-238-269.
1 10gramming. (Nice Omversity, Oba), 13DN. 5/0-701-230-205.

Online Resources:-

Flexible Electronics - an overview | ScienceDirect Topics

Flexible Electronics: Stretchable Electrodes and Their Future - Huang - 2019 – Advanced Functional

Materials - Wiley Online Library

Frontiers | Flexible Electronics and Healthcare Applications (frontiersin.org)

Flexible Electronic Devices for Biomedical Applications | SpringerLink

K1-Remember	K2-Understand	K3-Apply	K4-Analyse	K5-Evaluate	K6-Create
		C	Outcom		

Course Outcome

CO 1	Understand the molecular and atomic size of nanoparticles,	K1, K2
CO 2	Select the different carbon materials for required applications.	K2, K3
CO3	Understand the fundamentals of nano-electronic devices and MEMS and selection of materials	K5
CO 4	Select molecules to construct conducting wires, rectify, switches and DNA conductors and their role in molecular computer and DNA molecular devices.	K3, K4
CO 5	Impart knowledge on soft tissue and drug delivery materials.	K1, K6

Course outcome Vs Programme outcomes

PO/CO	PO 1	PO 2	PO 3	PO 4	PO 5	PO 6	PO 7	PO 8	PO 9	PO 10
CO 1	S (3)	M (2)	S (3)	M (2)	M (2)	S (3)	L(1)	M (2)	L (1)	M (2)
CO 2	S (3)	M (2)	M (2)	S (3)	S (3)	S (3)				
CO3	M (2)	M (2)	S (3)	S (3)	S (3)	M (2)	M (2)	L(1)	L(1)	S (3)
CO 4	S (3)	S (3)	S (3)	S (3)	M (2)	M (2)	L(1)	M (2)	M (2)	M (2)
CO 5	M (2)	S (3)	S (3)	S (3)	S (3)	L (1)	L(1)	S (3)	S (3)	S (3)
W. AV	2.6	2.6	3	2.8	2.6	2	1.4	2.2	2	2.6

S – Strong (3), M-Medium (2), L-Low (1)

Course Outcome Vs Programme Specific Outcome

PSO/CO	PSO 1	PSO 2	PSO 3	PSO 4	PSO 5
CO 1	S (3)	M (2)	M (2)	S (3)	S (3)
CO 2	S (3)	S (3)	M (2)	M (2)	S (3)
CO 3	M (2)	M (2)	S (3)	M (2)	S (3)
CO 4	L(1)	M (2)	M (2)	S (3)	S (3)
CO 5	M (2)	M (2)	M (2)	S (3)	S (3)
W. AV	2.2	2.2	2.2	2.6	3

S-Strong (3), M-Medium (2), L-Low (1)

202		I-SEMESTER			
DSE	Course code:542503	Non-Destructive Testing	T	Credits: 3	Hours: 3
1		Unit I	'		•
Objective 1	To introduce the stu	udents to liquid penetrant and m	agnetic p	particle inspecti	ion.
		ACE NDT METHODS -Defin		•	
		oncept of design and the role of N			-
-		particle testing, basic principle o	-	_	
-		ed in magnetic particle testing – de	velopme	nt and detection	of large flux
– longitudina		ation – demagnetization.			1
Outcome 1	Students learn about inspection.	liquid penetrant and magnetic p	article		K1, K5/K6
		Unit II			
-		s understand the principle, worki	_	_	-
		Properties of X-rays and gamma	•		
attenuation	 interaction of radiatio 	on with matter – Principle of radiog	graphic te	esting and record	ding medium
 films and 	$fluorescent\ screens-n$	non imaging detectors – film radio	graphy -	- calculation of	exposure for
X-ray and g	gamma rays – quality fa	ctors – Image quality indications a	nd their	use in radiograp	hy – neutron
radiography	7.	70 Mengelone			
	Students understand	the principle, working and uses	of		
Outcome 2	radiographic testing.	S 21 ACADDA IINIVERSITY	2		K3/K6
		Unit III	50	I	
Objective 3	To impart knowleds	ge about the ultrasonic testing			
		sonic waves – velocity, period, free	uency ar	nd wavelength –	reflection and
transmission	- near and far field ef				
	mour and rai mora or	fects and attenuation – gene <mark>ra</mark> tion	ı – piezo	pelectric and ma	agnetostriction
methods – n		fects and attenua <mark>tion –</mark> gene <mark>ra</mark> tion s – methods of Ultrasonic testing	_		-
	ormal and angle probes	s – <mark>methods</mark> of <mark>Ul</mark> tras <mark>oni</mark> c te <mark>st</mark> ing	- Princ	iple of pulse ec	ho method -
Equipment –	ormal and angle probes examples – rail road ins	THE RESIDENCE OF THE PARTY OF T	- Princ	iple of pulse ec	ho method -
Equipment –	ormal and angle probes examples – rail road ins	s – <mark>m</mark> etho <mark>ds</mark> of Ultras <mark>oni</mark> c te <mark>st</mark> ing spect <mark>io</mark> n, wa <mark>ll thickness m</mark> eas <mark>ur</mark> emo	- Princ	iple of pulse ec	cho method – frequency.
Equipment –	ormal and angle probes examples – rail road ins Students gain knowle	s – methods of Ultrasonic testing spection, wall thickness measureme edge on ultrasonic testing.	; – Princ ent – rang	iple of pulse ec	cho method – frequency. K1/K3/K5
Equipment – Outcome 3 Objective	examples – rail road ins Students gain knowle To make the studen current technique.	s – methods of Ultrasonic testing spection, wall thickness measuremented edge on ultrasonic testing. Unit IV	; — Princent — rang	iple of pulse ecge and choice of	cho method – frequency. K1/K3/K5 reddy
Outcome 3 Objective 4 EDDY CUR	examples – rail road ins Students gain knowle To make the studen current technique. RENT TESTING - In	s – methods of Ultrasonic testing spection, wall thickness measuremedge on ultrasonic testing. Unit IV uts understand the principle, wor	king and	iple of pulse edge and choice of I application of	cho method – frequency. K1/K3/K5 eddy aductivity of a
Outcome 3 Objective 4 EDDY CUR material – m	examples – rail road ins Students gain knowle To make the studen current technique. ERENT TESTING - In agnetic properties – con	s – methods of Ultrasonic testing spection, wall thickness measurementedge on ultrasonic testing. Unit IV ats understand the principle, wor	king and	iple of pulse edge and choice of I application of Inspection – corects – skin effect	cho method — Frequency. K1/K3/K5 eddy ductivity of a ct — inspection
Outcome 3 Objective 4 EDDY CUR material – m frequency – o	To make the studen current technique. RENT TESTING - In agnetic properties – coicoil arrangements – ins	s – methods of Ultrasonic testing spection, wall thickness measurement of the contract of the	king and	iple of pulse edge and choice of I application of Inspection – corects – skin effect	cho method — Frequency. K1/K3/K5 eddy ductivity of a ct — inspection
Outcome 3 Objective 4 EDDY CUR material – m frequency – 6	To make the student current technique. RENT TESTING - In agnetic properties - coic coil arrangements - insods - typical application	s – methods of Ultrasonic testing spection, wall thickness measurementedge on ultrasonic testing. Unit IV ats understand the principle, wor introduction – Principles of eddy il impedance – lift off factor and spection probes – types of circuit	king and	iple of pulse edge and choice of I application of Inspection – corects – skin effection edge of the pieces – phase	cho method — Frequency. K1/K3/K5 eddy ductivity of a ct — inspection
Objective 4 Cobjective 4 Cob	To make the student current technique. RENT TESTING - In agnetic properties - coic coil arrangements - insods - typical application	s – methods of Ultrasonic testing spection, wall thickness measurement testing. Unit IV Its understand the principle, wor introduction – Principles of eddy il impedance – lift off factor and spection probes – types of circuitans of eddy current techniques.	king and	iple of pulse edge and choice of I application of Inspection – corects – skin effection edge of the pieces – phase	cho method — frequency. K1/K3/K5 Feddy aductivity of et — inspection ase analysis —
Objective 4 Objective 4 EDDY CUR material – m frequency – o display metho	To make the student current technique. RENT TESTING - In agnetic properties — coic arrangements — insods — typical application Students able to appl	s – methods of Ultrasonic testing spection, wall thickness measuremented on ultrasonic testing. Unit IV Ints understand the principle, wore introduction – Principles of eddy il impedance – lift off factor and espection probes – types of circuit ens of eddy current techniques. Ly their knowledge on eddy current ed	king and current i edge efferent techn	iple of pulse edge and choice of I application of Inspection – corects – skin effection edge of the pieces – phase	cho method — frequency. K1/K3/K5 Feddy aductivity of a ct — inspection ase analysis —
Objective 4 Outcome 3 Objective 4 EDDY CUR material – m frequency – o display metho Outcome 4 Objective 5 THERMAL	To make the student current technique. RENT TESTING - In agnetic properties – coil arrangements – insods – typical application Students able to appl To expose the thern AND OPTICAL MET	s – methods of Ultrasonic testing spection, wall thickness measurementedge on ultrasonic testing. Unit IV Ints understand the principle, wore introduction – Principles of eddy il impedance – lift off factor and spection probes – types of circuit ins of eddy current techniques. In the introduction is of eddy current techniques.	king and current i edge efferent rechn NDT. applicat:	iple of pulse edge and choice of I application of Inspection – corrects – skin effection edge pieces – phasique.	cho method — Frequency. K1/K3/K5 Feddy Inductivity of set — inspection ase analysis — K1/K5/K6
Objective 4 Objective 4 EDDY CUR material – m frequency – o display metho Outcome 4 Objective 5 THERMAL acoustic emi	To make the student current technique. RENT TESTING - In agnetic properties — coil arrangements — insods — typical application Students able to appl To expose the thern AND OPTICAL MET assion testing — applic	s – methods of Ultrasonic testing spection, wall thickness measurement of the control of the con	king and current i edge efferent techn NDT. applications	iple of pulse edge and choice of I application of Inspection – corects – skin effection epieces – phase ique. ions – testing of continuous sur	cho method — Frequency. K1/K3/K5 eddy inductivity of a ct — inspection ase analysis — K1/K5/K6 Composites — veillance and
Objective 4 Objective 4 EDDY CUR material – m frequency – o display metho Outcome 4 Objective 5 THERMAL acoustic emiapplications	To make the student current technique. RENT TESTING - In agnetic properties — coil arrangements — insods — typical application Students able to appl To expose the therm AND OPTICAL MET assion testing — application materials science —	s – methods of Ultrasonic testing spection, wall thickness measurementedge on ultrasonic testing. Unit IV Its understand the principle, wore introduction – Principles of eddy sil impedance – lift off factor and spection probes – types of circuitans of eddy current techniques. Ity their knowledge on eddy current techniques. Unit V Inal and optical methods used in Thods- Imaging – principle and station of AET – on-line monitor Optical methods of NDT – photographs.	king and current i edge efferent techn NDT. application	iple of pulse edge and choice of I application of Inspection – conects – skin effection edge in the pieces – phase ique. ions – testing of continuous sureity – evaluation	cho method — Frequency. K1/K3/K5 Eddy Inductivity of a ct — inspection ase analysis — K1/K5/K6 Composites — veillance and a procedure —
Objective 4 Objective 4 EDDY CUR material – m frequency – o display metho Outcome 4 Objective 5 THERMAL acoustic emi applications Holographic	To make the student current technique. RENT TESTING - In agnetic properties — coil arrangements — insods — typical application Students able to appl To expose the therm AND OPTICAL MET assion testing — applic in materials science — NDT procedure — speck	s – methods of Ultrasonic testing spection, wall thickness measurementedge on ultrasonic testing. Unit IV Ints understand the principle, wore strong the strong of eddy will impedance – lift off factor and spection probes – types of circuitans of eddy current techniques. In the strong of eddy current techniques. Unit V Inal and optical methods used in Thods- Imaging – principle and eation of AET – on-line monitor optical methods of NDT – photographenomenon – speckle interference.	king and current is edge efformat technology application of elastic cometry —	iple of pulse edge and choice of I application of Inspection – conects – skin effection edge in the pieces – phase ique. ions – testing of continuous sureity – evaluation	cho method — Frequency. K1/K3/K5 eddy ductivity of a ct — inspection ase analysis — K1/K5/K6 Composites — veillance and a procedure —
Equipment – Outcome 3 Objective 4 EDDY CUR material – m frequency – o display metho Outcome 4 Objective 5 THERMAL acoustic emi applications Holographic	To make the student current technique. RENT TESTING - In agnetic properties – coil arrangements – insods – typical application Students able to appl To expose the therm AND OPTICAL MET assion testing – application materials science – NDT procedure – speckics – Fourier filtering te	s – methods of Ultrasonic testing spection, wall thickness measurementedge on ultrasonic testing. Unit IV Its understand the principle, wore introduction – Principles of eddy sil impedance – lift off factor and spection probes – types of circuitans of eddy current techniques. Ity their knowledge on eddy current techniques. Unit V Inal and optical methods used in Thods- Imaging – principle and station of AET – on-line monitor Optical methods of NDT – photographs.	king and current i edge efformatechn NDT. application or elastic ometry—	iple of pulse edge and choice of I application of Inspection – corects – skin effection epieces – phase ique. ions – testing of continuous sureity – evaluation speckle shear in	cho method — Frequency. K1/K3/K5 eddy ductivity of a ct — inspection ase analysis — K1/K5/K6 Composites — veillance and a procedure —

Suggested Readings :-

Dainty J.C. (1984). Laser Speckle & Related Phenomena, Springer-Verlag, New York.

Hull B.andJohn V. (2012). Non-Destructive Testing. Springer-Verlag New York Inc.

McGonnagleW.J. (1961). Non-Destructive Testing Methods, Mc Graw Hill Co., NY.

Metals Hand Book, Vol.2, 8th Edition, ASTM, Metals Park, Ohio.

Online Resources:-

Flexible Electronics - an overview | ScienceDirect Topics

Flexible Electronics: Stretchable Electrodes and Their Future - Huang - 2019 – Advanced Functional

Materials - Wiley Online Library

K1-Remember	K2-Understand	K3-Apply	K4-Analyse	K5-Evaluate	K6-Create
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Course Outcome

CO 1	Learn about liquid penetrant and magnetic particle inspection.	K1, K2
CO 2	Understand the principle, working and uses of radiographic testing.	K2, K3
CO 3	Gain knowledge on ultrasonic testing.	K5
CO 4	Apply their knowledge on eddy current technique.	K3, K4
CO 5	Analyze the thermal and optical methods used in NDT.	K1, K6

Course outcome Vs Programme outcomes

* ALAGAPPA UNIVERSITY

PO/CO	PO 1	PO 2	PO 3	PO 4	PO 5	PO 6	PO 7	PO 8	PO 9	PO 10
CO 1	S (3)	M (2)	S (3)	M (2)	M (2)	S (3)	L(1)	M (2)	L(1)	M (2)
CO 2	S (3)	M (2)	M (2)	S (3)	S (3)	S (3)				
CO3	M (2)	M (2)	S (3)	S (3)	S (3)	M (2)	M (2)	L(1)	L(1)	S (3)
CO 4	S (3)	S (3)	S (3)	S (3)	M (2)	M (2)	L(1)	M (2)	M (2)	M (2)
CO 5	M (2)	S (3)	S (3)	S (3)	S (3)	L(1)	L(1)	S (3)	S (3)	S (3)
W. AV	2.6	2.6	3	2.8	2.6	2	1.4	2.2	2	2.6

S – Strong (3), M-Medium (2), L- Low (1)

Course Outcome Vs Programme Specific Outcome

PSO/CO	PSO 1	PSO 2	PSO 3	PSO 4	PSO 5
CO 1	S (3)	M (2)	M (2)	S (3)	S (3)
CO 2	S (3)	S (3)	M (2)	M (2)	S (3)
CO3	M (2)	M (2)	S (3)	M (2)	S (3)
CO 4	L(1)	M (2)	M (2)	S (3)	S (3)
CO 5	M (2)	M (2)	M (2)	S (3)	S (3)
W. AV	2.2	2.2	2.2	2.6	3

	I-SEMESTER	
DSE Cou	rse code:542504 Nonlinear Optics and Materials T Credits: 3	Hours: 3
1	Unit I	
Objective 1	To introduce the concepts of electromagnetic theory and refractive index	
ELECTROMAG	NETIC THEORY -Maxwell equations – wave equations in various r	nedia and its
	gin of complex refractive index – classical theory of optical absorption (electrons)	ron oscillator
model) and disper	sion (Lorenz oscillator model) – classical theory of anharmonic oscillators.	
Outcome 1	Understand the concept of electromagnetic theory.	K1, K5/K6
	Unit II	
Objective 2	To expose the students, the concept of optical susceptibility.	
OPTICAL SUS	CEPTIBILITIES - Wave equation description of nonlinear optical susc	eptibilities –
quantum mechar	nical treatment of nonlinear optical susceptibilities - frequency and intensity de	ependence of
polarization – an	d dielectric susceptibility – first and higher order susceptibilities.	
Outcome 2	Appreciate the importance of optical susceptibility and nonlinear	V2/V6
Outcome 2	optical susceptibilities.	K3/K6
	Unit III	
Objective 3	To make the students to understanding the concept of second order non	linearity.
SECOND-ORDE	R NONLINEARITIES - Second harmonic generation - sum and different	nce frequency
_	netric processes – simple theory and calculations of nonlinear polarization –	various phase
matching techniqu	es in second harmonic generation (SHG).	
Outcome 3	Reveal the origin of second harmonic generation and other second	K1/K3/K5
Outcome 5	nonlinear optical processes and techniques.	K1/K5/K5
	Unit IV	
Objective 4	To introduce the processes of third order nonlinear optical effects.	
	NONLINEARITIES - Third harmonic generation – four-wave mixing – Ke	
	ent effect – self-phase modulation – crossphase modulation. Stimulated Ram	_
	un scatter <mark>ing. P</mark> arametric gain – parametric amplification and oscillation A	
	and up-conversion – difference frequency generation – optical phase conju	-
	 Photorefractive effect and applications – solitons: theory and applications 	ons – optical
bistability.		
Outcome 4	Understand the important third order optical nonlinearities, theory and	K1/K5/K6
	applications.	
	Unit V	
Objective 5	To make the students to understand the properties of non-linear optical i	
	PTICAL MATERIALS - Nonlinear optics of organic materials and poly	_
_	efractive materials – organic doped glasses – rare earth doped glasses	-
	optical fibers and photonic crystal fibers - ferroelectric materials and other	novel optical
materials.		1
Outcome 5	Gain knowledge on the properties of non-linear optical materials and	K2/K5/K6
Suggested Deading	polymers.	
Suggested Readin		
	05). Nonlinear Optics. World Scientific, Singapore. Lasers and Non-linear Optics. New Age International Pvt. Ltd.	
` ′	dVijayanC. (2014). Essentials of Nonlinear Optics.	
	Boyd. (2009). Nonlinear Optics. Academic Press, London.	
THEY. ROBERT W.	Boyd. (2007). Nominical Optics. Academic 11635, London.	

Bobo Gu, Chujun Zhao, Alexander Baev, Ken-Tye Yong, Shuangchun Wen, and Paras N. Prasad, Molecular nonlinear optics: recent advances and applications, Vol. 8, Issue 2, pp. 328-369 (2016),

https://doi.org/10.1364/AOP.8.000328.

Anton Autere, Henri Jussila, Yunyun Dai, Yadong Wang, Harri Lipsanen, Zhipei Sun, Nonlinear Optics with 2D Layered Materials, 25 March 2018 https://doi.org/10.1002/adma.201705963.

K1-Remember	K2-Understand	K3-Apply	K4-Analyse	K5-Evaluate	K6-Create
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Course Outcome

CO 1	Understand the concept of electromagnetic theory.	K1, K2
CO 2	Appreciate the importance of optical susceptibility.	K2, K3
CO3	Reveal the origin of second harmonic generation and other second nonlinear optical processes.	К5
CO 4	Understand the important third order optical nonlinearities.	K3, K4
CO 5	Gain knowledge on the properties of non-linear optical materials.	K1, K6

Course outcome Vs Programme outcomes

PO/CO	PO 1	PO 2	PO 3	PO 4	PO 5	PO 6	PO 7	PO 8	PO 9	PO 10
CO 1	S (3)	M (2)	S (3)	M (2)	M (2)	S (3)	L(1)	M (2)	L(1)	M (2)
CO 2	S (3)	M (2)	M (2)	S (3)	S (3)	S (3)				
CO 3	M (2)	M (2)	S (3)	S (3)	S (3)	M (2)	M (2)	L (1)	L(1)	S (3)
CO 4	S (3)	S (3)	S (3)	S (3)	M (2)	M (2)	L(1)	M (2)	M (2)	M (2)
CO 5	M (2)	S (3)	S (3)	S (3)	S (3)	L (1)	L(1)	S (3)	S (3)	S (3)
W. AV	2.6	2.6	3	2.8	2.6	2	1.4	2.2	2	2.6

S – Strong (3), M-Medium (2), L-Low (1) Course

Outcome Vs Programme Specific Outcome

PSO/CO	PSO 1	PSO 2	PSO 3	PSO 4	PSO 5
CO 1	S (3)	M (2)	M (2)	S (3)	S (3)
CO 2	S (3)	S (3)	M (2)	M (2)	S (3)
CO3	M (2)	M (2)	S (3)	M (2)	S (3)
CO 4	L(1)	M (2)	M (2)	S (3)	S (3)
CO 5	M (2)	M (2)	M (2)	S (3)	S (3)
W. AV	2.2	2.2	2.2	2.6	3

		I-SEMESTER	
Iours: 3	Credits: 3	Course code :542505	DSE
		Unit - I	
	laser systems.	ctive 1 To make the students understand about theoretical studie	Objecti
tio of rate	ein coefficients,	CIPLES OF LASERS-Spontaneous emission, Stimulated emission, E	RINCII
Population	Rate equations	ulated and spontaneous emission - Threshold condition for laser acti	fstimula
		on in three level and four level systems.	version
I/1	nts	Students understand the principle involved in Einstein coef	Outcon
K1		and action of laser.	Outcon
1		Unit - II	
	ong the learner	ctive 2 To impact the basic knowledge on laser system compound	Objecti
spot size -	resonator mode	CAL RESONATORS- Resonant cavities, Gaussian beam characteris	PTICA
odelocking	switching and	of resonators, geometries, quality factor of an optical resonator -	ypes of
		ts and techniques.	oncepts a
1/2		Students gain knowledge on laser compound and Q switchi	0.4
K3		ome 2 mode focusing concepts.	Outcon
		Unit - III	
	the students.	ctive 3 To introduce the knowledge about various laser systems an	Objecti
on ion gas	gen gas laser, A	R SYSTEMS- Gas lasers: He-Ne laser, Carbon dioxide gas laser, N	ASER S
or Laser -	re - Semicondu	Solid state lasers: Ruby laser, Nd-YAG laser, fiber laser, Ti-Sap	ser – S
		unction and heterojunction laser - Liquid Lasers: Dye lasers.	omojuno
K2	systems working	ome 3 Learners make use of the basic knowledge about various la methods.	Outcon
К2	systems working	ome 5	Outcon
К2	systems working	ome 3 methods.	
		methods. Unit - IV	Objecti
depth an	Welding - Fusi	ome 3 methods. Unit - IV ctive 4 To know about laser system used for materials processing.	Objecti IATER
depth an	Welding - Fusi g - Drilling hol	methods. Unit - IV ctive 4 To know about laser system used for materials processing. CRIALS PROCESSING- Laser power density – heat affected zor	Objecti IATER elding
depth an	Welding - Fusi g - Drilling hol	methods. Unit - IV ctive 4 To know about laser system used for materials processing. CRIALS PROCESSING- Laser power density – heat affected zor g geometry - Welding speeds - Advantages and uses of laser we	Objecti IATER elding and advantage
depth an	Welding - Fusi g - Drilling hol adjustment and	methods. Unit - IV ctive 4 To know about laser system used for materials processing. CRIALS PROCESSING- Laser power density – heat affected zor g geometry - Welding speeds - Advantages and uses of laser we tages and uses of laser drilling - resistor trimming - Capacitor he g - Controlled fracturing. The students gain knowledge on various laser processing methods.	Objecti IATER elding a dvantageribing -
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Hunter JG, Bowers JH, Burt RW, Sullivan JJ, Stevens SL, Dixon JA. Lasers in endoscopic gastrointestinal surgery. Am J Surg. 1984;148(6):736–41 https://doi.org/10.1016/0002-9610(84)90427-6.

Khalkhal, E., Rezaei-Tavirani, M., Zali, M. R., & Akbari, Z. (2019). The Evaluation of Laser Application in Surgery: A Review Article. Journal of Lasers in Medical Sciences, 10(Supplement), S104-S111. Retrieved from https://journals.sbmu.ac.ir/jlms/article/view/27719.

Jill Canin Endres MD, Randolph M. Steinhagen MD, Lasers in Anorectal Surgery, https://doi.org/10.1016/S0039-6109(16)46490-X.

K1-Remember	K2-Understand	K3-Apply	K4-Analyse	K5-Evaluate	K6-Create
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Course Outcome

CO 1	Understood the principle involved in Einstein coefficients and action of laser.	K1, K2
CO 2	Gain knowledge on laser compound and Q switching mode focusing concepts.	K2, K3
СОЗ	Learners make use of the basic knowledge about various laser systems working methods.	К5
CO 4	Gain knowledge on various laser processing methods and advantages.	K3, K4
CO 5	Know the laser applications on industrial and medical fields.	K1, K6



Course outcome Vs Programme outcomes

PO/CO	PO 1	PO 2	PO 3	PO 4	PO 5	PO 6	PO 7	PO 8	PO 9	PO 10
CO 1	S (3)	M (2)	S (3)	M (2)	M (2)	S (3)	L(1)	M (2)	L(1)	M (2)
CO 2	S (3)	M (2)	M (2)	S (3)	S (3)	S (3)				
CO3	M (2)	M (2)	S (3)	S (3)	S (3)	M (2)	M (2)	L(1)	L(1)	S (3)
CO 4	S (3)	S (3)	S (3)	S (3)	M (2)	M (2)	L(1)	M (2)	M (2)	M (2)
CO 5	M (2)	S (3)	S (3)	S (3)	S (3)	L (1)	L(1)	S (3)	S (3)	S (3)
W. AV	2.6	2.6	3	2.8	2.6	2	1.4	2.2	2	2.6

Course Outcome Vs Programme Specific Outcome

PSO/CO	PSO 1	PSO 2	PSO 3	PSO 4	PSO 5
CO 1	S (3)	M (2)	M (2)	S (3)	S (3)
CO 2	S (3)	S (3)	M (2)	M (2)	S (3)
CO3	M (2)	M (2)	S (3)	M (2)	S (3)
CO 4	L(1)	M (2)	M (2)	S (3)	S (3)
CO 5	M (2)	M (2)	M (2)	S (3)	S (3)
W. AV	2.2	2.2	2.2	2.6	3

S-Strong (3), M-Medium (2), L-Low (1)



	I-SEMESTER									
DSE	Cour	se code:542506	Python Programming	T	Credits: 3	Hours: 3				
	Unit - I									
Obje	Objective 1 To make the students understand and to introduce the concepts of algorithms and developing them.									

Algorithmic Problem Solving -Algorithms, building blocks of algorithms (statements, state, control flow, functions), notation (pseudo code, flow chart, programming language), algorithmic problem solving, simple strategies for developing algorithms (iteration, recursion). Illustrative problems: find minimum in a list, insert a card in a list of sorted cards, guess an integer number in a range, Towers of Hanoi.

Outcome 1	Students understand the principle involved in Developing algorithms.	K2
	Unit - II	
Objective 2	To make the students to understand different types of data, expressions and in Python environment.	statements

Data, Expressions, Statements - Python interpreter and interactive mode; values and types: int, float, boolean, string, and list; variables, expressions, statements, tuple assignment, precedence of operators, comments; modules and functions, function definition and use, flow of execution, parameters and arguments; Illustrative programs: exchange the values of two variables, circulate the values of n variables, distance between two points.

Outcome 2 Students understand various types of things in Python environment. Unit - III Objective 3 To introduce the knowledge about various laser systems among the students.

Control Flow, Functions – Conditionals: Boolean values and operators, conditional (if), alternative (if-else), chained conditional (if-elif-else); Iteration: state, while, for, break, continue, pass; Fruitful functions: return values, parameters, local and global scope, function composition, recursion; Strings: string slices, immutability, string functions and methods, string module; Lists as arrays. Illustrative programs: square root, gcd, exponentiation, sum an array of numbers, linear search, binary search.

Outcome 3 Learners make use of control flow and functions in Python environment. K1 Unit - IV

Objective 4 To introduce the concepts of lists, tuples and dictionaries in Python environment.

Lists, Tuples, Dictionaries - Lists: list operations, list slices, list methods, list loop, mutability, aliasing cloning lists, list parameters; Tuples: tuple assignment, tuple as return value; Dictionaries: operations and methods; advanced list processing - list comprehension; Illustrative programs: selection sort, insertion sort, mergesort, histogram.

Outcome 4	Students understand to use Python environment.	K5					
	Unit - V						
Objective 5	Objective 5 To make the students to use files, modules and packages.						

Files, Modules, Packages -Files and exception: text files, reading and writing files, format operator; command line arguments, errors and exceptions, handling exceptions, modules, packages; Illustrative programs: word count, copy file.

Outcome 5 The students use Python programming environment. K2

Suggested Readings:-

Eric Matthes. (2015). Python Crash Course. No Starch Press.

Kenneth Lambert. (2012). Fundamentals of Python: First Programms. Cengage Learning.

Mark Lutz. (2013). Learning Python. O'Reilly Media.

A Bogdanchikov et al, Python to learn programming, 2013 J. Phys.: Conf. Ser. 423 012027, <u>DOI 10.1088/1742-6596/423/1/012027</u>.

Calico: A multi-programming-language, multi-context framework designed for computer science education, D Blank, JS Kay, JB Marshall, K O'Hara, M Russo

K1-Remember	K2-Understand	K3-Apply	K4-Analyse	K5-Evaluate	K6-Create

Course Outcome

CO 1	Understand the principle involved in Developing algorithms.	K1, K2
CO 2	Understand different types of data, expressions and statements in Python environment.	K2, K3
CO3	Make use of control flow and functions in Python environment.	K5
CO 4	Understand and use lists, tuples and dictionaries in Python environment.	K3, K4
CO 5	Use files, modules and packages of Python programming environment.	K1, K6

Course outcome Vs Programme outcomes

PO/CO	PO 1	PO 2	PO 3	PO 4	PO 5	PO 6	PO 7	PO 8	PO 9	PO 10
CO 1	S (3)	M (2)	S (3)	M (2)	M (2)	S (3)	L(1)	M (2)	L(1)	M (2)
CO 2	S (3)	M (2)	M (2)	S (3)	S (3)	S (3)				
CO3	M (2)	M (2)	S (3)	S (3)	S (3)	M (2)	M (2)	L(1)	L(1)	S (3)
CO 4	S (3)	S (3)	S (3)	S (3)	M (2)	M (2)	L(1)	M (2)	M (2)	M (2)
CO 5	M (2)	S (3)	S (3)	S (3)	S (3)	L(1)	L(1)	S (3)	S (3)	S (3)
W. AV	2.6	2.6	3	2.8	2.6	2	1.4	2.2	2	2.6

S – Strong (3), M-Medium (2), L-Low (1)

Course Outcome Vs Programme Specific Outcome

PSO/CO	PSO 1	PSO 2	PSO 3	PSO 4	PSO 5
CO 1	S (3)	M (2)	M (2)	S (3)	S (3)
CO 2	S (3)	S (3)	M (2)	M (2)	S (3)
CO 3	M (2)	M (2)	S (3)	M (2)	S (3)
CO 4	L(1)	M (2)	M (2)	S (3)	S (3)
CO 5	M (2)	M (2)	M (2)	S (3)	S (3)
W. AV	2.2	2.2	2.2	2.6	3

Unit - I Objective 1 To elucidate fundamental chemical aspects of materials' composition-structure-properties and particulary and composition and in Multielement Crystals. Ionic Bonding, Mixed Ionic—Covalent E and Ionicity, Hydrogen Bonding, Cohesive Energies, Summary of Some Atomic Properties and Parlonization Energy and Electron Affinity, Electronegativity, Atomic Radii: Ionic, Covalent, Metallivan der Waals. Problems Outcome 1 Learners recognize different bonding nature forming crystals or materials in their structure. Unit II Objective 2 To know various types of band structure in different materials, electrical and optice properties. CLASSES OF MATERIALS-Characteristic Properties of Semiconductors- Microscopic Properties brunensionality and Quantum Confinement Macroscopic Properties. Electrical Conductive Mobility. Effects of Magnetic Fields. Optical Properties. Examples of Semiconductors and Their Compounds and Alloys. Compound, Semiconductors and Their Applications of Semiconductors. Outcome 2 Able to identify different classes of material based on their physical and electronic properties. Unit III Objective 3 To identify different polymers based on chemical and physical properties Properties. Polymers Under Tension. Viscoelasticity Thermal Properties. Thermal Properties of Peroperties. Polymers Under Tension. Viscoelasticity Thermal Properties. Thermal Properties of Peroperties. Polymers Under Tension. Viscoelasticity Thermal Properties. Polymers Under Tension. Viscoelasticity Thermal Properties. Thermal Properties of Peroperties. Polymers Under Tension. Viscoelasticity Thermal Properties. Thermal Properties of Peroperties. Polymers Under Tension. Viscoelasticity Thermal Properties. Thermal Properties of Peroperties. Polymers Under Tension. Viscoelasticity Thermal Properties. Thermal Properties of Peroperties Polymers Under Tension. Viscoelasticity Thermal Properties. Polymers Medication SURFACE AND THIN FILMS INTERFACES: Ideal Surfaces. Real Surfaces. Relaxation. Reconst Surface Defects Electro			II-SEMESTER			
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and Defects Dimensionality and Quantum Confinement Macroscopic Properties. Electrical Conductive Mobility. Effects of Magnetic Fields, Optical Properties. Examples of Semiconductors - Electronic Properties and Their Compounds and Alloys. Compound, Semiconductors and Their Applications of Semiconductors. Outcome 2 Able to identify different classes of material based on their physical and electronic properties. Unit III Objective 3 To identify different polymers based on chemical and physical properties POLYMERS: Structure and Geometry of Polymers. Polymer Crystals. Defects in Polymers Mec Properties. Polymers Under Tension. Viscoelasticity Thermal Properties. Thermal Properties of Polymers. Crystals Outcome 3 Gain knowledge on polymer properties pertaining to material applications. K1 Unit IV Objective 4 To understand the Surface behaviors of solid materials, defects, property change by modification SURFACE AND THIN FILMS INTERFACES: Ideal Surfaces. Real Surfaces. Relaxation.Reconst Surface Defects Electronic Properties of Surfaces. Work Function Thermionic Emission Field En Photoemission Surface States Surface Modification Anodization Passivation Surface Phonons Surfaces Adhesion and Friction Surface Plasmons Dispersion Forces. Friction Learn the tailor surface properties by altering surface defects, surface			±		-	-
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SURFACE AND THIN FILMS INTERFACES: Ideal Surfaces. Real Surfaces. Relaxation.Reconst Surface Defects Electronic Properties of Surfaces. Work Function Thermionic Emission Field En Photoemission Surface States Surface Modification Anodization Passivation Surface Phonons Surfaces Processes Adhesion and Friction Surface Plasmons Dispersion Forces. Friction Learn the tailor surface properties by altering surface defects, surface			Unit IV			
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Photoemission Surface States Surface Modification Anodization Passivation Surface Phonons S Processes Adhesion and Friction Surface Plasmons Dispersion Forces. Friction Learn the tailor surface properties by altering surface defects, surface	SURFACE A	ND THIN FILMS INT	ERFACES: Ideal Surfaces. Real St	urfaces.	Relaxation.Re	construction
Processes Adhesion and Friction Surface Plasmons Dispersion Forces. Friction Learn the tailor surface properties by altering surface defects, surface	Surface Defe	cts Electronic Propertie	s of Surfaces. Work Function The	rmionic	Emission Fie	eld Emission
Learn the tailor surface properties by altering surface defects, surface	Photoemissio	n Surface States Surfac	ee Modification Anodization Passi	vation S	Surface Phono	ons Surface
Learn the tailor surface properties by altering surface defects, surface	Processes Ad	hesion and Friction Surfa	ace Plasmons Dispersion Forces. Fri	ction		
Outcome 4 modifications with other material surfaces.	Outcome 4			cts, surf	ace	K1/K2/K5

Unit V

Objective 5

To provide the knowledge need to design and produce materials with tailored properties from first principles.

SYNTHESIS AND PROCESSING OF MATERIALS: Introduction Issues in Synthesis and Processing. Thermodynamic and Chemical Effects. Kinetic Effects. Crystal Growth. Synthesis and Processing of Metals. Synthesis and Processing of Steels. Synthesis and Processing of Stainless Steels Synthesis and Processing of Ceramics and Glasses. Powder Synthesis. Sol—Gel Synthesis Synthesis and Processing of Polymers and Carbon Molecules. Polymerization. Catalysts in Polymer Synthesis. Synthesis of Carbon Nanotubes

Outcome 5

Familiar with synthesize of materials with required characteristics by selecting different synthesis methods.

K3/K5/K6

Suggested Readings -

Joel I. Gersten Frederick W. Smith The Physics And Chemistry Of Materials,

John Wiley & Sons, Inc., ISBN 0-471-05794-0, 2001

Leonard V. Interrante, editor, Lawrence A. Casper, editor, Arthur B. Ellis, editor, Materials chemistry: an emerging discipline, Advances in chemistry series, ISSN 0065-2393; 245) ISBN 0-8412-2809-4

Online Resource

Nanomaterials: a review of synthesis methods, properties, recent progress, and challenges - Materials

Advances (RSC Publishing) DOI:10.1039/D0MA00807A

Materials Chemistry and Physics (scimagojr.com)

K1-Remember	K2-Understand	K3-Apply	K4-Analyse	K5-Evaluate	K6-Create
	3	AND INTERNATIONAL CAN	ONIVERSIT	ourse designed b	W. Dr. V. Dharuman

Course Outcome

CO 1	Recognize different bonding nature forming crystals or materials in their	K1
	structure.	
CO 2	Identify different classes of material based on their physical and	K1, K4
	electronic properties.	
CO3	Gain knowledge on polymer properties pertaining to material applications.	K1, K5
CO 4	Tailor surface properties by altering surface defects, surface modifications	K1, K2, K5
	with other material surfaces.	
CO 5	Familiar with synthesize of materials with required characteristics by selecting	K3, K5, K6
	different synthesis methods.	

Course outcome Vs Programme outcomes

PO/CO	PO 1	PO 2	PO 3	PO 4	PO 5	PO 6	PO 7	PO 8	PO 9	PO 10
CO 1	S (3)	M (2)	S (3)	M (2)	M (2)	M (2)	L(1)	L(1)	M (2)	M (2)
CO 2	M (2)	L(1)	M (2)	L (1)	M (2)	M (2)	M (2)	S (3)	L(1)	L(1)
CO3	M (2)	S (3)	M (2)	M (2)	L(1)	M (2)	S (3)	M (2)	S (3)	M (2)
CO 4	M (2)	S (3)	S (3)	S (3)	M (2)	L(1)	S (3)	M (2)	L(1)	M (2)
CO 5	M (2)	M (2)	S (3)	S (3)	M (2)	M (2)	M (2)	L(1)	M (2)	M (2)
W. AV	2.2	2.2	2.6	2.1	1.8	1.8	2.1	1.8	1.8	1.8

Course Outcome Vs Programme Specific Outcome

PSO/CO	PSO 1	PSO 2	PSO 3	PSO 4	PSO 5
CO 1	S (3)	M (2)	L(1)	L(1)	M (2)
CO 2	M (2)	S (3)	M (2)	S (3)	M (2)
CO3	M (2)	S (3)	M (2)	L(1)	M (2)
CO 4	S (3)	M (2)	S (3)	S (3)	M (2)
CO 5	S (3)	S (3)	M (2)	M (2)	M (2)
W. AV	2.6	2.6	2	2	2.0

S – Strong (3), M-Medium (2), L-Low (1)



			II-SEMESTER						
Core 7	Cou	rse code:542202	Characterization of Ma	terials	T	Credits: 4	Но	urs: 4	
			Unit - I						
Objecti	ve 1	To make the stude	nts understand some impo	rtant the	rmal an	alysis techniqu	ies.		
			hermogravimetric analysis (
_			ucts – differential thermal a	• ,		-			
-		• '	mentation – specific heat	capacity	measure	ements – deter	minat	ion of	
thermomec	hanica	l parameters.							
Outcor	ne 1		and the concept of image flized microscopes.	ormation	ı in Opt	ical microsco _l	oe .	K2	
			Unit II						
Objecti	ve 2		nts familiarize with image lized microscopic techniq		on in an	optical micro	scope	and	
microscopy	Microscopic Methods - Optical Microscopy: optical microscopy techniques – Bright field – Dark field optical nicroscopy – phase contrast microscopy -differential interference contrast microscopy - fluorescence nicroscopy - confocal microscopy - Metallurgical microscope.								
Outcor	me 2	Students learn the AFM.	working principle and op	eration o	of SEM,	TEM, STM a	ınd	K4	
			Unit III	360				1	
Objecti	ve 3	To make the stu- scanning probe n	dents learn the principle nicroscopes.	of worki	ng of el	ectron micros	copes	s and	
and Instrun	nentati		probe microscopy- SEM-lation – scanning probe mic on.						
Outcom	ne 3	Students understa	ind t <mark>h</mark> e necessary theory o eme <mark>nt</mark> , C-V, I-V, Electroch					K4	
		A A	Unit IV	9 4					
Objecti	ve 4	To make the stud techniques.	ents understand some im	portant :	semicon	ductor chara	cteriz	ation	
Electrical	meth	ods and Optical o	characterization- Two pro	be and f	our prol	be methods- v	an de	r Pauw	
			ent – scattering mechanism						
			n – electrochemical C-V	orofiling	– limita	tions -Photolui	mines	cence -	
light – mat	ter inte		ntation – Applications.						
Outcon	ne 4	resistivity measu	and the necessary theory or rement, C-V, I-V, Electroc					K2	
	electroluminescence techniques. Unit V								
Ohiecti	ve 5	To introduce the s	tudents the basics of some	imnortar	ıt snecti	asconic techni	anes		
						-		:	
	Spectroscopy- Principles and instrumentation for UV-Vis-IR, FTIR spectroscopy, Raman spectroscopy, ESR, NMR, NQR, mass spectroscopy – Bain bridge-Jordan Mass spectroscope – application.								
Outcome 5 Students learn basics and necessary theory of some important spectroscopic techniques and its applications.								T75	

Suggested Readings :-

Banwell C.N.and McCashE.M. (2017). Fundamentals of Molecular Spectroscopy. McGraw-Hill Education.

Belk J.A. (1979). *Electron Microscopy and Microanalysis of Crystalline Materials*. Applied Science Publishers, London.

KealeyD.and Haines P.J. (2002). *Analytical Chemistry*. Viva Books Private Limited, New Delhi. MurrL.E. (1991). *Electron and Ion microscopy and Microanalysis principles and Applications*. Marcel Dekker Inc., New York.

Stradling R.A. and Klipstain P.C. (1990). *Growth and Characterization of semiconductors*. Adam Hilger, Bristol.

Online resources:-

Characterization of Nanomaterials by Physical Methods, Annual Review of Analytical Chemistry 2009 2:1, 435-462, 10.1146/annurev-anchem-060908-155236.

Chapter 11 - Characterization of Nanomaterials: Tools and Challenges, 2019, Pages 313-353, 10.1016/B978-0-12-814130-4.00011-7.

Novel Synthesis and Characterization of Nanostructured Materials, 10.1007/978-3-642-41275-2.

K1-Remember	K2-Understand	K3-Apply	K4-Analyse	K5-Evaluate	K6-Create					
	Course designed by: Dr. J. Wilso									

Course Outcome

	1 A T T T T T T T T T T T T T T T T T T	
CO 1	Gain basic knowledge on various spectroscopy being used in scientific area for different applications	K1
CO 2	Characterization of materials using SEM, TEM and Microscopy analysis	K2/K6
CO 3	Investigate the different properties and characterization of nanomaterials for suitable applications	К3
CO4	Understand and applying the gained skill to develop a sustainable material for suitable application	K2/K6
CO5	Develop novel material by spectroscopic knowledge for specified applications and to providing a functional device	K6

Course outcome Vs Programme outcomes

PO/CO	PO 1	PO 2	PO 3	PO 4	PO 5	PO 6	PO 7	PO 8	PO 9	PO 10
CO 1	S (3)	S (3)	S (3)	M (2)	M (2)	M (2)	S (3)	L(1)	S (3)	M (2)
CO 2	S (3)	S (3)	L(1)	S (3)	M (2)	L(1)				
CO 3	S (3)	M (2)	S (3)	S (3)	M (2)	M (2)	M (2)	S (3)	S (3)	L(1)
CO 4	S (3)	S (3)	S (3)	M (2)	S (3)	S (3)	M (2)	M (2)	S (3)	M (2)
CO 5	M (2)	M (2)	S (3)	M (2)	S (3)	M (2)	S (3)	S (3)	M (2)	M (2)
W. AV	2.8	2.6	2.6	2.4	2.6	2.4	2.6	2.4	2.6	1.6

Course Outcome Vs Programme Specific Outcome

PSO/CO	PSO 1	PSO 2	PSO 3	PSO 4	PSO 5
CO 1	S (3)	M (2)	S (3)	S (3)	S (3)
CO 2	S (3)	S (3)	M (2)	M (2)	M (2)
CO3	S (3)	S (3)	S (3)	M (2)	L(1)
CO 4	S (3)	S (3)	S (3)	S (3)	M (2)
CO 5	M (2)	S (3)	S (3)	M (2)	M (2)
W. AV	2.8	2.8	2.8	2.4	2

S –Strong (3), M-Medium (2), L- Low (1)



			II-SEMES'	TER					
Core 8	Cou	irse code:542203	Quantum Mo	echanics	T	Credits: 4	Hours: 4		
			Unit I		'				
Objective	1	To know the fundar	nentals relations of	Quantum Mo	echanics	with Mathen	natical		
		Physics							
MATHEMA	ATI	CS FOR QUANTI	UM MECHANICS	(QM) AND	QM P	OSTULATE	S- Coordinate		
systems, Co	omp	lex numbers, Funct	tions (odd & even,	orthogonali	ty and	normalization), Differential		
equations, C)per	ators: linear, differe	ntial, and Hermitian	and Hamilto	nian op	erators, Eigen	functions and		
Eigen values	s, Fa	ilure of Classical M	echanics and the nee	d for QM, Po	stulates	of QM, time-	dependent and		
time-indepen	iden	t Schrodinger wave e	equations						
Outcome	1	Students understar	nd the basic informa	tion of Oper	ators, E	Ligen	K1, K2		
Outcome	1	functions and Eigen values and Postulates of QM.							
			Unit I	[
Objective	2	To learn propertie	s and applications o	f Quantum n	nodels				
QM MODE	ELS	AND THEIR APP	PLICATIONS—Parti	cle in a box	(1D, 2D) & 3D), dege	eneracy and its		
application 1	to li	near conjugated mo	lecular systems, fre	e particle. Bo	ohr's co	rrespondence	principle. QM		
tunnelling, F	Rigi	d Rotor: wave equat	ion and solution cale	culation of ro	otational	constants and	l bond length,		
Harmonic Os	scill	ator: wave equation a	and solution, anharmo	onicity force of	constant	and its signific	cance		
Outcome	2	Learners understa	nd the important of	QM applica	tions in	3D and	K2, K3		
Outcome	4	harmonicity.	CALARAMA INIU	coerry S	k i				
		3	Unit II	ENSILI S	Tree .				
Objective	3	To gain knowledge	on single and mult	i <mark>-elect</mark> rons sy	stem us	age			
APPLICAT	ION	OF OM TO H-AT	OM AND MULTI-	EL <mark>ECTRON</mark>	ATOM	S –The Hydro	gen atom and		
H-like ions:	Sol	ution to H and H-lik	te <mark>wa</mark> ve e <mark>quation, ra</mark>	<mark>d</mark> ial a <mark>nd</mark> angu	ılar func	ctions, quantui	n numbers n, l		
and m and t	heir	importance. the rad	ia <mark>l d</mark> istr <mark>ibut</mark> ion funct	<mark>tion</mark> s a <mark>nd</mark> H-l	ike orbi	tals and their	representation,		
Approximati	ion	Methods: The variati	on <mark>m</mark> etho <mark>d - trial var</mark>	<mark>iation fu</mark> nctio	n and va	ariational integ	gral (examples		
of variationa	ıl ca	lculations f <mark>rom p</mark> artio	ele i <mark>n a</mark> box)		A				
Outcome	3	Students analyze t	he im <mark>porta</mark> nt and us	s <mark>es of</mark> H atom	and va	riation	K3, K4,		
		methods		W AS			K5		
			Unit IV						
Objective	4	To familiarize ang	ular momentum and	tools for de	rivation				
QUANTUM		MECHANICAL	TREATMENT	OF AN	[GULA]	R TTMO	MENTUM –		
simultaneous			1 6		.	(T 1 1/T 2		
			valuation of commut						
_			The electron spin, Pa	auli exclusion	ı princip	ole and Stater of	leterminant for		
Outcome		Students get exper	and II coupling	me colvina n	nothode		K4, K5		
Outcome	4	Students get exper	Unit V		nethous		K4, K3		
Objective	5	To learn more reg	arding the importan		a crysta	le			
, and the second			AICAL BONDING				use of linear		
			od, Hydrogen moleci						
			njugated systems: H			-			
butadiene an			njugated systems. II	iuckei iiitiilo	и аррис	a to emylene	. Allyi system		
outautette all	4 00		nd the significance o	f molooular			K2 K5		
Outcome	5		nd the significance o	i molecular			K2, K5		
		bonding crystals							

Suggested Readings -

- A.K. Chandra, Introductory Quantum Chemistry, 4thed. Tata McGraw Hill 1994.
- I.N. Levine, Quantum Chemistry, 5thedn, Prentice Hall, 2000.
- P.W. Atkins, Molecular Quantum mechanics, Clarendon Press New York, 1973.
- R.K. Prasad, Quantum Chemistry, New Age International Publishers, New Delhi, 1997.
- R.P. Rastogi and V.K. Srivastava. An Introduction to Quantum Mechanics of Chemical Systems. Oxford &: IBH Publishing Co. New Delhi 1986

Donald A. McQuarrie, Quantum Chemistry. Viva Books PW. Ltd. New Delhi. 2003

P.W. Atkins and Julio de Paula. Atkins' Physical Chemistry, VII ed. Oxford University Press. 2002.

Online resources:

 $https://www.cambridge.org/highereducation/books/quantummechanics/C114CA0F4A218733CEEC875\\9DFA4661C\#overview$

https://onlinelibrary.wiley.com/doi/book/10.1002/0471654817.

K1-Remember	K2-Understand	K3-Apply	K4-Analyse	K5-Evaluate	K6-Create						
	Course designed by: Dr. J. B. Arul Joseph Helen Therese										

Course Outcomes

CO1	Comprehend the modern theory and issues with quantum materials.	K1, K2
CO2	Apply quantum theory in confined maters.	K2, K3
СОЗ	Analyze the physical behavior of electrons in atoms.	K3, K4, K5
CO4	Recognize the angular moment and the particle coupling mechanism.	K4, K5
CO5	Learn about the solutions for bonding in quantum particles.	K2, K5

Course outcome Vs Programme outcomes

PO/ CO	PO 1	PO 2	PO 3	PO 4	PO 5	PO 6	PO 7	PO 8	PO 9	PO 10
CO 1	S (3)	S (3)	M (2)	S (3)	M (2)	S (3)				
CO 2	S (3)	S (3)	S (3)	S (3)	M (2)	S (3)	S (3)	M (2)	M (2)	S (3)
CO3	S (3)	S (3)	M (2)	S (3)	S (3)	M (2)				
CO 4	S (3)	M (2)	M (2)	M (2)	M (2)	S (3)				
CO 5	S (3)	M (2)	S (3)	M (2)	S (3)	M (2)				
W. AV	3	2.8	2.6	2.8	2.6	2.4	2.4	2.2	2.2	2.6

Course Outcome Vs Programme Specific Outcome

PSO/ CO	PSO 1	PSO 2	PSO 3	PSO 4	PSO 5
CO 1	S (3)	M (2)	S (3)	S (3)	S (3)
CO 2	S (3)	S (3)	M (2)	M (2)	M (2)
CO 3	S (3)	S (3)	S (3)	M (2)	L(1)
CO 4	S (3)	S (3)	S (3)	S (3)	M (2)
CO 5	M (2)	S (3)	S (3)	M (2)	M (2)
W. AV	2.8	2.8	2.8	2.4	2

S-Strong (3), M-Medium (2), L-Low (1)



		II-SEMESTER			
Core 9	Course code:542204	Crystal Growth	T	Credits: 4	Hours: 4
	1	Unit -I			
		pts of nucleation and types o			
	=	- Homogeneous, heterogen			
		c theory of nucleation – statis	tical theo	ry of nucleati	on – nucleation
rate – inducti	-				
Outcome1	Familiar with the concep	ots of nucleation and its theo	ry		K1
		Unit II			
	To learn the theoretical a				
		H - Two-dimensional nuclear		•	•
_		BCF surface diffusion theor	y – soluti	on of BCF su	rface diffusion
	nospheric nucleation.				
Outcome 2	Gain knowledge about th				K2, K3
		Unit III			
Objective 3	To learn various method	ds of melt growth.			
	-	easurement and control - S	_		-
		ess – Bridgman method – Cz		method - Ve	meuil method -
Zone melting	-	nelt growth – theory and expe			
Outcome 3	Familiar with what is n	nelt growth and various met	hods of m	elt growth.	K4, K5
	201	Unit IV	-		
		n the growth of crystals by s			
		ent of supersaturation – Low	-		
_	_	<mark>te</mark> d cru <mark>cible rotati</mark> on te <mark>ch</mark> niqu	•		
Crystal grow	th in gel – Growth of biolo	gical <mark>cry</mark> sta <mark>ls</mark> – Hydroth <mark>er</mark> ma	l techniqu	ıe – Sol-gel gı	owth
Outcome 4	Expert in the solution gr	owth method.			K4, K5
		Unit V	A		
Objective 5	To understand various	methods of growing crystals	from vap	our phase.	
VAPOUR G	ROWTH - Physical vapou	r tran <mark>s</mark> port –chemi <mark>ca</mark> l vapor tr	ansport. I	Epitaxial grow	th techniques –
Liquid phase	epitaxy - vapour phase ep	itaxy: chloride, hydride, meta	alorganic	- molecular b	eam epitaxy -
chemical bea	m epitaxy.	PARINEHEELI E			
Outcome 5	Gain knowledge on gro	wth of crystals from their va	por phas	e.	K6
Suggested Ro	eadings:-				
Bhat H.L. (2	2019). Introduction to cryst	al growth. Tailor and Francis.			
Brice J.C. (1	986). Crystal Growth Proc	esses. John Wiley and sons, N	lew York.		
Dryburgh F	P.M, Cockayane Band Ba	rraclough K.G. (1986). Adv	ance Cry	stal Growth.	Prentice Hall,
London.					
Ohara M. A	nd ReidR.C. (1973). Mode	lling Crystal Growth Rates fro	m Solutio	on.	
7 wattlamaria	erA.C. (1969). Nucleation.	Margal Dakkar Dublishara			

Crystal Growth Online (http://crystalgrowthonline.com/): This website provides a collection of resources, articles, and information on crystal growth techniques and research.

American Association for Crystal Growth (AACG) (http://www.crystalgrowth.org/): AACG is a professional organization focused on crystal growth and provides access to conference proceedings, publications, and educational resources.

https://www.youtube.com/@veritasium This channel covers various science topics, including crystal growth and material science.

K1-Remember	K2-Understand	K3-Apply	K4-Analyse	K5-Evaluate	K6-Create
			(Course designed	by: Dr. C. Sekar

Course Outcome

CO1	Understand nucleation mechanisms and its role in material formation	K1, K2
CO2	Analyze various theories explaining crystal growth phenomena	K2
СОЗ	Gain proficiency in techniques and principles of crystal growth from melts	K3, K5
CO4	Explore the fundamentals and different methods of crystal growth from solutions	K2, K4
CO5	Comprehend vapor-phase crystal growth methods and their practical applications	K1, K2, K6

Course outcome Vs Programme outcomes

PO/CO	PO 1	PO 2	PO 3	PO 4	PO 5	PO 6	PO 7	PO 8	PO 9	PO 10
CO 1	S (3)	S (3)	M (2)	M (2)	M (2)	M (2)	S (3)	S (3)	S (3)	S (3)
CO 2	S (3)	S (3)	S (3)	M (2)	S (3)	L (1)	M (2)	M (2)	M (2)	L(1)
CO 3	S (3)	S (3)	S (3)	S (3)	L(1)	S (3)				
CO 4	S (3)	S (3)	S (3)	S (3)	M (2)	M (2)	S (3)	S (3)	S (3)	S (3)
CO 5	S (3)	S (3)	S (3)	L(1)	L(1)	S (3)				
W. AV	3	3	2.8	2.2	1.8	2.2	2.8	2.8	2.8	2.6

S – Strong (3), M-Medium (2), L-Low (1)

Course Outcome Vs Programme Specific Outcome

PSO/ CO	PSO 1	PSO 2	PSO 3	PSO 4	PSO 5
CO 1	S (3)	M (2)	S (3)	S (3)	M (2)
CO 2	M (2)	L(1)	S (3)	S (3)	M (2)
CO3	S (3)	M (2)	S (3)	S (3)	M (2)
CO 4	S (3)	M (2)	S (3)	S (3)	S (3)
CO 5	S (3)	L(1)	S (3)	S (3)	S (3)
W. AV	2.8	1.6	3	3	2.4

		II-SEMESTER				
Core 10	Course code:	LAB II Materials synthesis and	ī	P	Credits: 4	Hours: 8
Core to	542205	characterization	1	L	Credits. 4	mours. o
	The objective o	f the course is to make the students				
	• gain practical	knowledge on preparation of polymers a	and prope	erties		
ves	understand the	e physical and chemical processes of pol	lymers			
ecti		th polymer characterization methods				
Objectives	familiarize with	th use of polymer materials in different	application	on		
C	develop the all	pility to design a hypothesis driven rese	earch pro	ject :	and design a	and execute
	experiments to	o evaluate the stated hypothesis				
	1. High tempera	ture synthesis of materials				
	2. Sol-gel synth	nesis of metal oxide composites				
	3. Hydrogel syn	thesis of oxide composites				
	4. Electrochem	ical characterization of material behavio	our			
	1 -	nanocarbon materials				
	6. FTIR charact	erization of materials				
	7. TG-DTA stud	dies of nanomaterials				
	8. Powder X-ray	y diffraction- indexing, lattice parameter	rs and uni	it cel	l volume cal	culation
	9. Composite of	f metal oxides preparation				
	_	of carbon and metal	3			
	11. Composites	of polymer and carbon	3			
	_	of polymer and metal oxide	0			
	-	tion and confirmation				
Experiments		nical sensing of glucose				
ime		nical prep <mark>ar</mark> ation of thin films				
per	16. Thin film fo	rmation o <mark>n</mark> metal surfaces				
Ex]	17. Differential	pulse voltammetry technique	1			
Ø	After completi	on of this course, students synthesi	ze differ	rent	types of na	nomaterials
me	including metal	l oxides, carbo <mark>n na</mark> nostructur <mark>es</mark> , compo	sites and	l poly	mers. Stude	ents perform
Outcomes	preliminary cha	aracterization for confirming the form	nation of	the 1	target mater	ial either as
Ō	single phase or	as composites.				
	1	SALUE STORY				

1		II-SEMESTER			
DSE Cours	se code :542507	Molecular Spectroscopy	T	Credits: 3	Hours: 3
1	-	Unit - I			
Objective 1	To recall the bas	ic nature of Bonding's of materials			
SYMMETRY	ASPECTS OF	MOLECULAR ORBITALS -Vale	nce bond	theory - Molec	ular orbital
theory- Heitler	London theory fo	r Hydrogen molecule - Hybridization -	$-SP - SP^2$	² & SP ³ Hybrids.	
Outcome 1	Students under	stand the basic information of band	theory an	d its	V1 V2
Outcome 1	applications.				K1, K2
		Unit - II			
•	•	perties and important conditions of			
		Rotational energy of a diatomic mole		-	
isotopic subst	itution – Stark ef	ffect – its importance in microwave	spectrosc	opy – quadrupo	le hyperfine
	_	of polyatomic molecules – pure rotati		_	tomic linear
molecule – syr	nmetric top molec	cules- Molecular structure – using IR &	Raman s	pectroscopy.	
Outcome 2		s the formation and properties of ro	tating dia	tomic and	K2, K3,
	polyatomic mol				K5
		Unit - III			
, ,		dge on vibrational and Raman spect	1.0		
		ES- Vibrational spectra of diatomic an			
		IR studies - Vibrational Raman spo	and the same of th		
		anck - Condon principle - intensity	/ distribu	tion – portrait p	parabolae –
		on – mutual exclusion principle.			
Outcome 3	Students analyz	ze the impo <mark>rtan</mark> ce an <mark>d u</mark> se of <mark>vib</mark> ratin	g molecu	les.	K3, K4
		Unit - IV			K3, K4
Objective 4	To familiarize N	Unit - IV Non-linear effects and modern tools 1	or charac	eterization	
Objective 4	To familiarize N R SPECTROSCO	Unit - IV Non-linear effects and modern tools t OPIC PHENOMINA - Non-linear Ra	or charac	eterization nomena-Hyper R	aman effect
Objective 4 NON-LINEA Classical trea	To familiarize N R SPECTROSCO tment –Exper <mark>ime</mark>	Unit - IV Non-linear effects and modern tools to OPIC PHENOMINA - Non-linear Raental techniques- Stimulated Raman	or charac man Pher Scatterin	terization nomena-Hyper R ng –Inverse Ra	aman effect man Effect
Objective 4 NON-LINEA Classical trea Coherent Anti	To familiarize N R SPECTROSCO tment –Experime -Stoke's Raman S	Unit - IV Non-linear effects and modern tools to OPIC PHENOMINA - Non-linear Racental techniques - Stimulated Raman Scattering-Photo acoustic Raman Scat	or charac man Pher Scatterin tering-Mu	eterization nomena-Hyper R ng –Inverse Ra ulti photon spect	aman effect man Effect roscopy-two
Objective 4 NON-LINEA Classical trea Coherent Anti photon absorp	To familiarize N R SPECTROSCO tment –Experime -Stoke's Raman S	Unit - IV Non-linear effects and modern tools to OPIC PHENOMINA - Non-linear Raental techniques- Stimulated Raman	or charac man Pher Scatterin tering-Mu	eterization nomena-Hyper R ng –Inverse Ra ulti photon spect	aman effect man Effect roscopy-two
Objective 4 NON-LINEA Classical trea Coherent Anti photon absorp molecules.	To familiarize NR SPECTROSCO tment -Experime -Stoke's Raman Sotion- Multiphoton	Unit - IV Non-linear effects and modern tools of OPIC PHENOMINA - Non-linear Racental techniques - Stimulated Raman Scattering-Photo acoustic Raman Scattering absorption. X-ray spectra; rotational	or charac man Pher Scatterin tering-Mu I and vib	eterization nomena-Hyper R ng –Inverse Ra ulti photon spect	aman effect man Effect roscopy-two of diatomic
Objective 4 NON-LINEA Classical trea Coherent Anti	To familiarize NR SPECTROSCO tment -Experime -Stoke's Raman Sotion- Multiphoton	Unit - IV Non-linear effects and modern tools to OPIC PHENOMINA - Non-linear Ragental techniques - Stimulated Raman Scattering-Photo acoustic Raman Scatn absorption. X-ray spectra; rotational ise on NLO crystals and analysing n	or charac man Pher Scatterin tering-Mu I and vib	eterization nomena-Hyper R ng –Inverse Ra ulti photon spect	aman effect man Effect roscopy-two
Objective 4 NON-LINEA Classical trea Coherent Anti photon absorp molecules. Outcome 4	To familiarize MR SPECTROSCO tment -Experime -Stoke's Raman Sotion- Multiphoton Students expert	Unit - IV Non-linear effects and modern tools to OPIC PHENOMINA - Non-linear Ratental techniques- Stimulated Raman Scattering-Photo acoustic Raman Ra	or charace man Pher Scattering tering-Mu I and vib	eterization nomena-Hyper R ng —Inverse Ra alti photon spect rational spectra	aman effect man Effect roscopy-two of diatomic
Objective 4 NON-LINEA Classical trea Coherent Anti photon absorp molecules. Outcome 4 Objective 5	To familiarize MR SPECTROSCO tment -Experime -Stoke's Raman Sotion- Multiphoton Students expert	Unit - IV Non-linear effects and modern tools of OPIC PHENOMINA - Non-linear Racental techniques - Stimulated Raman Scattering-Photo acoustic Raman Scattering-Photo acoustic Raman Scattering absorption. X-ray spectra; rotational ise on NLO crystals and analysing modern Unit - V e regarding the resonance functions	or charace man Pher Scattering tering-Mul and vib methods	nomena-Hyper R ng –Inverse Ra ulti photon spectra	aman effect- man Effect- roscopy-two of diatomic K4, K5
Objective 4 NON-LINEA Classical trea Coherent Anti photon absorp molecules. Outcome 4 Objective 5 RESONANC	To familiarize N R SPECTROSCO tment -Experime -Stoke's Raman Sotion- Multiphoton Students expert To learn mor E SPECTROSCO	Unit - IV Non-linear effects and modern tools to OPIC PHENOMINA - Non-linear Ragental techniques - Stimulated Raman Scattering-Photo acoustic Raman Scattering-Photo acoustic Raman Scattering - Photo acoustic Raman Rama	or charace man Pher Scattering-Mul and vib methods and their magnetic	nomena-Hyper R ng –Inverse Ra ulti photon spectra rational spectra spectroscopy te field – Nuclear	aman effect- man Effect- roscopy-two of diatomic K4, K5 chniques resonance -
Objective 4 NON-LINEA Classical trea Coherent Anti photon absorp molecules. Outcome 4 Objective 5 RESONANC	To familiarize MR SPECTROSCO tment -Experime -Stoke's Raman Sotion- Multiphoton Students expert To learn mor E SPECTROSCO	Unit - IV Non-linear effects and modern tools of OPIC PHENOMINA - Non-linear Rate and techniques - Stimulated Raman Scattering-Photo acoustic Raman Scattering-Photo acoustic Raman Scattering absorption. X-ray spectra; rotational ise on NLO crystals and analysing manual of the regarding the resonance functions OPY - Interaction between spin and iff - Dipole -Dipole interaction and	or charace man Pher Scattering-Mul I and vib methods and their magnetic spin lattic	terization nomena-Hyper R ng -Inverse Ra ulti photon spectra rational spectra spectroscopy te field - Nuclear re interaction - I	aman effect man Effect roscopy-two of diatomic K4, K5 chniques resonance - Mossbauer -
Objective 4 NON-LINEA Classical trea Coherent Anti photon absorp molecules. Outcome 4 Objective 5 RESONANC Bloch equatio ESR-NQR (pr	To familiarize MR SPECTROSCO tment -Experime -Stoke's Raman Sotion- Multiphoton Students expert To learn mor E SPECTROSCO ns - Chemical shirtinciple only) spe	Unit - IV Non-linear effects and modern tools to OPIC PHENOMINA - Non-linear Ragental techniques- Stimulated Raman Scattering-Photo acoustic Raman	or charace man Pher Scattering-Mit I and vib methods and their magnetic spin lattice sbauer sp	cterization nomena-Hyper R ng —Inverse Ra ulti photon spect rational spectra spectroscopy te field — Nuclear e interaction — I ectroscopy — app	aman effectman Effectroscopy-two of diatomic K4, K5 chniques resonance - Mossbauer -
Objective 4 NON-LINEA Classical trea Coherent Anti photon absorp molecules. Outcome 4 Objective 5 RESONANC Bloch equatio ESR-NQR (pr	To familiarize N R SPECTROSCO tment -Experime -Stoke's Raman Sotion- Multiphoton Students expert To learn mor E SPECTROSCO ns - Chemical shirtinciple only) specture - molecular	Unit - IV Non-linear effects and modern tools to OPIC PHENOMINA - Non-linear Ragental techniques- Stimulated Raman Scattering-Photo acoustic Raman Ram	ior charace man Pher Scattering-Mul 1 and vib methods and their magnetic spin lattic sbauer specular structure	cterization nomena-Hyper R ng —Inverse Ra ulti photon spect rational spectra spectroscopy te field — Nuclear re interaction — I ectroscopy - appetures.	aman effectman Effectroscopy-two of diatomic K4, K5 chniques resonance - Mossbauer -
Objective 4 NON-LINEA Classical trea Coherent Anti photon absorp molecules. Outcome 4 Objective 5 RESONANC Bloch equatio ESR-NQR (pr	To familiarize N R SPECTROSCO tment -Experime -Stoke's Raman Sotion- Multiphoton Students expert To learn mor E SPECTROSCO ns - Chemical shirtinciple only) specture - molecular	Unit - IV Non-linear effects and modern tools to OPIC PHENOMINA - Non-linear Ragental techniques- Stimulated Raman Scattering-Photo acoustic Raman	ior charace man Pher Scattering-Mul 1 and vib methods and their magnetic spin lattic sbauer specular structure	cterization nomena-Hyper R ng —Inverse Ra ulti photon spect rational spectra spectroscopy te field — Nuclear re interaction — I ectroscopy - appetures.	aman effect man Effect roscopy-two of diatomic K4, K5 chniques resonance - Mossbauer -
Objective 4 NON-LINEA Classical trea Coherent Anti photon absorp molecules. Outcome 4 Objective 5 RESONANC Bloch equatio ESR-NQR (pr	To familiarize MR SPECTROSCO tment -Experime -Stoke's Raman Socion- Multiphoton Students expert To learn more E SPECTROSCO ns - Chemical shirtinciple only) specture - molecular Students under	Unit - IV Non-linear effects and modern tools to OPIC PHENOMINA - Non-linear Ragental techniques- Stimulated Raman Scattering-Photo acoustic Raman Ram	ior charace man Pher Scattering-Mul 1 and vib methods and their magnetic spin lattic sbauer specular structure	cterization nomena-Hyper R ng —Inverse Ra ulti photon spect rational spectra spectroscopy te field — Nuclear re interaction — I ectroscopy - appetures.	aman effects man Effects roscopy-two of diatomic K4, K5 chniques resonance - Mossbauer - plications -
Objective 4 NON-LINEA Classical trea Coherent Anti photon absorp molecules. Outcome 4 Objective 5 RESONANC Bloch equatio ESR-NQR (pr Electronic stru Outcome 5 Suggested	To familiarize N R SPECTROSCO tment -Experime -Stoke's Raman Sotion- Multiphoton Students expert To learn mor E SPECTROSCO ns - Chemical shirtinciple only) specture - molecular Students under Readings:-	Unit - IV Non-linear effects and modern tools to OPIC PHENOMINA - Non-linear Ragental techniques- Stimulated Raman Scattering-Photo acoustic Raman Ram	ior charace man Pher Scattering-Mul l and vib methods and their magnetic spin lattic sbauer spin cular structers spectros	sterization nomena-Hyper R ng —Inverse Ra ulti photon spect rational spectra spectroscopy te field — Nuclear re interaction — I ectroscopy - appetures. scopy.	aman effect man Effect roscopy-two of diatomic K4, K5 chniques resonance - Mossbauer - plications -
Objective 4 NON-LINEA Classical trea Coherent Anti photon absorp molecules. Outcome 4 Objective 5 RESONANC Bloch equatio ESR-NQR (pr Electronic stru Outcome 5 Suggested Aruldhass G	To familiarize MR SPECTROSCO tment -Experime -Stoke's Raman Sotion- Multiphoton Students expert To learn more E SPECTROSCO ns - Chemical shirtinciple only) specture - molecular Students under Readings: (2001). Molecular	Unit - IV Non-linear effects and modern tools to OPIC PHENOMINA - Non-linear Ragental techniques - Stimulated Raman Scattering-Photo acoustic Raman Scattering-Photo acoustic Raman Scattering - Photo acoustic Raman Scattering - NLO crystals and analysing in Unit - V e regarding the resonance functions OPY - Interaction between spin and actroscopy and its application - Mos structure - crystal symmetry and mole stand of the resonance and resonance	or charace man Pher Scattering-Mul I and vib and their magnetic spin lattic spin lattic sbauer spin cular struct e spectros	sterization nomena-Hyper R ng —Inverse Ra ulti photon spectr rational spectra spectroscopy te field — Nuclear re interaction — I ectroscopy - app stures. scopy. dia, New Delhi.	aman effect man Effect roscopy-two of diatomic K4, K5 chniques resonance - Mossbauer - plications -
Objective 4 NON-LINEA Classical trea Coherent Anti photon absorp molecules. Outcome 4 Objective 5 RESONANC Bloch equatio ESR-NQR (pr Electronic stru Outcome 5 Suggested Aruldhass G Colin N Ban	To familiarize MR SPECTROSCO tment -Experime -Stoke's Raman Socion- Multiphotor Students expert To learn mor E SPECTROSCO ns - Chemical shirtinciple only) specture - molecular Students under Readings: (2001). Molecular well. (2019). Fundament.	Unit - IV Non-linear effects and modern tools of OPIC PHENOMINA - Non-linear Rasental techniques- Stimulated Raman Scattering-Photo acoustic Raman Scattering-	for charace man Pher Scattering Mittering Mitt	sterization nomena-Hyper R ng —Inverse Ra ulti photon spect rational spectra spectroscopy te field — Nuclear se interaction — I sectroscopy - app stures. scopy. dia, New Delhi.	aman effects man Effects roscopy-two of diatomic K4, K5 chniques resonance - Mossbauer - plications -
Objective 4 NON-LINEA Classical trea Coherent Anti photon absorp molecules. Outcome 4 Objective 5 RESONANC Bloch equatio ESR-NQR (pr Electronic stru Outcome 5 Suggested Aruldhass G Colin N Ban Dogra S.K. (To familiarize N R SPECTROSCO tment -Experime -Stoke's Raman Sotion- Multiphoton Students expert To learn mor E SPECTROSCO ns - Chemical shirtinciple only) specture - molecular Students under Readings: (2001). Molecular twell. (2019). Fundation of the content of the co	Unit - IV Non-linear effects and modern tools of OPIC PHENOMINA - Non-linear Ragental techniques- Stimulated Raman Scattering-Photo acoustic Raman Scattering-	ior charace man Pher Scattering-Mul I and vib I and their magnetic spin lattic sbauer spin lattic sbauer spin lattic spaular structions. Hall of In McGraw blications.	sterization nomena-Hyper R ng —Inverse Ra ulti photon spect rational spectra spectroscopy te field — Nuclear se interaction — I sectroscopy - app stures. scopy. dia, New Delhi.	aman effectman Effectoroscopy-two of diatomic K4, K5 chniques resonance - Mossbauer - plications -

Fundamental Concepts of Molecular Spectroscopy – https://www.routledge.com/book/9781032274850. Nuclear Magnetic Resonance Spectroscopy an Introduction to principles, Applications and experimental methods -https://www.wiley.com/book/978111929580.

Shaffner, T. J. (1986) "A Review of Modern Characterization Methods for Semiconductor Materials," Scanning Electron Microscopy: Vol. 1986: No. 1, Article 2, https://digitalcommons.usu.edu/electron/vol1986/iss1/2

K1-Remember	K2-Understand	K3-Apply	K4-Analyse	K5-Evaluate	K6-Create
			Course des	igned by: Dr. S. S	aravana Kumar

Course Outcome

CO1	Learn basic principles of many molecule structures.	K1, K2
CO2	Analyze and apply the various molecular characterization techniques.	K2, K3, K5
CO3	Discover the various movements of molecule.	K3, K3, K4
CO4	Analytical expertise with non-linear spectroscopic materials.	K4, K5
CO5	Learn about resonance spectroscopy and apply it on materials.	K5, K6

Course outcome Vs Programme outcomes

PO/CO	PO 1	PO 2	PO 3	PO 4	PO 5	PO 6	PO 7	PO 8	PO 9	PO 10
CO 1	S (3)	S (3)	M (2)	S (3)	M (2)	S (3)	S (3)	M (2)	M (2)	M (2)
CO 2	M (2)	M (2)	S (3)	S (3)	S (3)	M (2)	S (3)	M (2)	S (3)	S (3)
CO 3	S (3)	S (3)	M (2)	S (3)	S (3)	M (2)	M (2)	M (2)	S (3)	M (2)
CO 4	S (3)	M (2)	M (2)	M (2)	S (3)	M (2)				
CO 5	M (2)	S (3)	S (3)	M (2)	S (3)	M (2)	M (2)	S (3)	M (2)	S (3)
W. AV	2.6	2.8	2.6	2.8	2.8	2.2	2.4	2.2	2.6	2.2

S –Strong (3), M-Medium (2), L-Low (1) Course

Outcome Vs Programme Specific Outcome

PSO/CO	PSO 1	PSO 2	PSO 3	PSO 4	PSO 5
CO 1	S (3)	S (3)	M (2)	M (2)	M (2)
CO 2	S (3)	M (2)	M (2)	S (3)	M (2)
CO 3	S (3)	M (2)	M (2)	M (2)	M (2)
CO 4	S (3)	M (2)	M (2)	M (2)	M (2)
CO 5	S (3)	S (3)	M (2)	M (2)	M (2)
W. AV	3	2.4	2.0	2.2	2.0

II-SEMESTER						
DSE Course code:542508 Semiconductor Materials and Devices T	Hours: 3					
Unit - I						
Objective 1 To introduce the concepts of various semiconductor principles, properties and their functions.						
INTRODUCTION -Introduction: Properties of semiconductors -Free electron Theory - Trans	port properties.					
Bonds and Bands in Semiconductor: -Electronic band structure - Junction Properties of so	emiconductors-					
Recombination mechanism - Electron, Hole recombination through traps - Junction properties	s of p-n, n+-n,					
p+-p junctions - Surface recombination - Recombination with donors and acceptors at low t	temperatures -					
Quantum theory of junction devices - Generation of recombination processes in junction devices.						
Outcome 1 The students gain knowledge on energy band structures.	K2					
Unit - II						
Objective 2 To introduce the students about various optical properties and their applica						
OPTICAL PROPERTIES - Optical properties of semiconductors - Optical constants - Li						
spectrum - Light absorption edge - Effect of free charge carriers on the absorption edge - Fu						
absorption and reflection- Electron transport phenomena: Theory of electron transport	•					
semiconductors - Boltzmann's transport equation for Bloch states - relaxation time - re	elaxation time					
approximation to the low field transport coefficients - scattering mechanism.						
Outcome 2 Students understand the basic and optical properties of materials.	K4					
Unit - III						
Objective 3 To expose the students to basic transport properties in semiconductor devices						
TRANSPORT PROPERTIES – Basic Process in Semiconductor Devices: Equilibrium prope						
and holes – impurities in semiconductors - carrier concentration as a function of temperature						
effects - Non-equilibrium phenomena - carrier transport - Transport properties in high fields – and generation processes - breakdown mechanism – Basic equations for Semiconductor devices.						
for the interior of devices – boundary conditions – Systems.	es - equations					
Outcome 3 Learners understand fundamentals to Understand on transport properties in materials.	K4					
Unit - IV						
Objective 4 To study the properties and fabrication of various transistors and their char						
FABRICATION OF TRANSISTORS AND THYRISTORS - Unipolar devices: Metal-						
contacts - Energy - Band Relation - Schottky Effect -Characterization of Barrier Height - Dev						
Ohmic Contact - JFET and MESFET - basic device characteristic - general characteristic - M						
device characteristic - MOSFET Structures - Nonvolatile memory devices. Bipolar translators above translator, switching translator. Thyristory basic characteristics. So						
characteristics - power transistor - switching transistor – Thyristors - basic characteristics - Sc Three terminal thyristor.	nouky diode -					
Outcome 4 Learners gain knowledge on fabrication of semiconductor devices.	K2					
Unit - V	K2					
To make the students about fabrication of LED's and Sensors in photonic dev	vice					
Objective 5 applications.						
FABRICATION OF LED'S AND SENSORS -Photonic Devices: Light Emitting diodes -						
optics - LED performance - reliability - Photodetectors - Photoconductor - Photodiode						
Photodiode - Phototransistor - Solar cells - Thin film solar cells - solid state sensors, opt optoelectronic components.	ical Sensors -					
Outcome 5 Learners understand different fabrication steps in optoelectronic devices.	K5					
2 2 2 2 2 2 2 2 2 2 2 2 2 2 2 2 2 2 2						

Suggested Readings:-

Butcher P.N, MarchN.H. andTosi M.P. (2014). Crystalline Semiconducting Materials and Devices. Springer.

Fraser D.A. (1986). The Physics of Semiconductor devices. Clarendon Press, Oxford.

Keller S.P. (1980). Handbook on Semiconductors, Vol. 1-4. T.S. Moss, Ed., North-Holland, Amsterdam.

Online resources

M. J. Deen & F. Pascal, Electrical characterization of semiconductor materials and devices—review, Journal of Materials Science: Materials in Electronics volume 17, pages549–575 (2006), https://link.springer.com/article/10.1007/s10854-006-0001-8.

International Technology Roadmap for Semiconductors—ITRS 2005 Edition, http://www.itrs.net/Common/2005ITRS/Home2005.htm.

K1-Remember	K2-Understand	K3-Apply	K4-Analyse	K5-Evaluate	K6-Create
•					

Course Outcome

CO 1	Gain knowledge on energy band structures.	K1, K2
CO 2	Understood the basic principles and optical properties of materials.	K2, K3
CO3	Make use of fundamental to Understand the principles of transport properties in materials.	K5
CO 4	Gain knowledge on fabrication of semiconductor devices.	K3, K4
CO 5	Understand different fabrication steps involved in optoelectronic devices.	K1, K6

Course outcome Vs Programme outcomes

PO/CO	PO 1	PO 2	PO 3	PO 4	PO 5	PO 6	PO 7	PO 8	PO 9	PO 10
CO 1	S (3)	M (2)	S (3)	M (2)	M (2)	S (3)	L (1)	M (2)	L(1)	M (2)
CO 2	S (3)	M (2)	M (2)	S (3)	S (3)	S (3)				
CO 3	M (2)	M (2)	S (3)	S (3)	S (3)	M (2)	M (2)	L(1)	L(1)	S (3)
CO 4	S (3)	S (3)	S (3)	S (3)	M (2)	M (2)	L(1)	M (2)	M (2)	M (2)
CO 5	M (2)	S (3)	S (3)	S (3)	S (3)	L(1)	L(1)	S (3)	S (3)	S (3)
W. AV	2.6	2.6	3	2.8	2.6	2	1.4	2.2	2	2.6

S – Strong (3), M-Medium (2), L-Low (1)

Course Outcome Vs Programme Specific Outcome

PSO/CO	PSO 1	PSO 2	PSO 3	PSO 4	PSO 5
CO 1	S (3)	M (2)	M (2)	S (3)	S (3)
CO 2	S (3)	S (3)	M (2)	M (2)	S (3)
CO 3	M (2)	M (2)	S (3)	M (2)	S (3)
CO 4	L(1)	M (2)	M (2)	S (3)	S (3)
CO 5	M (2)	M (2)	M (2)	S (3)	S (3)
W. AV	2.2	2.2	2.2	2.6	3

		II SEMESTER			
DSE C	ourse code:542509	Physical Metallurgy	T	Credits: 3	Hours: 3
		Unit - I			
Objective	To make the stud	ents understand about phase dia	gram of m	etallurgy.	
PHASE DIA	GRAMS -Composition	on and classification of pig iron ar	d cast iroi	n – iron ores -	manufacture o
wrought iron	and steel - The phase r	rule - Types of Binary Diagrams, -	- invariant	reactions- eut	tectic, eutectoic
peritectic and	peritectoid reactions	- Thermodynamics, Solution the	ory - free	energy comp	osition curves
Experimental	determination of equi	ilibrium diagram-grain size analy	sis, grain s	size measuren	nent - effect of
grain size on p	properties of metals and	d alloys.			
Outcomo	Students understan	d the principle involved in Einst	ein coeffic	ients	K1
Outcome	and action of laser.				Kı
		Unit - II			
Objective	2 To impact knowled	ge about iron carbon phase equi	librium di	agram and al	lloys
SOLID SOL	UTION - Types of so	olid solution – solid solution factor	ors govern	ing substitution	onal solubility
Hume-Rother	y rules- intermediate	phases -solid solution alloys -V	egard's la	w – Lever ru	le - mechanica
mixtures Ir	on-Carbon equilibrium	n diagram – Aluminum alloys	- Copper	alloys - Effe	ect of alloying
elements.					
Outcome '	The students gain l	knowledge on Iron-Carbon phase	equilibriu	ım	W2
Outcome 2	diagram.	This			K3
		Unit - III	5		
Ohioatiwa		The first control of the control of			
textures in co annealing, no	ATMENT – Recovery ld worked and anneal rmalizing, quenching	dents to various heat treatment py, recrystallisation and grain growled alloys,-TTT diagrams – CCT and tempering – baths used in he	vth: prope diagrams at treatme	rty changes, a – heat-treatm nt – hardenab	annealing twins nent processes ility – Jominy'
HEAT TRE. textures in co annealing, no end quench carburizing,	ATMENT – Recovery and worked and anneal rmalizing, quenching test – martempering riding, carbo nitriding.	y, recrystallisation and grain groveled alloys,-TTT diagrams – CCT and tempering – baths used in he g and austempering – case has	vth: prope diagrams at treatme ardening	rty changes, a – heat-treatm nt – hardenab	annealing twins nent processes ility – Jominy'
HEAT TRE. textures in co annealing, no end quench carburizing,	ATMENT – Recovery and worked and anneal rmalizing, quenching test – martempering riding, carbo nitriding.	y, recrystallisation and grain grow led alloys,-TTT diagrams – CCT and tempering – baths used in he g and austempering – case ha	vth: prope diagrams at treatme ardening	rty changes, a – heat-treatm nt – hardenab	annealing twins nent processes ility – Jominy'
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HEAT TRE. textures in co- annealing, no- end quench carburizing, cyaniding, nit Outcome (ATMENT – Recovery and worked and anneal rmalizing, quenching test – martempering riding, carbo nitriding. Students apply the	y, recrystallisation and grain growled alloys,-TTT diagrams – CCT and tempering – baths used in he g and austempering – case have evarious heat treatment process Unit - IV ents to understand about various	vth: prope diagrams at treatme ardening - es	rty changes, a - heat-treatm nt - hardenab - induction,	annealing twins nent processes ility – Jominy' flame, laser K2
HEAT TRE textures in co annealing, no end quench carburizing, cyaniding, nit Outcome Objective PHASE TRA	ATMENT – Recovery and worked and anneal remalizing, quenching test – martempering and students apply the To make the students apply the NSFORMATIONS	y, recrystallisation and grain grow led alloys,-TTT diagrams – CCT and tempering – baths used in he g and austempering – case ha e various heat treatment process Unit - IV ents to understand about various Types of phase changes – Driving	wth: prope diagrams at treatme ardening es phase tra	rty changes, a - heat-treatm nt - hardenab - induction, ansformations G aspects, dif	nannealing twins nent processes illity – Jominy' flame, laser K2 S Tusion in solids
HEAT TRE textures in co annealing, no end quench carburizing, cyaniding, nit Outcome Objective PHASE TRA – solidification	ATMENT – Recovery and worked and anneal rmalizing, quenching test – martempering a students apply the To make the students on – pearlitic transform – To make the students on – pearlitic transform – To make the students – To make	y, recrystallisation and grain growled alloys,-TTT diagrams – CCT and tempering – baths used in he g and austempering – case have evarious heat treatment process Unit - IV ents to understand about various	wth: prope diagrams at treatme ardening es phase tra	rty changes, a - heat-treatm nt - hardenab - induction, ansformations G aspects, dif	nannealing twins nent processes illity – Jominy' flame, laser K2 S Tusion in solids
HEAT TRE textures in co annealing, no end quench carburizing, cyaniding, nit Outcome Objective PHASE TRA – solidification	ATMENT – Recovery and worked and anneal rest in martempering test – martempering stiding, carbo nitriding. Students apply the To make the students apply the NSFORMATIONS - pearlitic transformed age hardening.	y, recrystallisation and grain growled alloys,-TTT diagrams – CCT and tempering – baths used in he g and austempering – case have evarious heat treatment process Unit - IV ents to understand about various errors of phase changes – Driving remations – martensitic transform	with: prope diagrams at treatme ardening - es sphase tra g forces, N- ations – k	rty changes, a - heat-treatm nt - hardenab - induction, ansformations G aspects, dif	nannealing twins nent processes illity – Jominy' flame, laser K2 S Tusion in solids
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HEAT TRE. textures in coannealing, no end quench carburizing, cyaniding, nit Outcome (Objective PHASE TRA — solidification precipitation Outcome (ATMENT – Recovery and worked and anneal rest in martempering test – martempering stiding, carbo nitriding. Students apply the To make the students apply the NSFORMATIONS – pearlitic transform and age hardening. Students gain known to mand the students gain known the students gain kno	y, recrystallisation and grain growled alloys,-TTT diagrams – CCT and tempering – baths used in he g and austempering – case has evarious heat treatment process. Unit - IV ents to understand about various ermations – martensitic transform owledge on phase transformations Unit - V ous engineering alloys and their	with: prope diagrams at treatme ardening - es sphase tra g forces, N- ations – k	rty changes, a - heat-treatm nt - hardenab - induction, unsformations G aspects, dif inetics of tra	mannealing twins nent processes ility – Jominy' flame, laser K2 S Tusion in solids nsformation - K4
HEAT TRE textures in co annealing, no end quench carburizing, cyaniding, nit Outcome Objective PHASE TRA – solidification precipitation Outcome Objective ENGINEER	ATMENT – Recovery and worked and anneal remalizing, quenching test – martempering and age hardening. To make the study and age hardening. Students gain known the students g	y, recrystallisation and grain growled alloys,-TTT diagrams – CCT and tempering – baths used in he g and austempering – case has evarious heat treatment process. Unit - IV ents to understand about various errors of phase changes – Driving remations – martensitic transform owledge on phase transformations Unit - V ous engineering alloys and their carbon steels – mild steels – high s	wth: prope diagrams at treatme ardening es sphase tra g forces, N- ations - k application trength str	rty changes, a - heat-treatm nt - hardenab - induction, ansformations G aspects, diffinetics of tra ns. uctural steels	mannealing twins nent processes ility – Jominy' flame, laser K2 S Tusion in solids nsformation - K4
HEAT TRE textures in co annealing, no end quench carburizing, cyaniding, nit Outcome Objective PHASE TRA – solidification precipitation Outcome Objective ENGINEER	ATMENT – Recovery and worked and anneal result worked worke	y, recrystallisation and grain grow led alloys,-TTT diagrams – CCT and tempering – baths used in he g and austempering – case ha le various heat treatment process Unit - IV ents to understand about various Types of phase changes – Driving mations – martensitic transform owledge on phase transformations Unit - V ous engineering alloys and their carbon steels – mild steels – high s at alloys – shape memory alloys –	with: prope diagrams at treatme ordening	rty changes, a - heat-treatm nt - hardenab - induction, ansformations G aspects, diffinetics of tra uctural steels as.	mannealing twins nent processes ility – Jominy' flame, laser K2 S Tusion in solids nsformation - K4
HEAT TRE textures in co annealing, no end quench carburizing, cyaniding, nit Outcome Objective PHASE TRA - solidification precipitation Outcome Objective ENGINEER - stainless ste Outcome	ATMENT – Recovery and worked and anneal remalizing, quenching test – martempering test – martempering and age hardening. To make the study and age hardening. To introduce various – super alloys – light and a	y, recrystallisation and grain growled alloys,-TTT diagrams – CCT and tempering – baths used in he g and austempering – case has evarious heat treatment process. Unit - IV ents to understand about various errors of phase changes – Driving remations – martensitic transform owledge on phase transformations Unit - V ous engineering alloys and their carbon steels – mild steels – high s	with: prope diagrams at treatme ordening	rty changes, a - heat-treatm nt - hardenab - induction, ansformations G aspects, diffinetics of tra uctural steels as.	mannealing twins nent processes ility – Jominy' flame, laser K2 S Tusion in solids nsformation - K4
HEAT TRE textures in co annealing, no end quench carburizing, cyaniding, nit Outcome Objective PHASE TRA — solidification precipitation Outcome Objective ENGINEER — stainless ste Outcome Suggested I	ATMENT – Recovery and worked and anneal remalizing, quenching test – martempering test – martempering siding, carbo nitriding. A To make the study. A To make the study. ANSFORMATIONS – on – pearlitic transformed age hardening. A Students gain known to include the study. A To introduce variation of the study. A Students gain known to include the study. A Nalyze the various carbon carbo	y, recrystallisation and grain growled alloys,-TTT diagrams – CCT and tempering – baths used in he g and austempering – case has evarious heat treatment process. Unit - IV ents to understand about various ermations – martensitic transform whedge on phase changes – Driving remations – martensitic transform towledge on phase transformations. Unit - V ous engineering alloys and their carbon steels – mild steels – high sent alloys – shape memory alloys – us properties of engineering allo	wth: prope diagrams at treatme urdening es sphase trassforces, N- ations - k application trength strapplication ys and application ys and application diagrams.	rty changes, a – heat-treatm nt – hardenab – induction, nsformations G aspects, diffinetics of tra uctural steels as. oly them	mannealing twins nent processes ility – Jominy' flame, laser K2 S Tusion in solids nsformation - K4 – tool materials
HEAT TRE. textures in coannealing, no end quench carburizing, cyaniding, nit Outcome : Objective PHASE TRA — solidification precipitation Outcome : Objective ENGINEER — stainless ste Outcome : Suggested H Avner S.H.	ATMENT – Recovery led worked and anneal remalizing, quenching test – martempering siding, carbo nitriding. Students apply the To make the students apply the NSFORMATIONS – on – pearlitic transform and age hardening. Students gain known in the students gain known	y, recrystallisation and grain grow led alloys,-TTT diagrams – CCT and tempering – baths used in he g and austempering – case has evarious heat treatment process. Unit - IV ents to understand about various ermations – martensitic transform wheelege on phase changes – Driving ermations – martensitic transform to Unit - V ous engineering alloys and their carbon steels – mild steels – high sent alloys – shape memory alloys – us properties of engineering allo	wth: prope diagrams at treatme ordening es sphase traces, N- ations - k application trength strapplication ys and application and application sphase traces.	rty changes, a - heat-treatm nt - hardenab - induction, ansformations G aspects, dif inetics of tra uctural steels is. oly them ion.	mannealing twins nent processes ility – Jominy' flame, laser K2 S Tusion in solids nsformation - K4 – tool materials
HEAT TRE textures in co annealing, no end quench carburizing, cyaniding, nit Outcome Objective PHASE TRA — solidification recipitation Outcome Objective ENGINEER — stainless ste Outcome Suggested I Avner S.H. Guy A.G. an	ATMENT – Recovery and worked and anneal remalizing, quenching test – martempering test – martempering siding, carbo nitriding. A To make the study. A To make the study. ANSFORMATIONS – on – pearlitic transformed age hardening. A Students gain known and age hardening. A To introduce various super alloys – light and the super alloys – light a	y, recrystallisation and grain growled alloys,-TTT diagrams – CCT and tempering – baths used in he g and austempering – case has evarious heat treatment process. Unit - IV ents to understand about various examples of phase changes – Driving mations – martensitic transform towledge on phase transformations. Unit - V ous engineering alloys and their carbon steels – mild steels – high sent alloys – shape memory alloys – us properties of engineering allows of Physical Metallurgy. Mc Graw Henents of Physical Metallurgy. Oxformations of Physical Metallurgy.	wth: prope diagrams at treatme ardening es sphase trag forces, N- ations - k application trength strapplication ys and application ord Univ.	rty changes, a - heat-treatm nt - hardenab - induction, ansformations G aspects, diffinetics of tra uctural steels as. bly them Press.	mannealing twins nent processes ility – Jominy' flame, laser K2 S Tusion in solids nsformation - K4 – tool materials
HEAT TRE. textures in coannealing, no end quench carburizing, cyaniding, nit Outcome Objective PHASE TRA Solidification precipitation Outcome Suggested F Avner S.H. Guy A.G. an Lakhtin Y. (ATMENT – Recovery ld worked and anneal rmalizing, quenching test – martempering diding, carbo nitriding. Students apply the students apply the students apply the students gain known age hardening. To introduce variation of the students gain known age hardening. To introduce variation of the students gain known age hardening. Analyze the various deadings:- (2019). Introduction to the students gain end thrend. (1984). Elem 2005). Engineering Physical students gain end gradients.	y, recrystallisation and grain growled alloys,-TTT diagrams – CCT and tempering – baths used in he g and austempering – case has a least treatment process. Unit - IV ents to understand about various. Types of phase changes – Driving mations – martensitic transform owledge on phase transformations. Unit - V ous engineering alloys and their carbon steels – mild steels – high sent alloys – shape memory alloys – us properties of engineering alloy. O Physical Metallurgy. Mc Graw I ments of Physical Metallurgy. Oxf ysical Metallurgy. CBS Publishers	wth: prope diagrams at treatme ordening ses sphase tra forces, Nations - kations	rty changes, a - heat-treatm nt - hardenab - induction, ansformations G aspects, diffinetics of tra uctural steels as. bly them Press.	mannealing twins nent processes ility – Jominy' flame, laser K2 S Tusion in solids nsformation - K4 – tool materials
HEAT TRE. textures in coannealing, no end quench carburizing, cyaniding, nit Outcome a Objective PHASE TRA — solidification precipitation Outcome a Objective ENGINEER — stainless ste Outcome a Suggested I Avner S.H. Guy A.G. an Lakhtin Y. (Polmear I. S	ATMENT – Recovery led worked and anneal rmalizing, quenching test – martempering siding, carbo nitriding. Students apply the students gain known age hardening. To introduce variation of the students gain known age hardening. To introduce variation students apply the students gain known age hardening. To introduce variation students and students alloys – light students gain known age adings:- (2019). Introduction to the students (1984). Elem (2005). Engineering Phys. (1995). Light Alloys	y, recrystallisation and grain growled alloys,-TTT diagrams – CCT and tempering – baths used in he g and austempering – case has evarious heat treatment process. Unit - IV ents to understand about various examples of phase changes – Driving mations – martensitic transform towledge on phase transformations. Unit - V ous engineering alloys and their carbon steels – mild steels – high sent alloys – shape memory alloys – us properties of engineering allows of Physical Metallurgy. Mc Graw Henents of Physical Metallurgy. Oxformations of Physical Metallurgy.	with: prope diagrams at treatme ordening	rty changes, a - heat-treatm nt - hardenab - induction, ansformations G aspects, diffinetics of tra ins. uctural steels as. bly them iron. Press. utors.	mannealing twinsment processes sility – Jominy's flame, laser K2 Sility – K2 K4 - tool materials

Phase transformation of precipitated TiO2 nanoparticles, Y Hu, H.-L Tsai, C.-L Huang, Materials Science and Engineering: A, Volume 344, Issues 1–2, 2003, Pages 209-214, https://doi.org/10.1016/S0921-5093(02)00408-2.

Semi-solid processing of engineering alloys by a twin-screw rheo-moulding process, S Ji, Z Fan, M.J Bevis, Materials Science and Engineering: A, Volume 299, Issues 1–2, 2001, Pages 210-217, https://doi.org/10.1016/S0921-5093(00)01373-3.

Synergistic effect of cavitation erosion and corrosion of various engineering alloys in 3.5% NaCl solution, C.T Kwok, F.T Cheng, H.C Man, Materials Science and Engineering: A, Volume 290, Issues 1–2, 2000, Pages 145-154, https://doi.org/10.1016/S0921-5093(00)00899-6.

K1-Remember	K2-Understand	K3-Apply	K4-Analyse	K5-Evaluate	K6-Create
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Course Outcome

CO 1	Construct phase diagrams.	K1, K2
CO 2	Gain knowledge on Iron-Carbon phase equilibrium diagram.	K2, K3
CO3	Apply the various heat treatment processes.	K5
CO 4	Gain knowledge on phase transformations	K3, K4
CO 5	Analyze the various properties of engineering alloys and apply them	K1, K6

Course outcome Vs Programme outcomes

PO/CO	PO 1	PO 2	PO 3	PO 4	PO 5	PO 6	PO 7	PO 8	PO 9	PO 10
CO 1	S (3)	M (2)	S (3)	M (2)	M (2)	S (3)	L(1)	M (2)	L(1)	M (2)
CO 2	S (3)	M (2)	M (2)	S (3)	S (3)	S (3)				
CO 3	M (2)	M (2)	S (3)	S (3)	S (3)	M (2)	M (2)	L(1)	L(1)	S (3)
CO 4	S (3)	S (3)	S (3)	S (3)	M (2)	M (2)	L(1)	M (2)	M (2)	M (2)
CO 5	M (2)	S (3)	S (3)	S (3)	S (3)	L(1)	L(1)	S (3)	S (3)	S (3)
W. AV	2.6	2.6	3	2.8	2.6	2	1.4	2.2	2	2.6

Course Outcome Vs Programme Specific Outcome

PSO/CO	PSO 1	PSO 2	PSO 3	PSO 4	PSO 5
CO 1	S (3)	M (2)	M (2)	S (3)	S (3)
CO 2	S (3)	S (3)	M (2)	M (2)	S (3)
CO 3	M (2)	M (2)	S (3)	M (2)	S (3)
CO 4	L(1)	M (2)	M (2)	S (3)	S (3)
CO 5	M (2)	M (2)	M (2)	S (3)	S (3)
W. AV	2.2	2.2	2.2	2.6	3

S-Strong (3), M-Medium (2), L-Low (1)



			II SEMESTER				
DSE	Cou	rse code:542510	Materials Processing	T	Credits: 3	H	Hours: 3
			Unit - I				
Objec			ne basic concepts of manufacturing	, <u>.</u>			
			PROCESSES -Fundamental analy				_
_	-		ods of forging, extrusion, rolling,	spinning,	turning, plannin	g and	1 shaping,
milling,	grindi	<u> </u>					
Outco	me 1		n the knowledge about the basics o	f various	manufacturing	K2	
		processes involve	d in manufacturing materials.				
			Unit - II				
Objec			owledge about surface treatment p				
			OCESSES - Necessity for surface		· ·		C .
		•	ening, conventional methods, carbu	_			•
			nventional methods, typical laser	variables	used in surface	alloy	'ing, laser
		rimental set up.					
Outco	me 2	The students lear	n the various surface treatment p	rocesses.		K4	
			Unit - III				
			arious welding processes.	٥			
			rious processes of welding, fusion	100	_	_	-
_	-	U 1	ot welding, thermit welding, hern	100	C- 1 5		•
_		•	ffects of welding, effects on grain				
			gy beam welding, la <mark>ser</mark> beam a <mark>nd</mark> ele				fect.
Outco	me 3	Learners make u	se of th <mark>e</mark> proc <mark>ess</mark> es <mark>involv</mark> ed in <mark>di</mark> ff	erent wel	ding techniques.		K4
			Unit - IV				
Objec	tive 4		<mark>lents abo</mark> ut me <mark>chanical w</mark> orkin <mark>g</mark> of				
			OF METALS - Hot working, co				

MECHANICAL WORKING OF METALS - Hot working, cold working, normalising, full annealing tempering, theory of tempering, effect of tempering temperature on mechanical properties of carbon steels, different tempering process, deformation of metals, elastic deformation, plastic deformation, slip, twinning – assessment of processed materials.

Outcome 4	Learners gain a better knowledge with mechanical working of metals.	K2
	TT *4 T7	

Unit - V

Objective 5 To make the students understand the knowledge about powder metallurgical processes.

POWDER METALLURGICAL PROCESS -Production of powders, powder mixing, compacting, types of presses, sintering, soaking, finishing process, limitations and advantages of powder metallurgy, applications production of cemented carbide cutting tools, self-lubricating bearings, magnets, cermet's, ultrasonic ceramic transducers.

Outcome 5 Learners understand the powder metallurgical process.

K5

Suggested Readings:-

Gupta R.B. (1995). Materials Science and Processes. Satya Prakashan, New Delhi.

Muralidhara M.K. (1998). Materials Science and Processes. Dhanpat Rai Publishing Co., New Delhi.

Rajan T.V, Sharma C.Pand Sharma A.(2010). Heat Treatment: Principles and Techniques. Prentice Hall India Learning Private Limited.

Rykalin, Uglov A, Kokona, (1987). A Laser and Electron beam material processing hand book, MIR Publishers.

M. B. Uday, M. N. Ahmad Fauzi, H. Zuhailawati & A. B. Ismail, Advances in friction welding process: a review, Pages 534-558 | Published online: 04 Dec 2013,

https://doi.org/10.1179/136217110X12785889550064.

Montasser Marasy Dewidar, Ho-Chel Yoon & Jae Kyoo Lim, Mechanical properties of metals for biomedical applications using powder metallurgy process: A review, Metals and Materials

K1-Remember	K2-Understand	K3-Apply	K4-Analyse	K5-Evaluate	K6-Create
		0 (1		

Course Outcome

CO 1	Gain knowledge about the basics of various manufacturing processes involved in manufacturing materials.	K1, K2
CO 2	Learn the various surface treatment processes	K2, K3
СОЗ	Understand the processes involved in different welding techniques.	K5
CO 4	Gain a better knowledge with mechanical working of metals.	K3, K4
CO 5	Understand the powder metallurgical process.	K1, K6

Course outcome Vs Programme outcomes

PO/CO	PO 1	PO 2	PO 3	PO 4	PO 5	PO 6	PO 7	PO 8	PO 9	PO 10
CO 1	S (3)	M (2)	S (3)	M (2)	M (2)	S (3)	L (1)	M (2)	L (1)	M (2)
CO 2	S (3)	M (2)	M (2)	S (3)	S (3)	S (3)				
CO3	M (2)	M (2)	S (3)	S (3)	S (3)	M (2)	M (2)	L (1)	L (1)	S (3)
CO 4	S (3)	S (3)	S (3)	S (3)	M (2)	M (2)	L (1)	M (2)	M (2)	M (2)
CO 5	M (2)	S (3)	S (3)	S (3)	S (3)	L (1)	L(1)	S (3)	S (3)	S (3)
W. AV	2.6	2.6	3	2.8	2.6	2	1.4	2.2	2	2.6

S – Strong (3), M-Medium (2), L-Low (1)

Course Outcome Vs Programme Specific Outcome

PSO/CO	PSO 1	PSO 2	PSO 3	PSO 4	PSO 5
CO 1	S (3)	M (2)	M (2)	S (3)	S (3)
CO 2	S (3)	S (3)	M (2)	M (2)	S (3)
CO 3	M (2)	M (2)	S (3)	M (2)	S (3)
CO 4	L(1)	M (2)	M (2)	S (3)	S (3)
CO 5	M (2)	M (2)	M (2)	S (3)	S (3)
W. AV	2.2	2.2	2.2	2.6	3

	II SEMESTER	
DSE Cours	e code:542511 Corrosion Science and Engineering T	Hours: 3
	Unit - I	
Objective 1	To introduce the students to corrosion process and corrosion control.	
	PROCESSES -Basic principles of electrochemistry and aqueous corros	ion processes
	Thermodynamics and Electrode Potential - Electrochemical Kinetics of Cor	-
	avior - Faraday's Law - Nernst equation; standard potentials Pourbaix	
	sion rate - Evans diagram - pitting, crevice and exfoliation corrosion; influence	•
=	tions; corrosion control; high temperature oxidation and hot corrosion; corros	=
property interact		
Outcome 1	The students learn various corrosion process and control.	K2
	Unit - II	
Objective 2	To make the students understand the methods used for testing corrosion.	
CORROSION	TESTING - Materials and specimens – surface preparation – measuring and we	eighing – linear
polarization – A	C impedance – in vivo corrosion – paint tests – seawater tests.	
Outcome 2	The students understand the methods for testing corrosion.	K4
	Unit - III	
Objective 3	To introduce the different methods used for coating.	
	NUFACTURE – Electrodeposition; flame and plasma spraying; thermal, H	V of detonation
gun, physical va	pour deposition; chemical vapour deposition; HIP surface treatments.	
Outcome 3	Students analyze and apply the different methods for coating.	K4
	Unit - IV	
Objective 4	To impart knowledge on various types of corrosion with respect to corro	sion.
CORROSION	IN SELECTED ENVIRONMENTS - Atmospheric Corrosion, Corrosion	
Corrosion in So	ils, Corrosion of Steel in <mark>C</mark> oncrete, Corrosion in Water, Microbiologically Ind	uced Corrosion
	Body, Corrosion in the Petroleum Industry, Corrosion in the Aircraft Industr	
the Microelectro	nies Industry.	
0 1	The students gain knowledge on corrosion type with respect to	170
Outcome 4	environment.	K2
	Unit - V	
Objective 5	To expose the students to various application of coating.	
COATING AF	PPLICATIONS -Abrasive, erosive and sliding wear. The interaction between	een wear and
corrosion. Coat	ing systems for corrosion and wear protection; new coating concepts includ	ing multi-layer
structures, functi	onally gradient materials, intermetallic barrier coatings and thermal barrier coa	tings.
0.4	The students learn about the various concepts and applications of	175
Outcome 5	coating.	K5
Suggested Rea	ndings:-	
Bockris J.O.N	M, Conway B.E, Yeager Eand White. (2013). Electrochemical Material	s Science in
Comprehensiv	re Treatise of Electrochemistry, Volume 4. Plenum press.	
Denny A.Jones	s. (2013). Principles and Prevention of Corrosion. Pearson.	
FontanaM.G.	(2017). Corrosion Engineering, McGraw Hill Education.	
Hutchings Ian	nd Philip Shipwar. (2019). Tribology: Friction and Wear of Engineeric	ng Materials.
D-44	•	

Butterworth-Heinemann.

Sukanchan Palit, Recent Advances in Corrosion Science: A Critical Overview and a Deep Comprehension, Direct Synthesis of Metal Complexes, 2018, Pages 379-41, https://doi.org/10.1016/B978-0-12-811061-4.00011-6.

D. Féron, 2 - Overview of nuclear materials and nuclear corrosion science and engineering, Nuclear Corrosion Science and Engineering Woodhead Publishing Series in Energy, 2012, Pages 31-56, https://doi.org/10.1533/9780857095343.1.31.

Vincent Maurice, Philippe Marcus, Progress in corrosion science at atomic and nanometric scales.

112 Tellionide 112 Charles 110 Tellionide 110 Charles	K1-Remember	K2-Understand	K3-Apply	K4-Analyse	K5-Evaluate	K6-Create
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Course Outcome

CO 1	Learn various corrosion process and corrosion control.	K1, K2
CO 2	Understand the methods used for testing corrosion.	K2, K3
CO3	Analyze and apply the different methods for coating.	К5
CO 4	Gain knowledge on corrosion type with respect to environment.	K3, K4
CO 5	Learn about the various concepts and applications of coating.	K1, K6

Course outcome Vs Programme outcomes

PO/CO	PO 1	PO 2	PO 3	PO 4	PO 5	PO 6	PO 7	PO 8	PO 9	PO 10
CO 1	S (3)	M (2)	S (3)	M (2)	M (2)	S (3)	L(1)	M (2)	L(1)	M (2)
CO 2	S (3)	M (2)	M (2)	S (3)	S (3)	S (3)				
CO 3	M (2)	M (2)	S (3)	S (3)	S (3)	M (2)	M (2)	L(1)	L(1)	S (3)
CO 4	S (3)	S (3)	S (3)	S (3)	M (2)	M (2)	L (1)	M (2)	M (2)	M (2)
CO 5	M (2)	S (3)	S (3)	S (3)	S (3)	L(1)	L (1)	S (3)	S (3)	S (3)
W. AV	2.6	2.6	3	2.8	2.6	2	1.4	2.2	2	2.6

S – Strong (3), M-Medium (2), L-Low (1) Course

Outcome Vs Programme Specific Outcome

PSO/CO	PSO 1	PSO 2	PSO 3	PSO 4	PSO 5
CO 1	S (3)	M (2)	M (2)	S (3)	S (3)
CO 2	S (3)	S (3)	M (2)	M (2)	S (3)
CO 3	M (2)	M (2)	S (3)	M (2)	S (3)
CO 4	L(1)	M (2)	M (2)	S (3)	S (3)
CO 5	M (2)	M (2)	M (2)	S (3)	S (3)
W. AV	2.2	2.2	2.2	2.6	3

1			II SEMESTER			
DSE	Cour		lid State Ionics	T	Credits: 3	Hours: 3
			Unit - I	'	-	
Obje	ective 1	To introduce the basic aspect	ts of solid-state physics	•		
BASIC	ASPE	CTS OF SOLID STATE 1	PHYSICS -Types of	bonding	in solids-Fu	ndamentals of
		-Simple Crystal structures-BC	•	diffractio	n-band struct	ures of metals
semicor	nductors	and insulators-Ionic and electr	onic conductivities.			
Outo	come 1	The students learn the basic a	aspects of solid-state pl	nysics.		K2
			Unit - II			
_		To impart knowledge on soli		_		
		IONICS - Concept of solid st	•	-		
		Superionic solids- crystalline				
		tural factors responsible for high	-	-		-
		oretical models of fast ion trans			lids-Nano-ion	
Out	come 2	Gain knowledge on solid stat		age.		K4
			Unit - III			
•	ective 3	To introduce the students to				
		ERIES AND APPLICATION			-	-
		poration technique - electromo				
_		energy density of a cell-polyn	A MARKET AND A SERVICE AND ARROWS ASSOCIATION ASSOCIATION AND ADMINISTRATION ASSOCIATION A	tion of po	olymer electro	olytes in micro
		lls-solid state battery-super cap				
Out	come 3	Learn about microbatteries		citors.		K4
			Unit - IV			
Obje	ective 4	To familiarize various chara materials.	cterization techniques 1	for new ca	athode	
CHAR	ACTER	IZATION OF NEW CATHO	<mark>)de materials</mark> - i	Phase ider	tification- Th	nermal analysis
DTA-D	SC-TG-			(EDV)	7 77	
		Energy dispersive X-ray flu	o <mark>rescence sp</mark> ectr <mark>os</mark> copy	(EDX)-2	X-ray - X-ra	y photoelectro
		Energy disp <mark>ersiv</mark> e X-ray flu PS) - Structural characteriza <mark>tic</mark>				_
spectros	scopy (X	The second secon				_
spectros FTIR-Ti	scopy (X ransport	PS) - Structural characterization	on – XRD studies -Exte	nded X-ra	y absorption	fine structure -
spectros FTIR-Ti	scopy (X	PS) - Structural characterization measurements.	on – XRD studies -Exte	nded X-ra	y absorption	_
spectros FTIR-Ti	scopy (X ransport	PS) - Structural characterization measurements. Learn about the various characterization is a second control of the characterization is a second control	on – XRD studies -Exte	nded X-ra	y absorption	fine structure -
spectros FTIR-Ti Outo	scopy (X ransport come 4	PS) - Structural characterization measurements. Learn about the various characterization is a second control of the characterization is a second control	on – XRD studies -Exteriation technique Unit - V	nded X-ra	y absorption	fine structure -
spectros FTIR-Ti Outo	ransport come 4 ective 5	PS) - Structural characterization measurements. Learn about the various characterials.	racterization technique Unit - V various application of	nded X-ra s availabl ionic mat	y absorption e for erials.	fine structure -
Spectros FTIR-T1 Outo Obje	ransport come 4 ective 5 CATIO	PS) - Structural characterization measurements. Learn about the various characteride materials. To expose the students to the	racterization technique Unit - V various application of -Primary lithium batteri	nded X-ra s availabl ionic mat es- thermo	y absorption e for erials. odynamics and	K2 d mass transpor
Spectros FTIR-T1 Outo Obje APPLI in solid	come 4 ective 5 CATIO state bat	PS) - Structural characterization measurements. Learn about the various characterials. To expose the students to the NS OF IONIC MATERIALS	racterization technique Unit - V various application of -Primary lithium batteri electrode kinetics-Seco	s availablionic mates thermondary lith	y absorption e for erials. odynamics and ium batteries-	K2 d mass transpor Li-ion electrod
Spectros FTIR-Ti Outo Obje APPLI in solid material	come 4 ective 5 CATIO state bat	PS) - Structural characterization measurements. Learn about the various characteride materials. To expose the students to the NS OF IONIC MATERIALS deries, battery performance and	racterization technique Unit - V various application of -Primary lithium batteri electrode kinetics-Seco	s availablionic mates thermondary lith	y absorption e for erials. odynamics and ium batteries-	K2 d mass transpor Li-ion electrod
Objection of the control of the cont	come 4 ective 5 CATIO state bat	PS) - Structural characterization measurements. Learn about the various characteride materials. To expose the students to the NS OF IONIC MATERIALS teries, battery performance and ation and fabrication characteristics.	racterization technique Unit - V various application of -Primary lithium batteri electrode kinetics-Seco terization of Li-ion cell of Lithium batteries.	ionic mates thermondary lithis secondary	y absorption e for erials. odynamics and tum batteries- rison of Li- id	K2 d mass transpor Li-ion electrod
Obje APPLIC in solid material cells in Outc	ective 5 CATIO state bat ls-prepar CMOS-l come 5	PS) - Structural characterization measurements. Learn about the various characterials. To expose the students to the NS OF IONIC MATERIALS deries, battery performance and ation and fabricationcharacteristic AM applications. Applications The students familiar with valdings:-	racterization technique Unit - V various application of -Primary lithium batteri electrode kinetics-Seco terization of Li-ion cell of Lithium batteries.	ionic mate	e for erials. odynamics and ium batteries- rison of Li- icrials	K2 d mass transpor Li-ion electrod odine andNiCd
Objection Solid material Cells in Suggest Chande	ective 5 CATIO state bat ls-prepar CMOS-l come 5	PS) - Structural characterization measurements. Learn about the various characteridate cathode materials. To expose the students to the NS OF IONIC MATERIALS deries, battery performance and ation and fabrication - characteristic AM applications. Applications The students familiar with values. The students familiar with values. 81). Superionic Solids-Principles.	racterization technique Unit - V various application of -Primary lithium batteri electrode kinetics-Seco terization of Li-ion cell of Lithium batteries. arious applications of ion es and applications. Nor	ionic mater compact the Holland	y absorption e for erials. odynamics and tum batteries- rison of Li- id- rials	K2 d mass transpor Li-ion electrod odine andNiCd
Obje APPLIC in solid material cells in Outc Sugge Chand Clive	come 4 ective 5 CATIO state battls-prepar CMOS-I come 5 ested Rea lra S. (19 D.S. Tuo	PS) - Structural characterization measurements. Learn about the various characteride materials. To expose the students to the NS OF IONIC MATERIALS deries, battery performance and ation and fabrication - characteristic AM applications. Applications The students familiar with valuings:- 81). Superionic Solids-Principle k, (1991). Modern Battery Technical Materials and Control of the students familiar with valuings:-	unit - V various application of -Primary lithium batteri electrode kinetics-Seco terization of Li-ion cell of Lithium batteries. urious applications of ion es and applications. Nor chnology, Elis Horwood	ionic mater compact the Holland	y absorption e for erials. odynamics and tum batteries- rison of Li- id- rials	K2 d mass transpor Li-ion electrod odine andNiCd
Objections Objections Objections Objections Objections Outcomp	ective 5 CATIO state bat ls-prepar CMOS-l come 5 sted Rea dra S. (19 D.S. Tuc oton T.R	PS) - Structural characterization measurements. Learn about the various characteridate cathode materials. To expose the students to the NS OF IONIC MATERIALS deries, battery performance and ation and fabrication - characteristic AM applications. Applications The students familiar with various: 81). Superionic Solids-Principles, (1991). Modern Battery Tec (2000). Battery Reference Boo	unit - V various application of -Primary lithium battericelectrode kinetics-Seconterization of Li-ion cell of Lithium batteries. urious applications of ices and applications. Nor chnology, Elis Horwoodk, Newnes.	ionic mater the Holland Publisher	e for erials. odynamics and ium batteries- rison of Li- id- rials I Amsterdam.	K2 d mass transpor Li-ion electrododine andNiCd K5
Objection Suggest Chand Clive Cromp Geoffi	ective 5 CATIO state bat ls-prepair CMOS-l come 5 sted Rea lra S. (19 D.S. Tuc pton T.R	PS) - Structural characterization measurements. Learn about the various characteride materials. To expose the students to the NS OF IONIC MATERIALS deries, battery performance and ation and fabrication - characteristic AM applications. Applications The students familiar with valuings:- 81). Superionic Solids-Principle k, (1991). Modern Battery Technical Materials and Control of the students familiar with valuings:-	unit - V various application of -Primary lithium battericelectrode kinetics-Seconterization of Li-ion cell of Lithium batteries. urious applications of ices and applications. Nor chnology, Elis Horwoodk, Newnes.	ionic mater the Holland Publisher	e for erials. odynamics and ium batteries- rison of Li- id- rials I Amsterdam.	K2 d mass transpor Li-ion electrododine andNiCd K5

Fan Wu a b c d e, Lilu Liu a, Shuo Wang d, Jieru Xu d, Pushun Lu d, Wenlin Yan d, Jian Peng d, Dengxu Wu d, Hong Li, Solid state ionics – Selected topics and new directions, Progress in Materials Science, Volume 126, May 2022, 100921, https://doi.org/10.1016/j.pmatsci.2022.100921.

J. Schoonman, Nanostructured materials in solid state ionics, Solid State Ionics

Volume 135, Issues 1-4, 1 November 2000, Pages 5-19, https://doi.org/10.1016/S0167-2738(00)00324-6.

C. Julien, Technological applications of solid state ionics, Materials Science and Engineering: B, Volume 6, Issue 1, May 1990, Pages 9-28, https://doi.org/10.1016/0921-5107(90)90109-0.

	K1-Remember	K2-Understand	K3-Apply	K4-Analyse	K5-Evaluate	K6-Create
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Course Outcome

CO 1	Learn the basic aspects of solid-state physics.	K1, K2
CO 2	Gain knowledge on solid state ionics, hydrogen storage.	K2, K3
CO 3	Learn about microbatteries, fuel cells, super capacitors.	K5
CO 4	Learn about the various characterization techniques available for cathode materials.	K3, K4
CO 5	Familiar with various applications of ionic materials	K1, K6

Course outcome Vs Programme outcomes

ALAGAPPA UNIVERSITY

PO/CO	PO 1	PO 2	PO 3	PO 4	PO 5	PO 6	PO 7	PO 8	PO 9	PO 10
CO 1	S (3)	M (2)	S (3)	M (2)	M (2)	S (3)	L(1)	M (2)	L(1)	M (2)
CO 2	S (3)	M (2)	M (2)	S (3)	S (3)	S (3)				
CO 3	M (2)	M (2)	S (3)	S (3)	S (3)	M (2)	M (2)	L(1)	L(1)	S (3)
CO 4	S (3)	S (3)	S (3)	S (3)	M (2)	M (2)	L(1)	M (2)	M (2)	M (2)
CO 5	M (2)	S (3)	S (3)	S (3)	S (3)	L(1)	L(1)	S (3)	S (3)	S (3)
W. AV	2.6	2.6	3	2.8	2.6	2	1.4	2.2	2	2.6

S – Strong (3), M-Medium (2), L-Low (1) Course

Outcome Vs Programme Specific Outcome

PSO/CO	PSO 1	PSO 2	PSO 3	PSO 4	PSO 5
CO 1	S (3)	M (2)	M (2)	S (3)	S (3)
CO 2	S (3)	S (3)	M (2)	M (2)	S (3)
CO 3	M (2)	M (2)	S (3)	M (2)	S (3)
CO 4	L(1)	M (2)	M (2)	S (3)	S (3)
CO 5	M (2)	M (2)	M (2)	S (3)	S (3)
W. AV	2.2	2.2	2.2	2.6	3

	III-SEMESTER					
Core 11 Co	ourse code:542301 Nanomaterials T C	redits: 4 Hours: 4				
	Unit -I					
Objective 1	To introduce the basic aspects of preparation of nanomaterials	and their related				
Objective 1	characterization techniques.					
	RTIES OF NANOPARTICLES - Size effect and properties of nat					
- particle shape -	melting point, surface tension, wettability - specific surface area ar	nd pore size – Reason fo				
change in optical properties, electrical properties, and mechanical properties – advantages.						
Outcome 1	Familiarize the properties of nanoparticles and its advantages	K1, K2				
	Unit II					
Objective 2	To study the synthesis and purification Single walled and Mult	i walled Nanotubes				
Objective 2	(SWNT and MWNT).					
	- Single walled and Multi walled Nanotubes (SWNT and MW					
F .	nthesis of carbon nanotubes by pyrolysis techniques - arc-disc	-				
nanotube properti	es – Nanowires – methods of preparation of nanowires –VLS mech	nanism.				
Outcome 2	The students apply ideas on enlightenment of Nanowires.	K2, K6				
	Unit III					
Objective 3	To impart the concepts behind 1 dimensional nanowires and i	nanofibers.				
NANOWIRES A	AND NANOFIBERS – Semiconductor and oxide nanowires –prepared	paration –solvothermal –				
electrochemical -	-PVD -Pulse laser deposition - template method (qualitative)- nan	ofibers –electro spinning				
technique.	ALAGAPPA UNIVERSITY					
Outcome 3	Gain the idea of ID nanostructures.	K4, K6				
	Unit IV					
Objective 4	To acquire knowledg <mark>e</mark> on t <mark>he growth o</mark> f cry <mark>st</mark> als by solution gro	owth.				
	ZATION - FESEM - near-field Scanning Optical Micros					
Transmission Ele	ectron Microscopy (H <mark>R</mark> TEM)- Absor <mark>ptio</mark> n an <mark>d</mark> emission spectra	1 – PL spectrum - singl				
_	acterizatio <mark>n –S</mark> canning capac <mark>itance micr</mark> osco <mark>p</mark> y – capil <mark>lary</mark> electr	ophoresis- laser induced				
fluorescence (CE	-LIF).					
Outcome 4	The students able to understand its application.	K4, K5				
	Unit V					
Objective 5	To inspire the knowledge of nanodevices for magnetic storage.					
NANODEVICE	S - Magnetic storage: - magnetic quantum well; magnetic dots - r	nagnetic date storage -				
high density quar	tized magnetic disks - magnetic super lattices – MRAMS - MTJs u	sing nanoscale tunneling				
junctions - Millip	ede for storage – nano-material sensors.					
	The students understand the principle involved in preparatio	n and				
Outcome 5	characterization of nanostructures and fabrication of	K2, K3				
	nanodevice.					
Suggested Readi	ngs					
EbbesenT.W. (E	Editor). (1997). Carbon nanotubes: preparation and properties. CRC	Press, USA.				
· ·	Editor). (1996). Nanomaterials Synthesis, properties and application	_				
_	wa (Editor). (2000). Handbook of Nanostructured Materials and T	echnology, Vol.1-5.				
Academic Press						
Hari Singh Nalv	va (Editor). (2002). Nanostructured materials and nanotechnology.	Academic Press, USA.				

Zhon Ling Wang. (2000). Characterization of nanophase materials. Wiley-VCH Verlag GmbH.

Nanowerk (https://www.nanowerk.com/) - covers a wide range of nanotechnology topics, including the fundamentals of nanomaterials, research developments, and industry news.

Nanotechnology Now (<u>http://www.nanotech-now.com/</u>) - features articles, blogs, and news related to nanotechnology, including the basics of nanomaterials and their applications.

ACS Nano Blog (https://axial.acs.org/category/acs-nano/) - affiliated with the American Chemical Society, offers insights into nanotechnology research, including the fundamental aspects of nanomaterials.

K1-Remember	K1-Remember K2-Understand		K4-Analyse	K5-Evaluate	K6-Create	
Course designed by: Dr						

Course Outcome

CO 1	Understand basic properties of nanomaterials	K1, K2
CO 2	Identify properties and synthesis mechanisms of various nanotubes	K2, K6
CO3	Examine properties and preparation methods for nanowires and nanofibers.	K4, K6
CO 4	Understand characterization techniques like FESEM, HRTEM, PL & UV spectra, electrophoresis, and microscopy	K4, K5
CO 5	Analyze nanodevices such as MRAMs, magnetic disks, magnetic data storage, and nanomaterial sensors.	K2, K3

Course outcome Vs Programme outcomes

PO/CO	PO 1	PO 2	PO 3	PO 4	PO 5	PO 6	PO 7	PO 8	PO 9	PO 10
CO 1	S (3)									
CO 2	S (3)									
CO3	S (3)	S (3)	S (3)	M (2)	S (3)	M (2)	M (2)	S (3)	S (3)	S (3)
CO 4	M (2)	S (3)	L(1)	S (3)	S (3)	S (3)	M (2)	L(1)	S (3)	L(1)
CO 5	S (3)	S (3)	S (3)	M (2)	L(1)	S (3)				
W. AV	2.8	3	2.6	2.6	2.6	2.8	2.6	2.6	3	2.6

S – Strong (3), M-Medium (2), L-Low (1) Course

Outcome Vs Programme Specific Outcome

PSO/ CO	PSO 1	PSO 2	PSO 3	PSO 4	PSO 5
CO 1	S (3)	M (2)	M (2)	L(1)	L(1)
CO 2	S (3)				
CO 3	S (3)	S (3)	M (2)	S (3)	S (3)
CO 4	L(1)	L(1)	L(1)	S (3)	L (1)
CO 5	M (2)	M (2)	M (2)	S (3)	S (3)
W. AV	2.4	2.2	2	2.4	2.2

			III-SEME	STER				
Core 12	Course code: 542302	Polyn	ner and Comp	oosite Materials	T	Credits: 4	Hours: 4	
			Unit	- I		1		
Objective 1 To introduce polymers, their synthesis and polymerization techniques.								
Introducti	on to polymers -	 Classificati 	on of polyme	rs – copolymers –	tacticity	-geometric i	somerism –	
	-	_		ment of molecular v	_	•	polymers –	
step growtl				tion – polymerisati		=		
Outcome	Outcome 1 Understand the basic properties of polymers, their synthesis and various polymerization techniques.						K2	
			Unit	- II				
Objective	2 To impart kn	owledge on t	the various pr	operties of polyme	rs.			
state – glas temperatur – dynamic	ss transition tempo e – techniques to	erature – the determine cr	crystalline sta ystallinity – N	hain dimensions – te – ordering of po lechanical propertion of viscoelastic beha	lymer c es – Intr	hains – crysta oduction to v	lline melting iscoelasticity	
Outcome Outcome	2 Students learnand mechanic			transition tempera	iture, ci	ystallinity	K4	
			Unit -	m 623				
				processing techniq				
Polymer	Processing, Rhe	eology and a	pplications -	Basic processing	operation	ons – extrusi	on, molding	
calendaring	g, coating – Introd	duction to po	lymer rheolog	y – non-Newtonian	flow –	analysis of si	mple flows -	
rheometry -	- capillary rheome	eter, Couette	rheometer and	plate rheometer - a	pplicati	ons-conductin	g polymers-	
	s-liquid crystal po		L. D. E. F.					
Outcome	C4da4- aal	lyze the diffe		processing method	ds, and	various	K4	
		2	Unit -	- IV				
_				o <mark>osi</mark> tes a <mark>nd</mark> their m				
	-			ite materials – the c	-			
		100x #06x		ss, carbon and meta		ers - fiber pac	king	
arrangeme	nts - bonding mec	chanisms – m	ech <mark>an</mark> ical beha	vi <mark>or</mark> of composites.				
Outcome			anical behavi	cation of composites.	tes, mat	rix and	K2	
			Unit					
				n of different types				
consolidati	on of resin pre-	-pregs, cons	olidation of 1	ites – liquid resin resin moulding co	mpound	s, injection	moulding of	
_	=	_	=	metal composites	_		_	
· .	•	composites –	powder-base	d routes, layered ce	ramic c	omposites, ca	rbon/carbon	
composites								
Outcome	apply them in		te the fabrica	tion techniques of	compos	ites and	K5	
Gowarikar D. & Clyne R. Fried. (2	A.J. (2014). <i>Plastic</i> V.R, Viswanatha E.T.W. (2008). <i>An</i> 2014). <i>Polymer Sc</i> K. (2008). <i>Fiber-I</i>	an N.V. &Sre on Introduction cience and Te	edhar J. (2019) to Composite chnology. Pear	lia.). <i>Polymer Science</i> . <i>Materials</i> . Cambric rson Prentice Hall. <i>aterials</i> , Manufactu	lge Univ	versity Press.Jo	oel	

Online resources:-

Polymer-Based Composites: An Indispensable Material for Present and Future Applications: Volume 2020 | Article ID 8834518 | https://doi.org/10.1155/2020/8834518

Polymeric composites for powder-based additive manufacturing: Materials and applications, 91, 2019, 141-168, 10.1016/j.progpolymsci.2018.11.001.

K1-Remember	K2-Understand	K3-Apply	K4-Analyse	K5-Evaluate	K6-Create
				Course designed	l by: Dr. J. Wilson

Course Outcome

CO 1	Gain basic knowledge on various polymers being used in both day today and scientific applications	K1
CO 2	Explore the fundamental properties of polymers to expand the knowledge of polymeric material	K2/K6
CO 3	Apply the basic knowledge to synthesizing the polymer by varies techniques	К3
CO 4	Understand and apply the gained skill to develop a polymeric composite for suitable application	K2/K6
CO 5	Develop novel material polymeric composite to enhance the functional properties for specified applications	K6

Course outcome Vs Programme outcomes

PO/CO	PO 1	PO 2	PO 3	PO 4	PO 5	PO 6	PO 7	PO 8	PO 9	PO 10
CO 1	S (3)	S (3)	S (3)	M (2)	M (2)	M (2)	S (3)	L (1)	S (3)	M (2)
CO 2	S (3)	S (3)	L (1)	S (3)	M (2)	L(1)				
CO3	S (3)	M (2)	M (2)	S (3)	M (2)	M (2)	M (2)	S (3)	S (3)	L (1)
CO 4	S (3)	S (3)	S (3)	M (2)	S (3)	S (3)	L(1)	M (2)	L (1)	M (2)
CO 5	M (2)	M (2)	S (3)	M (2)	S (3)	M (2)	S (3)	S (3)	M (2)	S (3)
W. AV	2.8	2.6	2.6	2.4	2.6	2.4	2.6	2.4	2.2	1.8

S – Strong (3), M-Medium (2), L-Low (1)

Course Outcome Vs Programme Specific Outcome

PSO/CO	PSO 1	PSO 2	PSO 3	PSO 4	PSO 5
CO 1	S (3)	M (2)	S (3)	S (3)	S (3)
CO 2	S (3)	S (3)	M (2)	M (2)	M (2)
CO 3	S (3)	S (3)	S (3)	M (2)	L(1)
CO 4	M (2)	L(1)	S (3)	L(1)	M (2)
CO 5	M (2)	S (3)	M (2)	M (2)	M (2)
W. AV	2.6	2.4	2.6	2.0	2.0

	III-SEMESTER	
Core 13 C	ourse code :542303 Solid state Physics T Credits: 4	Hours: 4
	Unit - I	
·	To recall the basic nature of Bonding's of crystals	
CRYSTAL S'	TRUCTURE AND BONDING - Crystalline solids - crystal systems - Br	avais lattices –
coordination n	umber - packing factors - cubic, hexagonal, diamond structure, Sodium Chlo	ride Structure –
lattice planes	and Miller Indices- interplanar spacing - directions. Types of bonding - leading - lea	attice energy -
Madelung cons	stants – Born Haber cycle – cohesive energy.	
Outcome 1	Students understand the basic information of bonding of solids and its applications.	K1, K2, K3
	Unit - II	
	To understand the conductivity of Solid materials	
	TRON THEORY - Drude theory – Wiedemann-Franz Law and Lorentz num	
_	neracy-density of states, concentration - free electron statistics (Fermi-Dirac	
and electronic	Specific heat, Electrical resistivity and conductivity of metals – Boltzmann tran	nsport theory –
-electrical and	thermal conductivity of electrons.	
Outcome 2	Learners understand the properties and applications of conducting materials.	K2, K3
	Unit - III	
Objective 3	To analyze the lattice and thermal resistance of crystalline materials	
LATTICE DY	NAMICS - Mono atomic and diatomic lattices - an harmonicity and ther	mal expansion-
phonon –Mon	nentum of phonons, Inelastic scattering of photons by long wavelength I	phonons, Local
phonon model	- Einstein and Debye model, density of states, Thermal conductivity of	solids- due to
electron-due to	phonons – thermal resistance of solids – phonon-phonon interaction-normal	l and Umklapp
processes - sca	ttering experiments.	
Outcome 3	Students analyze the use of lattice dynamics.	K3, K4
	Unit - IV	•
Objective 4	To analyze the importance of periodic potentials of bands	
PERIODIC I	POTENTIALS AND ENERGY BANDS - Bloch's theorem - Kronig-	Penney model-
Construction of	of Brillouin Zones- Effective mass of electron-nearly free electron model -	- Tight binding
approximation-	Construction of Fermi Surfaces-density of states curve-electron, holes and ope	en orbits-Fermi
surface studies	- Cyclotron resonance – anomalous skin effect –de Hass van Alphen effect.	
0 1 1	Students get expertise on Periodic potentials and tight binding	170 174
Outcome 4	approximation methods	K2, K4
	Unit - V	
Objective 5	To evaluate types of semi and superconductors	
-	SEMICONDUCTORS AND SUPERCONDUCTIVITY - Semiconductor	ors – direct and
	carrier statistics (intrinsic and extrinsic) – law of mass action– electrical cond	
	ariation - III - V and II - VI compound semiconductors. Superconduct	-
	nomalous characteristics – isotope effect, Meissner effect – type I and II su	
•	(elementary) - Josephson junctions and tunnelling – SQUID - High	•
	s - applications.	1
Outcome 5	Students understand the significance of semi and superconducting materials.	K3, K5
Ashcroft N.V		to the Theory.

Springer.

Rogalski M.S. and Palmer S.B. (2000). Solid State Physics. Gordon Breach Science Publishers. Wahab M.A. (2019). Solid State Physics: Structure and Properties of Materials. Narosa Publishing House Pvt. Ltd.

Online resources:-

Solid State Physics - https://www.e booksdirectory.com/details.php?ebook=10489

Lecture Notes for Solid State Physics - https://www.e-booksdirectory.com/details.php?ebook=9717

K1-Remember	K2-Understand	K3-Apply	K4-Analyse	K5-Evaluate	K6-Create		
		Course designed by: Dr. S. Saravana kuma					

Course Outcome

CO 1	Understand the basics of crystal structure and bonding of materials	K1, K2, K3
CO 2	Learn theoretical aspects of moving electrons in solid.	K2, K3
CO3	Utilize thermal energy transition in material lattice dynamics.	K3, K4
CO 4	Become familiar with the energy diagrams for various conducting materials.	K2, K4
CO 5	Examine the underline concept and choose advanced conducting materials for practical application.	K3, K5

Course outcome Vs Programme outcomes

PO/CO	PO1	PO2	PO3	PO4	PO5	PO6	PO7	PO8	PO9	PO10
CO 1	S (3)	S (3)	S (3)	M (2)	S (3)	M (2)				
CO 2	S (3)	S (3)	S (3)	S (3)	M (2)	S (3)	S (3)	M (2)	S (3)	M (2)
CO 3	S (3)	M (2)	S (3)	M (2)	M (2)	M (2)				
CO 4	S (3)	M (2)	S (3)	S (3)	M (2)					
CO 5	S (3)									
W. AV.	3	2.6	2.8	2.6	2.4	2.6	2.8	2.4	2.6	2.2

S – Strong (3), M-Medium (2), L-Low (1)

Course Outcome Vs Programme Specific Outcome

PSO/CO	PSO 1	PSO 2	PSO 3	PSO 4	PSO 5
CO 1	S (3)	S (3)	S (3)	M (2)	M (2)
CO 2	S (3)	S (3)	M (2)	M (2)	M (2)
CO 3	S (3)	M (2)	M (2)	M (2)	M (2)
CO 4	S (3)	M (2)	M (2)	M (2)	M (2)
CO 5	S (3)	S (3)	S (3)	S (3)	M (2)
W. AV.	3	2.6	2.4	2.2	2.0

			III-SEMESTER						
Core 14	Cour	rse code: 542304	Ceramic Materials	T	Credits: 4	Hours: 4			
	10000		Unit I						
Object	Objective 1 To introduce the concepts of ceramic materials processing.								
CERAMI	C PRO		processing – precipitation,			ring, sol-gel, CVD -			
			oressing, slip casting, inject						
			re sintering, hot pressing, I	HIP, reac	tion bonded si	ntering, microwave			
		e finishing techniques				T			
Outco	me 1	Understand the co	ncept of ceramic processin	ıg.		K1, K5/K6			
		<u> </u>	Unit II						
Object		_	ents, the concept of struct						
			e ceramics – zirconia, alun						
			le, tungsten carbide, titaniu		e – nitrides – si	licon nitride, boron			
nitride, tita	anium		des, - sialon – bio ceramics			T			
Outco	me 2	Appreciate the impotechniques.	ortance of ceramics and its	process	ing	K3/K6			
			Unit III						
Object	ive 3	To understand the	concept of electrical prop	erties of	ceramic mate	erials.			
ELECTR	ONIC	CERAMICS— Cerar	nic insulators and capacitor	s – ferro	electric cerami	cs – barium titanate			
			d applications of electron						
ferrites, zi	nc ferr	ites – applications - g	arnets - superconducting co	eramics -	- varistors – ox	ides and non-oxide			
varistorsan		1000	ALAGAPPA UNIVERSITY	3					
Outco	me 3	Reveal the electron	nic properties of ceramic r	naterials	•	K1/K3/K5			
011			Unit IV						
Object			rocesses of refectories of c			'1' 1 '			
REFRAC	TOKY	CERAMICS - Refi	a <mark>ct</mark> ories – types of refracto a <mark>se</mark> d and nitride-ba <mark>sed</mark> refra	ries - spe	Eusian aget ret	es - silica, alumina,			
		erature applications.	ised and militide-based refra	ctories –	r usion cast lei	ractories – ceranne			
Outco			ocesses of refectories of co	eramic <mark>m</mark>	aterials and	K1/K5/K6			
		applications.	Unit V	13					
Object	ive 5	To understand the	preparation and propert	ies of gla	ss ceramics				
GLASS C	ERAN	MICS - Glass forming	g processes – Glass transiti	on – Glas	ss transformati	on range - Heat			
			in glass, nucleation agent						
fiber glass	es, opti	cal glasses and non-o	xide glasses.						
Outco	me 5	Gain knowledge or reliance.	n the importance of glass o	eramics	in practical	K2/K5/K6			
Suggeste	d Rea	dings:-				•			
Chester J Lewis M Reed J.S.	J.H. (19 J.H. (20 J. (2008 on D.W	992). Refractories, Pro 911). Glasses and Gla). Principles of Ceran 7. Lee W.E. (2018). M	gh Performance Glasses. Oduction and Properties. Iross Ceramics. Springer. nic Processing. Wiley-Intersodern Ceramic Engineering	n and Ste	eel Institute, Lo	ndon.			

Online Resources:-

Automotive and industrial applications of structural ceramics in Japan, Akira Okada, Journal of the European Ceramic Society, Volume 28, Issue 5, 2008, Pages 1097-1104, https://doi.org/10.1016/j.jeurceramsoc.2007.09.016.

Development of refractory ceramics from residual silica derived from rice husk ash, F.Z. Sobrosa, N.P. Stochero, E. Marangon, M.D. Tier, Ceramics International, Volume 43, Issue 9, 2017, Pages 7142-7146, https://doi.org/10.1016/j.ceramint.2017.02.147.

Characterization of different starch types for their application in ceramic processing, Eva Gregorová, Willi Pabst, Ivan Bohačenko, Journal of the European Ceramic Society, Volume 26, Issue 8, 2006, Pages 1301-1309, https://doi.org/10.1016/j.jeurceramsoc.2005.02.015.

K1-Remember	K2-Understand	K3-Apply	K4-Analyse	K5-Evaluate	K6-Create		
		Course designed by: Dr. J. Wilson					

Course Outcome

CO 1	Understand the concept of ceramic materials processing.	K1, K2
CO 2	Appreciate the importance of ceramics and its processing techniques.	K2, K3
CO3	Reveal the electronic properties of ceramic materials.	K5
CO 4	Understand the processes of refectories of ceramic materials and applications.	K3, K4
CO 5	Gain knowledge on the importance of glass ceramics in practical reliance.	K1, K6

Course outcome Vs Programme Outcomes

				The state of the s		The Real Property lies				
PO/CO	PO 1	PO 2	PO 3	PO 4	PO 5	PO 6	PO 7	PO 8	PO 9	PO 10
CO 1	S (3)	M (2)	S (3)	M (2)	M (2)	S (3)	L (1)	M (2)	L (1)	M (2)
CO 2	S (3)	S (3)	S (3)	S (3)	S (3)	M (2)	M (2)	S (3)	S (3)	S (3)
CO3	M (2)	M (2)	S (3)	S (3)	S (3)	M (2)	M (2)	L(1)	L (1)	S (3)
CO 4	S (3)	S (3)	S (3)	S (3)	M (2)	M (2)	L(1)	M (2)	M (2)	M (2)
CO 5	M (2)	S (3)	S (3)	S (3)	S (3)	L(1)	L (1)	S (3)	S (3)	S (3)
W. AV	2.6	2.6	3	2.8	2.6	2	1.4	2.2	2	2.6

S-Strong (3), M-Medium (2), L-Low (1)

Course Outcome Vs Programme Specific Outcome

PSO/ CO	PSO 1	PSO 2	PSO 3	PSO 4	PSO 5
CO 1	S (3)	M (2)	M (2)	S (3)	S (3)
CO 2	S (3)	S (3)	M (2)	M (2)	S (3)
CO 3	M (2)	M (2)	S (3)	M (2)	S (3)
CO 4	L(1)	M (2)	M (2)	S (3)	S (3)
CO 5	M (2)	M (2)	M (2)	S (3)	S (3)
W. AV	2.2	2.2	2.2	2.6	3

		III-SEMESTER							
Core 15	Course Code: 542305	Lab III: Device Characterization	P	Credits: 4	Hours: 8				
Objectives	The objective of the course is to equip the students with adequate experimental skill which includes design and testing of electronic components, devices and sensors. Students shall also perform thermal and mechanical properties of select materials								
Experiments	2. Zener diode 3. Common E 4. Common B 5. FET and SC 6. Clipper and 7. Verification 8. Verification 10. Verification 11. Determinat 12. Transient a 13. Resistive se 14. Stress and s 15. Thermal pr 16. Impact test 17. Corrosion s	train study (tensile strength, compression perties of materials and surface roughness study tudies	hhoff's ocity the parallel on & be	eorem RLC circuits nding moment)					
Outcome	testing of electro	ne course work, students gain adequate onic components, devices and sensors. ochanics and thermal properties of selec	In addi	tion, they also b					

		III SEMESTER			
DSE C	ourse code:542513	Biosensors	T	Credits: 3	Hours: 3
		Unit - I			
•		c characteristics, types of biosensing			
		osensor – definition-Historical p	-		
•	namic Range, signal	to noise, sensitivity, selectivity, int	erference	e- examples - a	applications –
Problems.					
Outcome 1	Become knowledgeab	le in the field of biosensors.			K1/K2
		Unit - II			
Objective 2	To understand diffe surface.	rent methods for attaching recogn	ition mo	lecule on the s	sensor
TYPES OF T	RANSDUCERS- Tra	nsducer – definition-types – optica	ıl, electro	chemical, Elec	trochemical
,	•	ometric,conductimetric), thermal, M	ass – pie	zoelectric – ac	oustic wave
with examples					
Outcome 2	Ability to select diffe applications.	rent types of sensors based on type	of requi	rement and	K3/K6
		Unit - III			
Objective 3	To identify differen	t recognition molecules for differen	nt biosen	sing application	ons
BIORECOG	NITION SYSTEMS	5– Enzymes; Microorganism ba	sed bios	sensor, immo	bilization of
microorganism	- botanical biosensors	s-Biosensors using cultured cells-inta	ct tissues	s-receptor elem	ents.
Outcome 3	Ability to select the analytes.	biorecognition system to detect pa	ırticular	type of	K1/ K5/K6
		Unit - IV			
Objective 4	To understand the v	vork <mark>in</mark> g pri <mark>nciples of el</mark> ectro <mark>ni</mark> c and	d optical	sensor device	s.
DNA ELECT	RONIC APPLICAT	IONS - Mo <mark>lec</mark> ular wire <mark>s an</mark> d s <mark>w</mark> itche	s Biomol	lecular comput	er, molecular
arrays as mem	ory stores, DNA for n	nolec <mark>u</mark> lar de <mark>vic</mark> es - m <mark>ole</mark> cule <mark>sb</mark> etwe	en nanofa	abricated electr	odes.
	A STATE OF THE PARTY OF THE PAR	ılar co <mark>nductivity to</mark> wards <mark>co</mark> nstruc		_	
Outcome 4	wires, rectifiers swi	tches by <mark>sem</mark> iconduct <mark>or in</mark> terfacing	g with bio	omolecules	K2, K4, K6
	towards bioelectron	TOTAL CONTRACT OF THE PARTY OF	7		
		Unit - V			
		iosensors, glucose biosensor, differ			
		n- Historical developments – genera		glucose sensir	ng -types of
	toring – invasive and	non-invasive – sensor market-India	an status.		
Outcome 5		ry and recent development of gluco	se senso	rs.	K2/K4/K6
Suggested R	eadings:-				
Cooper J. Ca	ss T. (2004). Biosenso	rs. 3- Biotechnology Advances.			
Cooper J.M.	Cooper J. Cass A.E.G.	(2004). Biosensors. Oxford Univers	sity Press	s.	
Malhotra B.l	D. Turner A.P.F. (200	3). Advances in Biosensors. Elsevie	r JAI.		
Mulchandani	A. Rogers K.R. (1998	3). Enzyme and Microbial Biosensors	Techniq	ues and Protoc	ols.
	ss, Totowa, New Jersey	•	•		
	· · · · · · · · · · · · · · · · · · ·				

Online resources:-

Basics of Biosensors and Nanobiosensors - Nanobiosensors - Wiley Online Library

Biosensors: Design, Development and Applications | IntechOpen

Biosensors: components, mechanisms, and applications - ScienceDirect

K1-Remember	K2-Understand	K3-Apply	K4-Analyse	K5-Evaluate	K6-Create
			Cour	se designed by: Dr. V	. Dharuman

Course Outcome

CO 1	Understand basic characteristics, types of biosensing devices	K1/K2
CO 2	Understand different methods for attaching recognition molecule on the sensor surface.	K3/K6
CO 3	Identify different recognition molecules for different biosensing applications	K1/ K5/K6
CO 4	Understand the working principles of electronic and optical sensor devices.	K2, K4, K6
CO 5	Learn the origin of biosensors, glucose biosensor, different generations and recent trends	K2/K4/K6

Course outcome Vs Programme outcomes

PO/CO	PO 1	PO 2	PO 3	PO 4	PO 5	PO 6	PO 7	PO 8	PO 9	PO 10
CO 1	S (3)	M (2)	S (3)	M (2)	M (2)	S (3)	M (2)	M (2)	M (2)	L (1)
CO 2	S (3)	M (2)	S (3)	M (2)	M (2)	S (3)	M (2)	M (2)	L(1)	M (2)
CO3	S (3)	M (2)	M (2)	M (2)	S (3)	M (2)	S (3)	S (3)	M (2)	M (2)
CO 4	S (3)	M (2)	S (3)	M (2)	S (3)	L(1)	S (3)	M (2)	S (3)	M (2)
CO 5	M (2)	S (3)	M (2)							
W. AV	2.8	2.1	2.6	2.0	2.4	2.2	2.2	2.2	2.0	1.8

S – Strong (3), M-Medium (2), L-Low (1)

Course Outcome Vs Programme Specific Outcome

PSO/CO	PSO 1	PSO 2	PSO 3	PSO 4	PSO 5
CO 1	S (3)	S (3)	M (2)	M (2)	M (2)
CO 2	S (3)	M (2)	M (2)	M (2)	S (3)
CO3	M (2)	M (2)	S (3)	M (2)	S (3)
CO 4	M (2)	M (2)	M (2)	S (3)	M (2)
CO 5	M (2)	M (2)	M (2)	S (3)	S (3)
W. AV	2.4	2.2	2.2	2.4	2.6

			III SEMESTER			
DSE	Cour	se code:542514	Bioelectronics	T	Credits: 3	Hours: 3
			Unit - I	•		
Objec	ctive 1	To impart know	vledge on bioelectronic devices a	nd their appl	ications in va	rious fields.
META	AL OXI	DE SEMICOND	UCTOR (MOS) STRUCTURE	- pn Junction	n, pn Junctio	n Equilibrium,
Effect	of the B	ias Voltage, Curre	ent – Voltage Characteristics of pr	junction - M	OS Structure -	Accumulation
Operat	ting Mo	de- Depletion Ope	erating Mode- Inversion Operatin	g Mode, C-V	Plots of an M	OS Structure.
Outc		Familiarize with semiconductors a	basic semiconducting propert nd its structure.	ies of metal	oxide	K1/K4/K6
			Unit - II			
Objec	ctive 2		basics of biosensor devices, meta of biosensor devices.	l oxide semic	onductors in	biosensor
META	AL OXI	DE SEMICOND	UCTOR BASED BIOELECTRO	NIC DEVIC	ES -	
Biosens	or overv	view- Transducers	- characteristics - Ion sensitive	field effect tra	nsistor – enz	yme field effect
transisto	or- Cell	based biosensors	and sensor of cell metabolism -	- light addres	sable potenti	ometric sensors
(LAPS).						
Outc	ome 2		tal oxides, ion selective electrode I biosensing applications	s field effect	transducers	K1/K2/K6
			Unit - III	h	l	
Objec	ctive 3	To learn on mo	lecules as electronic components	for developi	ng molecular	electronic
MOLE	CULAR	R ELECTRONIC	CS – Molecular wires and swite	hes; molecul	ar arrays as 1	memory stores
biomole	cular co	mputer, Properties	of DNA and its potential applicat	ions in molec	ular electronic	S.
		Understand mol	lecular <mark>co</mark> nduc <mark>tiv</mark> ity towards c <mark>on</mark> s	structing cond	ducting	
Outc	ome 3	wires, rectifiers	s switc <mark>he</mark> s by <mark>se</mark> mic <mark>o</mark> nd <mark>ucto</mark> r in <mark>t</mark>	erfacing with	ı	K2, K4, K6
		biomolecules to	wards <mark>bi</mark> oele <mark>ctronics device</mark> s.			
			Unit - IV			
Objec	ctive 4	To learn on the	microelectrode types, polarizab	le and non-po	olarizable elec	ctrodes and
		their application	ns in biome <mark>dic</mark> al field.	LI.		
MICR	OELE	CTRODES FOR	R BIOLOGICAL MONITORI	NG – Elect	rochemical c	ells, oxidation
reducti	ion reac	tions – Polarizatio	on, polarizable and non-polarizable	e electrodes,	electrode beh	avior of circuit
metho	ds. Body	y surface recordin	g electrode array, Microelectrode	s for electric	stimulation of	tissues.
Outc	ome 4	Selection of mic	ro electrodes for applications in	medical field	I	K3/K4/K6
			Unit - V			
Objec	ctive 5	To understand	the conduction in neurons, their	electrical pr	operties and	circuit
		models				
BIOEL	ECTRI	CITY AND BI	OELECTRIC PHENOMENO	N -Biology	of the Neuro	on, Biophysical
_			tial, The Neuron as the thresho			
_	_		unctions, Silicon Neurons Neuro	ons - Equival	ent Circuit N	Model for Cell
Membra	ne - Ho	<u> </u>	nd Equivalent Circuits.			
Outc	ome 5		uronal network and mechanism stem and to develop equivalent c	_	nsmission	K2/K4/K6
L		·				

Suggested Readings:-

Andreas Offenhausser and Ross Rinaldi. (2009). Nanobioelectronics-for electronics, biology and medicine.

Chad A. Mirkin and Christ of Niemeyer M. (2007). *Nanobiotechnology II More Concepts and Applications*.

Christ of Niemeyer M and Chad A. Mirkin. (2004). *Nanobiotechnology Concepts, Applications and Perspectives*.

David S. Good sell. (2004). Bionanotechnology.

Jason J Davis. (2009). Engineering the bioelectronic interface.

Online resources:-

<u>PPT – Metal-Oxide-Semiconductor (MOS) PowerPoint presentation | free to view - id: 3e1ae5-MTIzY (powershow.com)</u>

Advances in Molecular Electronics: A Brief Review - ScienceDirect

Introduction To Bioelectric Phenomena [d4pqq1zv79np] (idoc.pub)

K1-Remember	K2-Understand	K3-Apply	K4-Analyse	K5-Evaluate	K6-Create			
		Course designed by: Dr. V. Dharum						

Course Outcome

CO 1	Familiarize with basic semiconducting properties of metal oxide semiconductors and its structure.	K1/K4/K6
CO 2	Selection of metal oxides, ion selective electrodes field effect transducers for the required biosensing applications	K1/K2/K6
CO3	Understand molecular conductivity towards constructing conducting wires, rectifiers switches by semiconductor interfacing with biomolecules towards bioelectronics devices.	K2, K4, K6
CO 4	Selection of micro electrodes for applications in medical field	K3/K4/K6
CO 5	Learn about neuronal network and mechanism of signal transmission in biological system and to develop equivalent circuits	K2/K4/K6

Course outcome Vs Programme outcomes

PO/CO	PO1	PO2	PO3	PO4	PO5	PO6	PO7	PO8	PO9	PO10
CO 1	S (3)	M (2)	S (3)	M (2)	M (2)	S (3)	M (2)	L(1)	M (2)	M (2)
CO 2	S (3)	M (2)	M (2)	S (3)	M (2)	M (2)	M (2)	M (2)	S (3)	M (2)
CO3	M (2)	S (3)	M (2)	L (1)	M (2)	S (3)	M (2)	S (3)	M (2)	L(1)
CO 4	M (2)	M (2)	M (2)	M (2)	S (3)	S (3)	S (3)	M (2)	M (2)	M (2)
CO 5	S (3)	M (2)	L (1)	M (2)	M (2)	S (3)	M (2)	M (2)	M (2)	L(1)
W. AV.	2.6	2.2	2.0	2.0	2.2	2.8	2.1	2.0	2.2	1.6

Course Outcome Vs Programme Specific Outcome

PSO/CO	PSO 1	PSO 2	PSO 3	PSO 4	PSO 5
CO 1	S (3)	M (2)	S (3)	M (2)	M (2)
CO 2	S (3)	M (2)	M (2)	S (3)	M (2)
CO 3	M (2)				
CO 4	S (3)	S (3)	S (3)	M (2)	L(1)
CO 5	M (2)	M (2)	M (2)	S (3)	M (2)
W. AV.	2.6	2.2	2.4	2.0	1.8

S – Strong (3), M-Medium (2), L-Low (1)



			III SEMESTER			
DSE	Cou	rse code:542515	Chemical Sensors	T	Credits: 3	Hours: 3
	•		Unit I	•		
Obje	ective 1	To introduce the con	cept of sensors with its pri	nciple and d	lefinition.	
			VITIONS AND CONCEPT			
_	_	•	o-chemical and biological to		* *	-
		_	ary; Main technical defini		ration, selectivity	, sensitivity,
			nse time; Problems and trade			T
Outo	come 1	Understand the cond	cept of sensors with its prin	ciple and de	efinition.	K1/ K5
		m · · ·	Unit II	•	7.47	
Obje	ective 2	for fabrication.	s physico-chemical methods	s in sensor a	and the sensor ma	iterials used
DHACI	COCE		S AND TRANSDUCERS -	Thermal se	nsors: Electroche	mical cancar
			ductimetric); Semiconducto		•	
l ·		=	e, bio/chemiluminescence,			
		nitations & problems t		2111), 110	30 310 3110 4114 410	
			erials used in sensors and d	lifferent typ	es of physico-	
Outo	come 2		ecent years.		r J	K3/K4
		I.	Unit III	Sept.		
Obje	ective 3	To gain knowledge a	bout materials used for bio	sensors.		
BIOCE	HEMIC	AL SENSORS – a.	Enzymes; Oligonucleotide	s and Nucl	eic Acids; Lipids	s (Langmuir
Blodge	tt bilaye	ers, Phospholipids, L	iposomes); Membrane rece	ptors and t	ransporters; Imm	unoreceptors
Limitat	ions &	problems. b. Catalytic	biose <mark>nso</mark> rs: mono-enzyme	electrodes;	bi-enzyme electro	odes: enzym
l	-	-	empetition electrodes. c. At			-
_		-	ochi <mark>ps</mark> and biosensor arrays;			
0.4		Understand fundame	enta <mark>ls</mark> of bio- electronic dev	rices and hor	w to select the	1/2/1/5
Outo	come 3	materials for biosens	sors.	7		K3/K5
		-0	Unit IV	/ A		
Obje	ective 4	To know about fabri	cation o <mark>f s</mark> ensors usi <mark>ng m</mark> o	dern techno	logy.	
CENC	OD EN	NCINEEDING Ma	thods for sensors fabrication	on, golf agg	umblad manalaya	*G G0*00*
l			entact printing, MEMS. Eng		•	
printin	ng, phot	onthography, interocc	mact printing, willing. Ling	incering con	cepts for mass pro	Jauction.
Outo	come 4	Understand the devi	ce fabrication strategies use	ed in sensor	preparation.	K1/K5
			Unit V			
Obje	ective 5	To impart knowledg	e on advanced sensor mate	rials used ir	practical applica	ation
l			monitoring; Technological	-	-	•
			glucose monitoring; Implan	table sensor	rs for long-term	monitoring;
		e benefits; Problems				
		L	ous sensor materials used f	or health ca	re monitoring.	K2/K5
		adings:-	44) 77 11 4 071			
_			11). Handbook of Biosenso	ors and Bios	ensor Kinetics, E	lsevier B.V.
			N: 978-0-444-53262-6)		una Az-II t	omtotie. T
			hubert, (1992). "Biosenson	_		
	rticai Cn -98783-		Elsevier Science Publishers l	b. v . Amster	uam, The Netherl	anus, (ISBN
		,	ical Sensors. Springer.			
Janata	ı J. (200)	7). Finiciples of Chem	icai sensois, springer.			

Online Resources:-

Infrared optical sensors for water quality monitorin, B. Mizaikoff, Water Sci Technol (2003) 47 (2): 35–42. https://doi.org/10.2166/wst.2003.0079

Biochemical sensors based on polymer microrings with sharp asymmetrical resonance, Chung-Yen Chao; L. Jay Guo, Appl. Phys. Lett. 83, 1527–1529 (2003), https://doi.org/10.1063/1.1605261.

Course Outcome

CO 1	Understand the concept of sensors with its principle and definition.	K1/K3
CO 2	Understand the materials used in sensors and different types of physico-chemical sensors in recent years.	K3/ K4
CO 3	Understand fundamentals of bio- electronic devices and how to select the materials for biosensors	K3/K5
CO 4	Understand the device fabrication strategies used in sensor preparation	K1/ K5
CO 5	Understand the various sensor materials used for health care monitoring.	K2/ K5

Course outcome Vs Programme outcomes

PO/CO	PO 1	PO 2	PO 3	PO 4	PO 5	PO 6	PO 7	PO 8	PO 9	PO 10
CO 1	S (3)	M (2)	S (3)	M (2)	M (2)	S (3)	L(1)	M (2)	L(1)	M (2)
CO 2	S (3)	M (2)	M (2)	S (3)	S (3)	S (3)				
CO 3	M (2)	M (2)	S (3)	S (3)	S (3)	M (2)	M (2)	L (1)	L(1)	S (3)
CO 4	S (3)	S (3)	S (3)	S (3)	M (2)	M (2)	L (1)	M (2)	M (2)	M (2)
CO 5	M (2)	S (3)	S (3)	S (3)	S (3)	L (1)	L (1)	S (3)	S (3)	S (3)
W. AV	2.6	2.6	3	2.8	2.6	2	1.4	2.2	2	2.6

S – Strong (3), M-Medium (2), L-Low (1) Course

Outcome Vs Programme Specific Outcome

PSO/CO	PSO 1	PSO 2	PSO 3	PSO 4	PSO 5
CO 1	S (3)	M (2)	M (2)	S (3)	3
CO 2	S (3)	S (3)	M (2)	M (2)	S (3)
CO 3	M (2)	M (2)	S (3)	M (2)	S (3)
CO 4	L(1)	M (2)	M (2)	S (3)	S (3)
CO 5	M (2)	M (2)	M (2)	S (3)	S (3)
W. AV	2.2	2.2	2.2	2.6	3

		III SEMESTER			
DSE Cours	e code:542516	Thin Film Science and Technology	Т	Credits:	3 Hours
		Unit I			
Objective	To understar	nd the film growth technology and stru	ictural de	fects in fori	ned film.
GROWTH A	ND STRUCTU	RE OF FILMS -Introduction to thin file	ns and app	olications - C	General featu
- Nucleation th	eories - Post-nuc	cleation growth - Thin film structures- S	tructural d	efects.	
Outcome 1	Understand	the general features and film growth t	echniques	used.	K1, K5/K
		Unit II			
Objective 2	To introduce analysis	e various measurement and monitoring	g techniqu	ies used for	thin films
THICKNESS	MEASUREM	IENT AND MONITORING - Multiple	beam int	erference - o	quartz crystal
ellipsometric -	stylus techniqu	es. Characterization: X-ray diffraction -	electron	microscopy	- high and le
energy electroi	diffraction.				
Outcome 2	Study the va	rious measurement and monitoring te	chniques.		K3/K6
		Unit III		<u>'</u>	
Objective 3	3 To gain kn	owledge about preparation techniques	used for	film formati	ion.
		S – Physical methods: thermal evapora			
		ering mechanism and methods - Pulsed l			
		l methods: chemical vapour deposition	n and ch	emical solu	tion depositi
techniques - sp	ray pyrolysis - la	aser ablation.	3		
Outcome 3	Understand	d fundament <mark>als</mark> of preparation method	S		K1/K3/K
	<u> </u>	Unit IV			
Objective 4	To know al	bout prope <mark>rt</mark> ies o <mark>f thin film.</mark>	life and the second		
PROPERTIE	S OF THIN FI	LMS - O <mark>pti</mark> cal - refle <mark>cti</mark> on and ant <mark>i-</mark> ref	lection co	atings - inte	rference filte
thin film solar	cells - electrop	photograph <mark>y.</mark> El <mark>ectric</mark> al and <mark>diel</mark> ectr <mark>ic</mark> be	ehaviour o	of thin films	- componen
thin film diod	e and transistor	- strain gauges and gas sensors. Aniso	tropy in r	nagnetic fili	ns - domain
films - comput	er memories - sı	<mark>up</mark> erconduct <mark>ing thin</mark> films - SQ <mark>UID</mark> - me	chanical p	roperties: te	sting method
adhesion - surf	ace and tribolog	ical coatings.			
_	Understand		s obtaine	d from	
Outcome 4	thin film.	d the properties and analysis the result			K1/K5/K0
Outcome 4	L I	d the properties and analysis the result Unit V			K1/K5/K0
Outcome 4 Objective	thin film.	10 someone as a			
Objective :	thin film. To impart	Unit V	in samp	le preparati	on.
Objective :	thin film. To impart	Unit V knowledge on high vacuum production	in samp	le preparati	on.
Objective :	thin film. To impart UUM PRODUC ction of ultra-hig	Unit V knowledge on high vacuum production CTION- Mechanical pumps - Diffusion gh vacuum - thin film vacuum coating un nderstand the necessity of high vacuum	in samp n pump - nit	le preparation measureme	on.
Objective : HIGH VACU gauges - produ	thin film. To impart UUM PRODUC ction of ultra-his Students un sample pre	Unit V knowledge on high vacuum production CTION- Mechanical pumps - Diffusion gh vacuum - thin film vacuum coating un nderstand the necessity of high vacuum	in samp n pump - nit	le preparation measureme	on. nt of vacuur
Objective : HIGH VACU gauges - produ Outcome : Suggested R	thin film. To impart JUM PRODUC ction of ultra-his Students un sample pre- eadings:-	Unit V knowledge on high vacuum production CTION- Mechanical pumps - Diffusion gh vacuum - thin film vacuum coating un nderstand the necessity of high vacuum	n in samp n pump - nit n product	le preparation measurement ion in	on. nt of vacuur
Objective : HIGH VACU gauges - produ Outcome : Suggested R Berry R.W, Ha	thin film. To impart JUM PRODUC ction of ultra-hig Students un sample pre eadings:- ill P.MandHarris	Unit V knowledge on high vacuum production CTION- Mechanical pumps - Diffusion gh vacuum - thin film vacuum coating un nderstand the necessity of high vacuum paration.	n in samp n pump - nit n product	le preparation measurement ion in	on. nt of vacuur
Objective : HIGH VACU gauges - produ Outcome : Suggested R Berry R.W, Ha ChopraK.L. (1	thin film. To impart UUM PRODUC ction of ultra-his Students un sample pre eadings:- ill P.MandHarris 979). Thin Film	Unit V knowledge on high vacuum production CTION- Mechanical pumps - Diffusion gh vacuum - thin film vacuum coating un nderstand the necessity of high vacuum paration. s M.T. (1968). Thin Film Technology. Vo	n in sample n pump - nit n product	le preparation measurement ion in measurement.	on. nt of vacuur K2/K5/K
Objective : HIGH VACU gauges - produ Outcome : Suggested R Berry R.W, Ha ChopraK.L. (1	thin film. To impart JUM PRODUC ction of ultra-hig sample pre eadings:- all P.MandHarris 979). Thin Film adKaur I. (2011).	Unit V knowledge on high vacuum production CTION- Mechanical pumps - Diffusion gh vacuum - thin film vacuum coating un nderstand the necessity of high vacuum paration. s M.T. (1968). Thin Film Technology. Va Phenomena. Krieger Pub Co.	n in sample n pump - nit n product on Nostrar	le preparation measurement ion in measurement.	on. nt of vacuur K2/K5/K

Online Resources:-

Synthesis of ZrO2 thin films by atomic layer deposition: growth kinetics, structural and electrical properties, Michel Cassir, Fabrice Goubin, Cécile Bernay, Philippe Vernoux, Daniel Lincot, Applied Surface Science, Volume 193, Issues 1–4, 2002, Pages 120-128, https://doi.org/10.1016/S0169-4332(02)00247-7.

Mechanical properties of thin films, William D. Nix, Metallurgical Transactions A volume 20, pages2217–2245 (1989), https://doi.org/10.1007/BF02666659

K1-Remember	K2-Understand	K3-Apply	K4-Analyse	K5-Evaluate	K6-Create

Course Outcome

CO 1	Understand the general features and film growth techniques used	K1, K2
CO 2	Study the various measurement and monitoring techniques	K2, K3
CO3	Understand fundamentals of preparation methods	K5
CO 4	Understand the properties and analysis the results obtained from thin film	K3, K4
CO 5	Understand the necessity of high vacuum production in sample preparation.	K1, K6

Course outcome Vs Programme outcomes

PO/CO	PO 1	PO 2	PO 3	PO 4	PO 5	PO 6	PO 7	PO 8	PO 9	PO 10
CO 1	S (3)	M (2)	S (3)	M (2)	M (2)	S (3)	L(1)	M (2)	L(1)	M (2)
CO 2	S (3)	M (2)	M (2)	S (3)	S (3)	S (3)				
CO 3	M (2)	M (2)	S (3)	S (3)	S (3)	M (2)	M (2)	L (1)	L(1)	S (3)
CO 4	S (3)	S (3)	S (3)	S (3)	M (2)	M (2)	L(1)	M (2)	M (2)	M (2)
CO 5	M (2)	S (3)	S (3)	S (3)	S (3)	L (1)	L(1)	S (3)	S (3)	S (3)
W. AV	2.6	2.6	3	2.8	2.6	2	1.4	2.2	2	2.6

S – Strong (3), M-Medium (2), L-Low (1)

Course Outcome Vs Programme Specific Outcome

PSO/CO	PSO 1	PSO 2	PSO 3	PSO 4	PSO 5
CO 1	S (3)	M (2)	M (2)	S (3)	S (3)
CO 2	S (3)	S (3)	M (2)	M (2)	S (3)
CO 3	M (2)	M (2)	S (3)	M (2)	S (3)
CO 4	L(1)	M (2)	M (2)	S (3)	S (3)
CO 5	M (2)	M (2)	M (2)	S (3)	S (3)
W. AV	2.2	2.2	2.2	2.6	3

III SEMESTER										
DSE		se code 2517	Superconducting Materials and Applications	Т	Credits: 3	Hours: 3				
	Unit - I									
	Objective 1 To introduce the basic experimental aspects of the superconductivity.									
	BASIC EXPERIMENTAL ASPECTS -Zero electrical resistance - Meissner effect - a.c. diamagnetic									
_	-	_	city – optical absorption by superconductor – entro		-	-				
- destruction of superconductivity by external magnetic fields - type I and type II materials -										
superconducting behaviour under high pressures –flux quantisation – normal and Josephson tunneling.										
Outo	Outcome 1 The students understand the basic concepts of superconductivity K2									
			Unit - II							
_			about superconducting materials and its alloys.							
			MATERIALS - Elemental superconductors –sup	ercond	acting compo	unds and its				
			- chevral phase compounds.							
Outo	come 2	Gain kno	wledge in superconducting materials.			K4				
			Unit - III							
Obje	ctive 3		the students to understand the experimental stu	dies of	supercondu	cting				
		materials			D' C C C	0 1				
I			E SUPERCONDUCTORS – La-Ba-Cu-O, Y-Ba							
fulleren		ir crystai s	structures – Experimental studies on the new mater	iais – C	organic supero	conductors –				
		I] d4	The state of the s		-1-	1/1				
Outo	come 3	Understa	nd the experimental studies of superconducting Unit - IV	materi	ais	K1				
Ohio	otivo 1	To inquir	e the theoretical aspects of superconductivity.							
			CTS - Isotope effect – BCS theory – Role of elect	**************************************	nd nhonons	annliaationa				
			re results to calculate electron-phonon coupling		•	* *				
1			cories on high Tc materials, Coherence length, ex							
1			al current Jc – heavy fermion superconductivity.	7103310	ii ioi ciiticai	temperature				
			e theoretical aspects of superconductivity.			K5				
		пррту сп	Unit - V							
Obie	ective 5	To learn	various application in superconductivity							
			erconducting magnets – power generators, motor	s, tran	sformers, po	wer storage,				
1			ephson junction devices – IR sensors – SQUIDS –							
1		er storage	•		C	·				
		The stude	ents able to understand various technological ap	plicatio	on of					
Outo	ome 5		conductivity.			K2				
Sugge	sted Rea	adings:-	•							
Blund	ell S. (20	009). Supe	erconductivity: A Very Short Introduction. Oxford	Univers	sity Press.					
Kowk	H.S. and	d ShawD	.T (Eds.). (1988). Superconductivity and its Ap	plicati	ons. Elsevie	r Science				
Publis	shing.									
Narlik	carA.V.	(1990).	Studies on High temperature superconductors-	Adva	inces in res	earch and				
applic	ations. N	Nova Scie	ntific, New Delhi.							
Narlik	arA.V. a	ndEkbote	. (1983). Introduction to Superconductivity. South	Asia pı	ıblishers.					
Schrie	Schrieffer J.R. (2009). Theory of Superconductivity, Levant Books.									

Online resources:-

High-Tc superconducting materials for electric power applications, David Larbalestier, Alex Gurevich, D. Matthew Feldmann & Anatoly Polyanskii, Nature volume 414, pages368–377 (2001), https://doi.org/10.1038/35104654.

Development of a superconducting magnet for nuclear magnetic resonance using bulk high-temperature superconducting materials, Takashi Nakamura, Yoshitaka Itoh, Masaaki Yoshikawa, Tetsuo Oka, Jun Uzawa, Volume31B, Issue2, April 2007, Pages 65-70, https://doi.org/10.1002/cmr.b.20083.

Materials science challenges for high-temperature superconducting wire, S. R. Foltyn, L. Civale, J. L.

Course Outcome

CO 1	Understand the basic concepts of superconductivity	K1, K2
CO 2	Gain knowledge in superconducting materials.	K2, K3
CO 3	Understand experimental studies of superconducting materials	K5
CO 4	Apply the theoretical aspects of superconductivity.	K3, K4
CO 5	Understand various technological application of the superconductivity.	K1, K6

Course outcome Vs Programme outcomes

PO/CO	PO 1	PO 2	PO 3	PO 4	PO 5	PO 6	PO 7	PO 8	PO 9	PO 10
CO 1	S (3)	M (2)	S (3)	M (2)	M (2)	S (3)	L (1)	M (2)	L(1)	M (2)
CO 2	S (3)	M (2)	M (2)	S (3)	S (3)	S (3)				
CO 3	M (2)	M (2)	S (3)	S (3)	S (3)	M (2)	M (2)	L (1)	L(1)	S (3)
CO 4	S (3)	S (3)	S (3)	S (3)	M (2)	M (2)	L (1)	M (2)	M (2)	M (2)
CO 5	M (2)	S (3)	S (3)	S (3)	S (3)	L(1)	L(1)	S (3)	S (3)	S (3)
W. AV	2.6	2.6	3	2.8	2.6	2	1.4	2.2	2	2.6

S –Strong (3), M-Medium (2), L-Low (1) Course

Outcome Vs Programme Specific Outcome

PSO/ CO	PSO 1	PSO 2	PSO 3	PSO 4	PSO 5
CO 1	S (3)	M (2)	M (2)	S (3)	S (3)
CO 2	S (3)	S (3)	M (2)	M (2)	S (3)
CO 3	M (2)	M (2)	S (3)	M (2)	S (3)
CO 4	L(1)	M (2)	M (2)	S (3)	S (3)
CO 5	M (2)	M (2)	M (2)	S (3)	S (3)
W. AV	2.2	2.2	2.2	2.6	3

		IV-SEMESTER			
Core 16	Course Code: 542999	Project Dissertation work/Internship Programme		Credits: 15	Hours: 30
		m of the research project/internship is			
		students to demonstrate the personal abili-	ties and	skills required t	to produce and
		n extended piece of work.			
		ge in personal inquiry, action and reflection	_	_	ssues.
		on, and demonstrate an understanding of, t			
	• To reflec	t on learning and share knowledge, views a	ind opini	ions.	
	Specific obje	ctives for allowing one full semester to	carry o	out research pro	ject and/or to
		nternship training programme are as follow	-	•	
		A) Planning and Development S	Students	should:	
	-	a clear and achievable goal			
		and justify a focus on the chosen area(s) of		tion	
		the steps followed to achieve the stated goa	al		
	Adhere to	o the stated goal throughout the project.			
		B) Literature/data collection St	udents s	should:	
	Select an	d utilize adequate, varied resources			
		and use relevant information critically			
	Acknowl	edge sources of information appropriately.			
		9 0 0 0 0 0			
		C) Choice and Application of Technic	-		
		experiment/tech <mark>ni</mark> ques relevant to the project	t's goal		
	_	is selection			
		e chosen tech <mark>ni</mark> ques consistently and effecti sufficient data relevant to the goal	very.		
	Acquires	sufficient data relevant to the goal	1		
		D) Data analysis Students	s should		
	• Analyse	the data in terms o <mark>f th</mark> e goal an <mark>d th</mark> e focus o	of the pro	oject	
		personal thought			
		arguments with evidence			
	Respond	thoughtfully to ideas and inspiration.			
		E) Organization of the Dissertation	n Studen	nts should:	
	Organize	their work in a coherent manner according			e
		nformation clearly	,	1	
	• Present r	eferences, bibliography and symbolic repre	sentation	ns appropriately.	
		5			
	. 11 410	F) Analysis of the Process and Outco			1
		the strengths and weaknesses of the project			
sə A	_	opropriate, suggest ways in which the project the achieved results in terms of the initial go			-
ctiv	of interac		an anu t	ne focus on the	chosen area(s)
Objectives		vareness of the overall perspectives related t	to the ch	osen topic or pi	ece of work.

		I-SEMI	LSTER			
NME 1	Course code :5427	01 Electron	ics For Daily Life	T	Credits: 2	Hours: 3
		U	nit -I			
	~		nics home applianc			
			lectrical safety – Ele	-		-
			ssment and manage			_
	=		lectrical insulation -	Electri	cal fires, Arc	flash - Safety
	ging energy sources.					
Outcome 1 Ge	et familiar with the					K1, K2
			nit II			
	learn about electr					
			G - Switches – hold			
			inding – importance		onents of eart	hing system –
			specifications of eart			
Outcome 2 G	et familiar in hand		ppliances and elect	ronics g	adgets.	K3, K4
			it III			
	get familiar with					
			of processor and Me	-	_	
		V – smart watch	n- Medical diagnosi	s based	on smart pho	one- Human–
Computer Interact	The second secon	SE SE SECREDA I	NIVERSITY SE			
Outcome3 St	tudents learn abou	t smart electron	100			K2
		All and a second	- 10			K2
	0	Ur	nit IV			K2
		Ur oncept of energy	nit IV and energy devices			
ENEGRY DEV	ICES- Energy den	Ur oncept of energy sity vs Power de	nit IV and energy devices ensity – Primary, Se		y Batteries- V	
ENEGRY DEVI Cell- Alkaline-Lit	ICES- Energy den thium ion –Flow ba	Ur oncept of energy sity vs Power de ttery- Supercapac	nit IV and energy devices ensity – Primary, Se		y Batteries- V	
ENEGRY DEVI Cell- Alkaline-Lit	ICES- Energy den	Ur oncept of energy sity vs Power de ttery- Supercapac ergy devices.	nit IV and energy devices ensity – Primary, Se eitor- Fuel Cell.		y Batteries- V	
ENEGRY DEVI Cell- Alkaline-Lit Outcome4 Ge	ICES- Energy den thium ion –Flow ba et familiar with ene	Ur oncept of energy sity vs Power de ttery- Supercapace ergy devices.	and energy devices ensity – Primary, Se citor- Fuel Cell.		y Batteries- V	Wet Cell, Dry
ENEGRY DEVICE Cell- Alkaline-Lit Outcome4 Ge Objective 5 To	ICES- Energy den thium ion –Flow bat familiar with energy get knowledge on	oncept of energy sity vs Power de ttery- Supercapace ergy devices. Understanding	and energy devices ensity – Primary, Se citor- Fuel Cell.	econdar		Wet Cell, Dry K5
ENEGRY DEVICE Cell- Alkaline-Lit Outcome4 Ge Objective 5 To ENERGY CON	ICES- Energy denthium ion –Flow bat familiar with energy get knowledge on SERVATION- Re	Ur oncept of energy sity vs Power de ttery- Supercapace ergy devices. Ur energy conserva	and energy devices ensity – Primary, Sector- Fuel Cell. nit V ation Source- Photovolt	aic Cell	– Energy Ef	Wet Cell, Dry K5
ENEGRY DEVICE Cell- Alkaline-Lit Outcome4 Ge Objective 5 To ENERGY CON (CLF, LED)- Gre	ICES- Energy denthium ion –Flow bat familiar with energy get knowledge on SERVATION- Regen Computing-Hom	oncept of energy sity vs Power de ttery- Supercapace ergy devices. Un energy conserva enewable Energy ae appliance- Ene	and energy devices ensity – Primary, Secitor- Fuel Cell. nit V ntion Source- Photovoltargy efficiency in Vel	econdar aic Cell hicles –	– Energy Ef Solar car.	Vet Cell, Dry K5 Ficient lamps
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Course Outcome

CO1	Acquire knowledge of electrical safety principles, preventing electric shock, and addressing safety concerns with emerging energy sources.	K1
CO2	Learn about electrical accessories and earthing systems, their significance, components, types, and adherence to SI specifications.	K2, K3
CO3	Comprehend the history of processors, memory storage and apply smart electronics in devices, while understanding human-computer interaction.	K2, K4
CO4	Gain comprehensive understanding of various energy storage technologies, along with the concepts of energy density and power density.	K2, K5
CO5	Learn about renewable energy sources, energy-efficient lighting, green computing, eco-friendly appliances, and solar-powered vehicles.	K1, K6

Course outcome Vs Programme outcomes

PO/CO	PO 1	PO 2	PO 3	PO 4	PO 5	PO 6	PO 7	PO 8	PO 9	PO 10
CO 1	S (3)	S (3)	S (3)	L(1)	L (1)	S (3)	S (3)	S (3)	L (1)	S (3)
CO 2	S (3)	S (3)	S (3)	L(1)	L(1)	M (2)	L(1)	M (2)	L (1)	S (3)
CO 3	S (3)	S (3)	S (3)	L (1)	L(1)	M (2)	S (3)	S (3)	S (3)	S (3)
CO 4	S (3)	S (3)	S (3)	M (2)	L (1)	M (2)	L (1)	M (2)	S (3)	M (2)
CO 5	S (3)	S (3)	S (3)	M (2)	L(1)	M (2)	S (3)	L (1)	M (2)	S (3)
W. AV	3	3	3	1.4	1	2.2	2.2	2.2	2	2.8

S-Strong (3), M-Medium (2), L-Low (1) Course

Outcome Vs Programme Specific Outcome

PSO/ CO	PSO 1	PSO 2	PSO 3	PSO 4	PSO 5
CO 1	S (3)	S (3)	M (2)	S (3)	S (3)
CO 2	S (3)	M (2)	M (2)	S (3)	M (2)
CO3	S (3)	S (3)	L(1)	M (2)	M (2)
CO 4	S (3)	L(1)	S (3)	M (2)	M (2)
CO 5	S (3)	M (2)	S (3)	M (2)	M (2)
W. AV	3	2.2	2.2	2.4	2.2

		I-SEMESTER			
NME 2	Course code:542702	Food Chemistry	Т	Credits: 2	Hours: 3
TVIVIE 2	Course couc.342702	Unit -I	1	Cicuits. 2	Hours. 5
Objective 1	To enable the students to ac the food		macro an	d micro cons	tituents of
	AL SAFETY - General princip				
	rn - Respiratory protection - Ri				
	residual voltages - Hazardous	areas, Electrical insulation	n - Electr	ical fires, Arc	flash - Safety
	nerging energy sources. Know about the factors gove	ouning the food			171 173
Outcome 1	Know about the factors gov	Unit II			K1, K2
Objective 2	To know the structure and o		of constit	uents of food	
	AL ACCESSORIES AND EA				ng rose — plugs
	– fuse – circuit breaker – Earth				
	ing – pipe, plate and rod earthing			policins of car	tining by sterin
Outcome2	Able to name and describe t			the major	172 174
	components of foods and se				K3, K4
		Unit III			
Objective 3	To demonstrate the knowled concepts of chemistry as the	ey apply to food systems	3		
	ECTRONICS - Historical Back				
	le – LCD and LED TV – sma	rt watch- Medical diagn	osis base	d on smart p	hone- Human–
Computer Int		APPA UNIVERSITY S			
Outcome 3	Know about the techniques	200	ing and p	oreservation	K2
Objective 4	To familiarize the student w	Unit IV	ioon wate	n and food	
					W + C 11 D -
Cell- Alkaline	EVICES- Energy density vs Pe-Lithium ion –Flow battery- St	<mark>ipe</mark> rcapacito <mark>r- F</mark> uel Cell.		ry Batteries-	
Outcome4	Learn food a <mark>dditi</mark> ves an <mark>d t</mark> hei		n		K5
01: 4: 7		Unit V			
Objective 5					
	ONSERVATION- Renewable				fficient lamps
(CLF, LED)-	Green Computing-Home applia				
Outcome 5	Familiarize with the nature	of packed food from ind	ustrial p	rocesses	K5, K6
Suggested F	S				
	, Grosch, W. & Schieberle, P.	(2004) Food Chemistry	3rd Ed.	(translation o	f fifth
	ion), Springer	(
Press	S., Parkin, K. L., and Fennema			emistry 4th E	dition, CRC
	. (2018). Principles of Food Che	•			
Harish Kum	ar Chopra andParmjit Singh Pa	nesar, (2010). Food Chen	nistry, Na	rosa Publicat	ion.
Jaswinder K	aur and Barry H. Grump.(2010)	. Fundamentals of Food C	hemistry,	Abhizeet Pub	lications.
Peter C. K.	Cheng, (2015). Handbook of Fo	od Chemistry, Vol 1, Spr	inger Re	ference.	
Online reso	urces:-				
https://www.	britannica.com/technology/food-p	processing			
https://byjus	.com/biology/food-processing/				
	ift.org/policy-and-advocacy/adv				
K1-Rememl	oer K2-Understand K3-A	pply K4-Analyse	K5-I	Evaluate	K6-Create
			Course	designed by:	Dr. C. Sekar
				· ·	

Course Outcome

CO1	Know about the factors governing the food quality and chemical constituents	K1
CO2	Able to name and describe the general chemical structures of the major components of foods and selected minor components	K2, K3
СОЗ	Know about the techniques involved in food processing and preservation	K2, K4
CO4	Learn food additives and their function in preservation	K2, K5
CO5	Familiarize with the nature of packed food from industrial processes	K1, K6

Course outcome Vs Programme outcomes

PO/CO	PO 1	PO 2	PO 3	PO 4	PO 5	PO 6	PO 7	PO 8	PO 9	PO 10	
CO 1	S (3)	S (3)	S (3)	L (1)	L(1)	S (3)	S (3)	S (3)	L (1)	S (3)	
CO 2	S (3)	S (3)	S (3)	L(1)	L (1)	M (2)	L(1)	M (2)	L (1)	S (3)	
CO 3	S (3)	S (3)	S (3)	L(1)	L (1)	M (2)	S (3)	S (3)	S (3)	S (3)	
CO 4	S (3)	S (3)	S (3)	M (2)	L (1)	M (2)	L(1)	M (2)	S (3)	M (2)	
CO 5	S (3)	S (3)	S (3)	M (2)	L (1)	M (2)	S (3)	L (1)	M (2)	S (3)	
W. AV	3	3	3	1.4		2.2	2.2	2.2	2	2.8	

S –Strong (3), M-Medium (2), L-Low (1) Course

Outcome Vs Programme Specific Outcome

PSO/CO	PSO 1	PSO 2	PSO 3	PSO 4	PSO 5
CO 1	S (3)	S (3)	M (2)	S (3)	S (3)
CO 2	S (3)	M (2)	M (2)	S (3)	M (2)
CO 3	S (3)	S (3)	L (1)	M (2)	M (2)
CO 4	S (3)	L(1)	S (3)	M (2)	M (2)
CO 5	S (3)	M (2)	S (3)	M (2)	M (2)
W. AV	3	2.2	2.2	2.4	2.2

	III-SE	MESTER						
NME 3	Course code :542703 Nanoma	aterials Biosensors T	Credits: 2	Hours: 3				
	τ	Jnit - I						
Objective 1	Objective 1 To understand different methods for attaching recognition molecule on the sensor							
Objective 1	surface. understand basic characteristics of biosensors, nanoparticles and hybrids							
BASICS OF	NANOBIOSENSORS -Basic concept	s, Classification, Compo	onents; Features	of Biosensors –				
Sensitivity, Se	lectivity, Reproducibility, Portability	, Stability, Detection Li	mit, Response	time - types of				
nanobiosensor	s; Nanoparticle biomolecule - hybrids	, Nanoparticle for biosen	sing.					
	Ability to Select different types of se		_	112/11/				
	and applications. Understanding th	e hybrid of nanomater	ials and	K3/K6				
	biomolecules							
		nit - II						
	To learn about Synthetic methods of							
	SIS OF NANOPARTICLES - Meta oxide nanoparticles - synthesis using b							
inorganic nanc		acteria, rungi, piant extr	acis, biological	applications of				
_	Get familiar with green synthesis of	metal/oxide nanonartic	les using					
(hitaama)	bacteria, fungi and plant extracts	metal oxide nanopartic	ics using	K4/K5/K6				
		nit - III						
Objective 3	To identify different recognition mol	ecules for different bio	sensing applica	tions				
-	R RECOGNITION ELEMENTS	CONTRACTOR AND ADDRESS OF THE PARTY OF THE P						
elements – En	zymes, Antibodies; Nuclei <mark>c acids; M</mark> o	ethods of Immobilization	n - Co-valent an	d non-covalent,				
self-assembly.								
Outcome 3	Ability to select biorecognition syst analytes.	<mark>em to</mark> dete <mark>ct</mark> particular	type of	K1/ K5/K6				
	U	nit - IV						
_	To know el <mark>ectric</mark> al and o <mark>ptical techn</mark>							
	L AND OPTICAL BIOS <mark>EN</mark> SORS		_					
_	biosensors; Glucose biosensors - C		nciples – Absor	rbance, Chemi-				
	Fluorescence, Phosphorescence; Colo			T74/				
	Learn different biosensing technique		orinciples of	K1/				
	electrochemical and optical biosenso	rs Init - V		K2/K5/K6				
Objective 5	To get familiar nanotechnology appl		food industries					
	NOLOGY AND ITS APPLICAT							
	gy and food packaging, natural biopo							
	nanosensors, outstanding issues, risks							
	recision farming, Smart delivery syste							
fertilizers.								
Outcome 5	Outcome 5 Familiarize with applications of nanosensors in medical and food K1/							
	industries and able to identify the m	aterials for both applic	ations	K2/K5/K6				
Suggested R	9							
	pole, Jr., Frank J. Owens.(2006).Introd	-	•					
	hn Wiley Weinhim (2008).Nanostruc			LICA				
_	alwa. Nanostructured Materials and N	anotechnology, Academ	ic Press London	USA,				
Concise Edit	OII.							

Kourosh Kalantar, Zadeh Benjamin Fry. (2008). *Nanotechnology Enabled Sensors*, Springer, Newyork.

Seminario, Jorge. (2014). Design and applications of Nanomaterials for Sensor, Springer Publications.

Vijay K. Vardan, L. Chen, Jining, John Wiley. (2008). *Nanomedicine Design and applications of Magnetic Nanoparticles*, Nanosensors and Nanosystems, New Jersey.

Online resources:-

Nanotechnologies in Food Science: Applications, Recent Trends, and Future Perspectives | SpringerLink Frontiers | Application of Nanotechnology in Food Science: Perception and Overview (frontiersin.org)

K1-Remember	K2-Understand	K3-Apply	K4-Analyse	K5-Evaluate	K6-Create		
	Course designed by: Dr. V. Dharui						

Course Outcome

CO 1	Ability to Selectin different types of sensors based on type of requirement and applications. Understanding the hybrid of nanomaterials and biomolecules	K1, K2
CO 2	Familiarize with green synthesis of metal/oxide nanoparticles using bacteria, fungi and plant extracts	K3, K6
CO 3	Ability to selecting biorecognition system to detect analytes	K4, K5, K6
CO 4	Learn different biosensing techniques, glucose biosensors, principles of electrochemical and optical biosensors	K1, K5, K6
CO 5	Familiarize with applications of nano sensors in medical and food industries and able to identify the materials for both applications	K1, K2, K5, K6

Course outcome Vs Programme outcomes

PO/CO	PO1	PO2	PO3	PO4	PO5	PO6	PO7	PO8	PO9	PO10
CO 1	S (3)	M (2)	L(1)	L(1)	M (2)	L (1)				
CO 2	S (3)	M (2)	M (2)	M (2)	M (2)	S (3)	M (2)	M (2)	M (2)	M (2)
CO3	M (2)	S (3)	M (2)	L (1)	M (2)	M (2)	S (3)	S (3)	M (2)	M (2)
CO 4	M (2)	M (2)	S (3)	M (2)	S (3)	M (2)				
CO 5	M (2)	S (3)	L(1)	L(1)	M (2)	L(1)				
W. AV.	2.4	2.0	2.2	1.8	2.0	2.4	1.8	1.8	2.2	1.6

S – Strong (3), M-Medium (2), L- Low (1)

Course Outcome Vs Programme Specific Outcome

PSO/ CO	PSO 1	PSO 2	PSO 3	PSO 4	PSO 5
CO 1	S (3)	S (3)	M (2)	M (2)	M (2)
CO 2	S (3)	M (2)	S (3)	S (3)	M (2)
CO 3	M (2)	M (2)	M (2)	M (2)	S (3)
CO 4	M (2)	M (2)	S (3)	S (3)	M (2)
CO 5	S (3)	S (3)	M (2)	M (2)	M (2)
W. AV.	2.6	2.4	2.4	2.4	2.2

		III-SEMESTER		
NME 4	Course code :542704	Green Chemistry	T Credits:	2 Hours:3
•		Unit -I		•
Objective 1	To introduce the bas management.	ic concept and principles of green	chemistry for envi	ronmental
		MISTRY -History of green chemis	•	•
		incorporation of reactants in lous products – Designing safer		
Outcome 1	Familiarize with bas	ic concepts of green chemistry and	d apply to	K1, K2
		Unit II		_ I
Objective 2	To make the students	s know about green reagents and i	ts importance to th	ne environment
GREEN REA	GENTS AND CATA	ALYSTS - Choice of starting mater	ials – reagents (Din	nethyl carbonate,
polymer supp	orted reagents) - catal	ysts (microencapsulated Lewis aci	ds, zeolites, basic c	atalysts polymer
supported cata	lysts, introduction to b	iocatalysts).		
Outcome 2	Recognize the cataly	tic reaction with green reagents a	nd its	K3, K4
	importance.	The same		К3, К4
		Unit III		
Objective 3		lvents and its impacts in green ch phase reactions (Claisen rearran		
Electrochemic reactions in ne	cal synthesis (synthes utral ionic liquids (hyd thylene insertion reacti		– reactions in acid Heck reactions, O-a	dic ionic liquids-
Outcome 3		rati <mark>ons</mark> of <mark>materi</mark> als with green pr	ocess and its	K2
	applicatio <mark>n to th</mark> e en			
01: 4: 4	T. C. 11:	Unit IV	(1 1	
•	· ·	nthesis of materials using green m we induced green synthesis (Hoff		and Ovidation of
		een synthesis (Esterification, Sapor		
,	•	tion of alcohols to alkenes, Grignar		,
_	thesis of furans and py	_	a reaction) Solia s	apported organic
, ,		f preparation of various drugs usi	ng green	
Outcome 4	synthesis methods	- propulation of the load artugo ass		K5
	0	Unit V		
Objective 5	To impart the knowl	edge on applications of green synt	hesis technology	
	_	NTHESIS - Introduction – synthes		ca acid, catechol,
	· · · · · · · · · · · · · · · · · · ·	ethacrylate, urethane. Environmer		esis of aromatic
amines – free i		synthesis of ibuprofen and paracetar		
Outcome 5	Obtain skills and tec in industry.	hnology towards green chemistry	and apply	K5, K6
Suggested R	•			
	, ,	emistry, Narsoa publishers.		
AhluwaliaV.	K. andKidwaiM. (2004). New trends in Green Chemistry,	Anamaya Publishers	3.

Bela Torokand Timothy Dransfield , (2017). *Green Chemistry, An Inclusive Approach*, 1st Edition, Elsevier.

Online resources:-

https://www.khanacademy.org/science/electrical-engineering

https://www.electronics-tutorials.ws/

https://ocw.mit.edu/courses/electrical-engineering-and-computer-science/

K1-Remember	K2-Understand	K3-Apply	K4-Analyse	K5-Evaluate	K6-Create
		Course designed b	y: Dr. C. Sekar		

Course Outcome

CO1	Familiarize with basic concepts of green chemistry and apply to them in various field.	K1
CO2	Recognize the catalytic reaction with green reagents and its importance. To identify available green solvents and apply them to various synthesis process	K2, K3
CO3	Recognize the preparations of materials with green process and its application to the environment.	K2, K4
CO4	Gain the knowledge of preparation of various drugs using green synthesis methods	K2, K5
CO5	Obtain skills and technology towards green chemistry and apply in industry.	K1, K6

Course outcome Vs Programme outcomes

PO/CO	PO 1	PO 2	PO 3	PO 4	PO 5	PO 6	PO 7	PO 8	PO 9	PO 10
CO 1	S (3)	S (3)	S (3)	L (1)	L (1)	S (3)	S (3)	S (3)	L(1)	S (3)
CO 2	S (3)	S (3)	S (3)	L (1)	L (1)	M (2)	L (1)	M (2)	L(1)	S (3)
CO 3	S (3)	S (3)	S (3)	L (1)	L(1)	M (2)	S (3)	S (3)	S (3)	S (3)
CO 4	S (3)	S (3)	S (3)	M (2)	L (1)	M (2)	L (1)	M (2)	S (3)	M (2)
CO 5	S (3)	S (3)	S (3)	M (2)	L (1)	M (2)	S (3)	L (1)	M (2)	S (3)
W. AV	3	3	3	1.4	1	2.2	2.2	2.2	2	2.8

S – Strong (3), M-Medium (2), L- Low (1)

Course Outcome Vs Programme Specific Outcome

PSO/CO	PSO 1	PSO 2	PSO 3	PSO 4	PSO 5
CO 1	S (3)	S (3)	2	S (3)	S (3)
CO 2	S (3)	M (2)	M (2)	S (3)	M (2)
CO 3	S (3)	S (3)	L(1)	M (2)	M (2)
CO 4	S (3)	L(1)	S (3)	M (2)	M (2)
CO 5	S (3)	M (2)	S (3)	M (2)	M (2)
W. AV	3	2.2	2.2	2.4	2.2



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